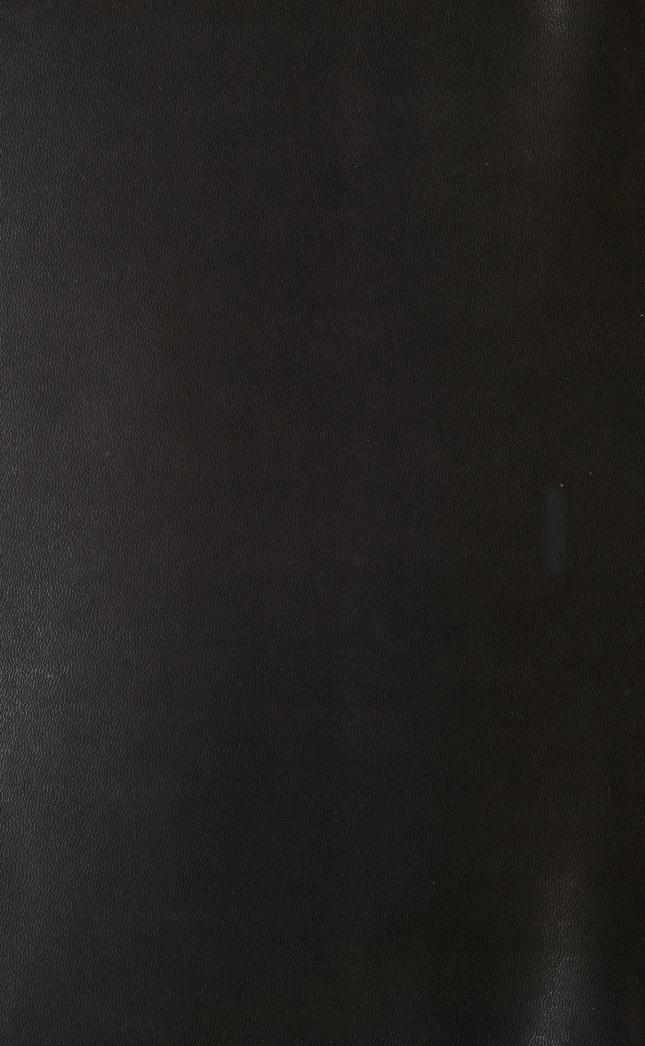
SIEMENS

LEVEL METER
200 Hz to 1620 kHz with Frequency lock-in

D 354

Instructions for Operation \$45034-0354-8302-51-7618

SIEMENS AKTIENGESELLSCHAFT





LEVEL METER

D 354

200 Hz to 1620 kHz with Frequency lock-in

Instructions for Operation \$45034-D354-B302-51-7618

SIEMENS AKTIENGESELLSCHAFT

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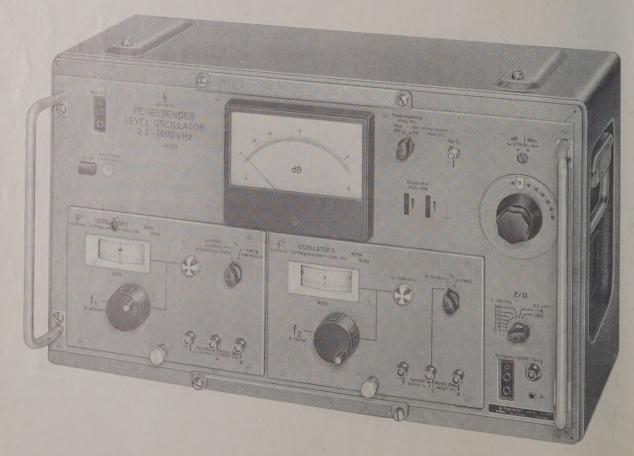
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Level meter Type D 354 with the slide-in chassis Oscillator I Type D 369 and Oscillator II Type D 370



Level oscillator Type W 231 with the slide-in chassis Oscillator I Type W 233 and Oscillator II Type W 234

1. DESCRIPTION

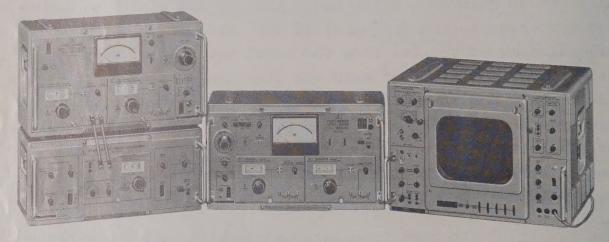
1.1 Application

Level meter and level oscillator, both fitted exclusively with silicon transistors, are constructed and coordinated in such a way as to produce complete measuring setups having particularly high level and frequency accuracy.

Level meter and level oscillator form a measuring setup for wideband level, attenuation and gain measurements in the audio and carrier frequency ranges from 200 Hz to 1620 kHz. Measurements can be made on a wideband or selective basis. With selective measurements the frequency of the level meter can be automatically controlled from the level oscillator and vice versa. Synchronization of main and fine tuning renders tuning operation on one of the two devices unnecessary and permits selective measurements to be made with all their advantages, yet retaining the ease common to wideband measurements. Frequency lock—in derived from a crystal spectrum results in high frequency accuracy of both devices.

As a result of its high frequency and level accuracy the measuring setup is particularly suited to development and testing of devices and systems in communications and electronics. Further, the measuring setup can be used when equipment is being lined up and, when it is a question of great accuracy, also in operational measurements. Its frequency range includes the CCITT groups and supergroups up to 1548 kHz and also all carrier systems and devices having up to 300 voice channels. Even in systems having a large number of voice channels (e.g. V 960, V 2700) many measurement problems fall within the range of the measuring setup. In the same way it covers the frequency range of modulation facilities of radio relay systems which are provided for the transmission of the basebands mentioned above and that of the corresponding balanced and coaxial carrier cables.

The measuring setup can be extended quite simply to form a sweep-frequency measuring setup. The internal oscillators are replaced by external ones which operate in the same frequency range. Their frequency is electronically swept. The sweep range is continually adjustable between ± 25 Hz and ±800 kHz. The oscillator units of the level oscillator continue to operate, providing the frequency markers necessary for the sweep operation, the accuracy of which corresponds to that of the level oscillator. The equipment necessary to sweep the measuring voltage is housed in the sweep-frequency attachment Type W 935, or G 2022 resp., which can be adapted by means of slide-in chassis for large and small sweep ranges depending upon the measuring problem in hand.



Sweep frequency measuring setup 200 Hz to 1.6 MHz

Left: Level oscillator, below: Sweep attachment, middle:

Level meter, right: Level tracer

The level tracer Type D 346 displaying on the large screen a continuous trace representing some measured quantity as a function of frequency is connected to the specimen either directly or via the level meter. By adding to the display level and frequency lines, a coordinate system is traced out which is entirely free of tube distortion and parallax. This ensures a very accurate and reliable evaluation of the measured curve. When the level expansion is activated the sensitivity can be so increased that a change in level of 0.1 dB produces a deflection of 15 mm on the screen. Thus also sweep measurements in terms of tenths of a percent are easily possible.

If, on the other hand, level differences of up to 100 dB are to be represented on the screen, the level tracer will be connected to the dynamic output via the logarithmic amplifier. With the wide variation of the sweep range (+25 Hz to +800 kHz), the large sweep frequency range (0.015 to 25 Hz and manual setting), and high frequency accuracy $(\frac{\Delta f}{f} < 10^{-5})$ all likely measurement problems can be solved in the frequency range of this sweep measurement setup with great time saving.

1.2 Electrical Data

Level Oscillator

Basic device W 231 with slide-in chassis oscillators I W 233 and II W 234
wrom bilde-in chassis oscillators i w 255 and ii w 254
Frequency range 200 Hz to 1620 kHz
set measuring frequency f _m f ₁ + f ₂
Main setting t ₁
with spectrum lock-in in 10-kHz steps0,1620 kHz or continuously 0 to 1620 kHz
Fine setting f
with spectrum lock-in
smallest frequency increment readable approx.20 Hz
Frequency error
f ₁ and f ₂ with spectrum lock-in+1.10 ⁻⁵
f ₁ with spectrum lock-in, f ₂ continuously+1·10 ⁻⁵ +30 Hz
Frequency change with +10% mains voltage change
f_1 and f_2 with spectrum lock-in
f ₁ with spectrum lock-in, f ₂ continuously ±2 · 10 ⁻⁷ ±2 Hz
Automotic tuning
Automatic tuning

frequency tuning of the level met	ter from the
level oscillator for	
from the level meter for	f and f

Automatic frequency sweep with sweep attachment W 935/G 2022 and slide--in chassis f₁ Type W 940 for wide sweeps....+3 to +800 kHz with sweep attachment W 935/G 2022 and slide--in chassis for Type W 941 for narrow sweeps..+25 to +3000 Hz mid-frequency, continuously adjustable 200 Hz to 1620 kHz from ... Model B 302:0 dB=0.775 V B 602:0 Np=0.775V O dBm=1 mV O Npm=1 mV Level output for zero instrument mark, adjustable in steps of 10 dB, 1 Np -60 to +10 dB -6 to +1 Np -60 to +10 dBm -6 to +1 Npm continuous variable about15 dB 1.5 Np smallest adjustable level -75 dB -7.5 Np -7.5 Npm -75 dBm Level output error at 100 kHz and the relative values: range switch 0 dB, 0 Np Instrument mark 0 and $Z_i = Z = 75\Omega$ ••••• +0.1 dB +0.01 Np Attenuator error •••••• +0.1 dB +0.01 Np Frequency response of the output level +0.1 dB +0.01 Np Level output change with +10% mains voltage variation +0.03 dB +0.003 Np Typical total level error for $Z_i = Z = 75\Omega$, coaxial, outer wire grounded Frequency range 10 kHz to 1 MHz Transmitting level 0 to -50 dB (-5 Np), +0.2 dB full-scale deflection with automatic +0.02 Np regulation Mains voltage variation +10% Temperature range +15 °C to +35 °C Outputs three-pole jackfloating, balanced coaxial jack 1.6/5.6..... external wire grounded

Internal impedanceΩ Ω
for frequency range 0.2 to 5 kHz, can be switched to 600 Ω
for the range 2 to 1620 kHz can be switched to
Signal-to-distortion ratio a_{k2} or a_{k3} at 100 kHz and with the relative values
O Np, O dB: Zi=Z=75 Ω
Spurious emissions
External modulation (AM) 0 to 100%
Frequency range to 20 kHz
Frequency response, as referred to 1 kHz
Envelope distortion ratio for m=100%approx.40 dB
Required modulation voltage for 1%
modulationapprox. 30 mV
Output voltage for frequency measurements (frequency
counter)
Power supply "protective-insulation" grade
approx. 13 VA at 220 V
LEVEL METER
Basic device D 354
Wideband
Frequency range
rrequency range
Model
B 302:0 dB = 0.775 mV B 602:0 Np = 0.775 mV O dB m = 1 mW O Np m = 1 mW
Measuring ranges
for zero instrument reading can be switched in steps of
10 dB, 1 Np
with balanced input40 to +20 dB -5 to +2 Np -30 to +20 dBm -4 to +2 Npm

```
smallest measurable (read-
                          -50 (-60) dB
                                       -6 (-7) Np
 able) level ......
                          -40 (-50) dBm
                                       -5(-6) Npm
                          -60 to +20 dB
                                       -7 to +2 Np
 with coaxial input .....
                                       -6 to +2 Npm
                          -50 to +20 dBm
 smallest measurable (readable)
                          -70 (-80) dB -8 (-9) Np
-60 (-70) dBm -7 (-8) Npm
   level ......
Level error at 100 kHz
 with the relative values: range
 switch 0 dB, 0 Np
 zero instrument mark ..... +0.1 dB
                                       +0.01 Np
 attenuator error ..... +0.1 dB
                                       +0.01 Np
Frequency response of the reading +0.1 dB
                                       +0.01 Np
Variation of the reading with
 a mains voltage variation of
 +10% ..... +0.03 dB
                                       +0.003 Np
   Typical total level error for
   Z_i = Z = 75 \Omega, coaxial, outer wire grounded
   Frequency range 10 kHz to 1 MHz
   Level measuring range 0 to -50 dB (-5 Np)
                                       +0.02 Np
   full-scale deflection
   Mains voltage variation +10%
   Temperature range +15 °C to +35 °C
   after calibration
 Impedance of the balanced floating
                      0.3 to 1000kHz ......24 kΩ
0.2 to 1620 kHz......22 kΩ
 Impedance of the coaxial, single-ended input.....10 k\Omega | 60 pF
 Dc output
 for level scale-spread device or
 Ac output
 frequency range ...... signal
 output level for zero instrument
 mark: at Z=75\Omega ..... dB (O Np)
 Earphone output .....for audio-frequency modulated input signal
```

Selective

Basic device D 354 with the slide-in chassis oscillators I D 369 and II D 370
Frequency range 200 Hz to 1620 kHz
Main setting f ₁
with spectrum lock-in in 10 kHz steps 0 to 1620 kHz continuously 0 to 1620 kHz
Fine setting f ₂
with spectrum lock-in
Frequency error
f_1 and f_2 with spectrum lock-in
Frequency change with ±10% mains voltage variation f ₁ and f ₂ with spectrum lock-in±2×10 ⁻⁷ f ₁ with spectrum lock-in f ₂ continuously±2×10 ⁻⁷ ±2 Hz
Automatic tuning system
frequency tuning of the level oscillator from the level meter for
frequency tuning of the level meter from the level oscillator for
Automatic frequency sweep
with sweep attachment W 935/G 2022 and slide-in chassis f ₁ W 940 for wide sweeps
with sweep attachment W 935/G 2022 and slide-in chassis f ₂ W 940 for narrow sweeps
mid-frequency, continuously adjustable from 200 Hz to 1620 kHz

B 302:0 dB\$=0.775 V B 602:0 Np\$=0.775V O dBm\$=1 mW O Npm\$=1 mW

Measuring ranges			
in the frequency range 2 to 1620 kHz for zero instrument mark, can be switched in steps of 10 dB, 1 Np			
"Low-distortion" measuring function with balanced input100 to +20 dB -11 to +2Np -90 to +20 dBm -10 to +2Npm			
smallest (readable) measurable level			
with coaxial input			
smallest measurable (readable) level			
"Low-noise" measuring function with balanced input60 to +20 dB -6 to +2 Np -50 to +20 dBm -5 to +2Npm			
smallest measurable(readable) level70 (-80) dB -7 (-8) Np -60(-70) dBm -6 (-7) Npm			
with coaxial input			
smallest (readable) measurable level			
Measuring ranges			
in the frequency range 200 Hz to 2 kHz			
"low-noise" measuring function for zero instrument mark can be switched in steps of 10 dB, 1 Np			
with balanced input60 to +20 dB* -6 to +2 Np* -50 to +20 dBm -5 to +2Npm			
smallest measurable (readable) level			

In the frequency range >800 Hz measurements can also be made in the more sensitive measuring ranges in the "low-distortion" position.

with coaxial input80 to +20 dB* -70 to +20 dBm	-8 to +2 Np* -7 to +2 Npm
smallest measurable (readable) level	-9 (-10) Np -8 (-9) Npm
Measuring error at 100 kHz, 0 dB, 0 Np and the relative values: range switch 0 dB, 0 Np zero instrument mark +0.1 dB	+0.01 Np
attenuator error +0.1 dB	+0.01 Np
in the most sensitive range ±0.3 dB	±0.03 Np
Frequency response of the indication	
in the frequency range 2 to 1620 kHz	+0.02 Np
200 Hz to 2 kHz ±0.4 dB	+0.04 Np
Indication changes with +10% mains voltage variation +0.03 dB	<u>+</u> 0.003 Np
Typical total measuring error for $Z_1=Z=75~\Omega$, coaxial, outer wire grounded $Z_1=Z=75~\Omega$, and $Z_1=Z=75~\Omega$ and $Z_1=Z=75$	+0.2 dB +0.02 Np
Selectivity	
can be switched to 3 ba	indwidths
selectivities available	

In the frequency range > 800 Hz measurements can also be made in the more sensitive measuring ranges in the "low-distortion" position.

Narrow band Filter 1 (200 Hz to 1620 kHz)		Medium band Filter 2 (2 to 1620 kHz)	Wideband Filter 3 (10 to 1620 kHz)		
Width of pass band ∆a ≤ 0.5 dB	<u>+</u> 5 Hz	+20 Hz	<u>+</u> 800 Hz		
Bandwidth ∆a = 3 dB	~ 20 H z	~ 80 Hz	~ 3.1 kHz		
Stop-band attenuation a = 30 dB at a = 60 dB at	±60 Hz ±150 Hz	<u>+</u> 150 Hz <u>+</u> 500 Hz	<u>+</u> 4 kHz +10 kHz		
f _{TE1}	Intermediate frequencies f _{IF1} 2.40 MHz f _{IF2} 100 kHz				
Intermediate frequenc	ey rejection for	r f _{IF1} , f _{IF2}	≥80 dB(9 Np)		
Image-frequency rejection for $f_m + 2f_{IF1}$					
Residual distortion attenuations a _{k2} and a _{k3} in "low-distortion" position with increase in sensitivity to 60 dB (7 Np)					
in the frequency range 2 to 1620 kHz =80 dB (9 Np)			0 dB (9 Np)		
with increase in sensitivity by 50 dB (6 Np)					
in the frequency ra	ange 500 Hz to 200 Hz to	2 kHz \{\bar{2}}	70 dB (8 Np) 60 dB (7 Np)		
Impedance of the inpu					
as with wideband me	easurements		see page		
IF output e.g. for logarithmic amplifier level output, at Z=600 Ω			kHz		

Ac output

frequency	100) kHz	
level output for zero instrument mark, at $Z=75\ \Omega$ 0	dB	(0 Np))
internal impedance	75	Ω	

De output

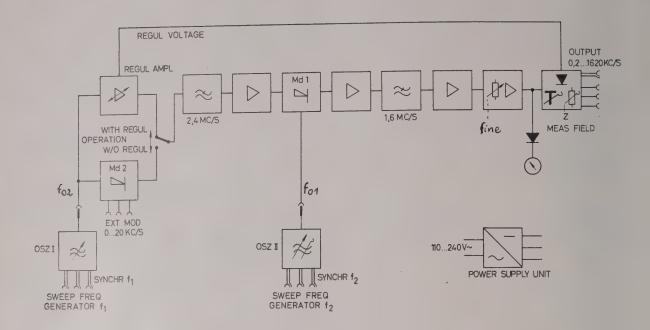
for level	scale-spread	device or re-	
corder: at	$Z=2.5 \text{ k}\Omega$		0 to 250 mV

Earphone outputfor audio-frequency modulated input signal

1.3 Functioning

1.3.1 Level Oscillator

The level oscillator is designed as a beat-frequency oscillator so that the whole frequency range can be covered without band switching. This, along with the unmistakable nature of the scale designations, leads to speedy and continuous measurements. By means of a frequency-spectrum circuit in the variable oscillator I it is possible, if desired, to set the free-running oscillator exactly to a multiple of the fundamental frequency of a crystal oscillator, whereby only a coarse manual setting is necessary, whilst the remaining frequency difference is automatically balanced out by a regulating circuit. In this way it is possible to obtain a crystal-accurate frequency every 10 kHz. Oscillator II provides for interpolating between two spectrum component frequencies: it derives its frequency from the same crystal as oscillator I and in addition from a free-running interpolation oscillator whose frequency, however, is two orders of magnitude lower than that of oscillator II and therefore, as referred to its output frequency, is similarly constant as is the crystal frequency.



level oscillator

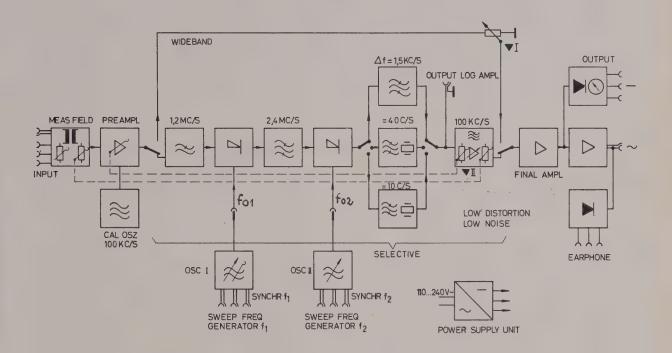
As the variable oscillator frequencies f₀₁ and f₀₂' in the level oscillator and level meter are the same, the level meter can be controlled from the transmitting oscillators or the level oscillator from the level-meter oscillators.

A built-in electronic regulating circuit keeps the transmiting level highly constant. The output level can be set between +10 and -75 dB (+1 and -7.5 Np) in 10 dB (1 Np) steps and finely.

The 13 octave wide frequency band is subdivided in the measuring field into an audio range from 0.2 to 5 kHz and a carrier-frequency range from 2 to 1600 kHz. In the audio range the internal impedances ~ 0 Ω and 600 Ω can be selected; in the carrier-frequency range ~ 0 , 75, 125, 134, 140, 150 and 600 Ω .

1.3.2 Level Meter

The level meter operates according to the superheterodyne principle with double frequency conversion. With selective measurements the frequency range extends from 200 Hz to 1620 kHz. For selective measurements in voice channels from 200 Hz on and pilot level measurements in the total frequency range up to 1620 kHz a particularly narrow filter is provided. Wideband measurements in the range from 200 Hz to 1620 kHz are possible when the heterodyne section is disconnected.



level meter

For wideband measurements the output amplifier follows the preamplifier. The measuring range for zero instrument mark extends from -60 to +20 dB (-7 to +2 Np). The highest sensitivity is given by thermal noise and the bandwidth of the input circuit.

To obtain even higher sensitivity, as is necessary for example in measuring crosstalk and stop-band attenuation of filters, the measuring bandwidth must be reduced. For this purpose a

heterodyne unit with double frequency conversion is interposed between preamplifier and output amplifier for selective measurements. The selectivity is determined by three optionally connectable filters of differing bandwidths.

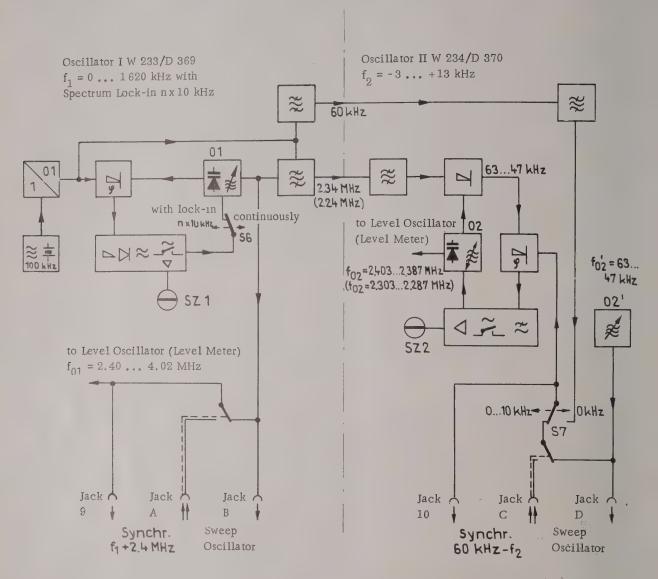
The level meter has a relatively wide filter (1.6 kHz Hz flat, 3.1 kHz between 3 dB points) for surveying and swept measurements, a filter with a bandwidth 40 Hz for point by point measurements and extremely low levels (10 Hz) for pilot level measurements. According to the measurements in hand, the "low-noise" and "low-distortion" operating options are provided to procude the greatest signal-to-noise ratio or the lowest residual distortion. With selective measurements the nominal deflection appears on the instrument when the input level is as low as -120 dB (-13 Np).

High frequency accuracy is achieved by means of a lock-in oscillator I and a finely tunable interpolation oscillator II. The oscillators have a common fundamental crystal and are extremely similar to the ones in the level oscillator.

The level meter has a balanced floating input and a coaxial single-ended grounded input. In addition either a high impedance input or an input terminated into the characteristic impedance of the specimen can be chosen by means of a transfer switch. The terminating impedance itself is adjustable to the usual values between 75 and 600 Ω . The actual input level can be considered by means of the level switch. Further the reading can be switched to voltage level or power level. Attenuation differences which arise with the switching from balanced to coaxial input and from the "low-distortion" to the "low-noise" mode and also with the transfer from voltage level to power level, are automatically taken into account the actual values being illuminated on the level switch — so that reading errors can be avoided.

In addition to the instrument indication there is a dc output for the connection of a graphic recorder or a scale-spreading device (PEGELLUPE). As a result of the high stability of the level meter measurements in terms of tenths of a percent can so easily be carried out. An ac output produces a level of 0 dB across 75 Ω for zero instrument mark. At the earphone output an audio-frequency modulated input signal can be monitored. Finally there is another output with a particularly high intensity range. Connected with the level tracer Type D 346 and the logarithmic amplifier slide-in chassis Type D 920 of the tracer the attenuation characteristic of a filter, for example, can be represented within a level range of 100 dB.

1.3.3 Oscillators I and II for Level Oscillator and Level Meter



The frequency data given in brackets refer to the os-cillators of the level meter

1.3.3.1 Oscillator I (spectrum oscillator) W 233 for the Level Oscillator W 231 and D 369 for the Level Meter D 354

Oscillator I (spectrum oscillator) produces the control voltage for the main modulators in the level oscillator and the level meter. It sweeps the frequency range $f_{01}=2.40$ to 4.02 MHz. When operating with spectrum lock-in, switch S6 in

"spectrum lock-in position n x 10 kHz", the output frequency of the oscillator can be set to all values n x 10 kHz with crystal accuracy. For this purpose it contains a 10-kHz crystal spectrum which is derived from a crystal-controlled 100-kHz oscillator. This 10-kHz spectrum is compared with the frequency of the oscillator 01 in a frequency regulating circuit.

A lock-in indicator (Sz 1) shows whether the frequency of O1 lies on or near a spectrum point. After disconnecting the frequency spectrum generator with switch S6, oscillator I can be also operated with continuous frequency control.

1.3.3.2 Oscillator II (Interpolator) W 234 for Level Oscillator W 231 and D 370 for Level Meter D 354

Oscillator II (interpolator) generates the signal voltage (f_{02} = 2.403 to 2.387 MHz) for the main modulator of the level oscillator, and the drive voltage (f_{02} = 2.303 to 2.287 MHz) for the second modulator of the level meter, respectively. It is continuously tunable in a range of 16 kHz so that every frequency between two spectrum points can be "interpolated" with an overlap. The frequency (f_{02}) of oscillator 02 is controlled by the interpolation oscillator 02' (f_{02} ' = 63 to 47 kHz). By means of a frequency regulating circuit the resultant frequency is the sum of the frequencies of the interpolation oscillator (f_{02} ') and the spectrum frequencies 2.34 MHz (level oscillator) and 2.24 MHz (level meter) respectively.

The interpolation frequency is nearly two orders of magnitude below that of the spectrum frequency used so that its absolute error corresponds approximately to that of the crystal-accurate spectrum frequency. Therefore the voltage produced by oscillator II has approximately the frequency accuracy of a crystal.

If desired, oscillator II can be set with crystal accuracy to the output frequency $f_{02} = 2.40$ MHz (2.30 MHz). To do so the interpolation oscillator is switched off at switch S7 and the 60-kHz frequency derived from the 10-kHz spectrum used as

control frequency for oscillator 02.

Oscillator II only operates in the "locked" position. This is shown on the main visual indicator, i.e. Sz 2 shows green.

1.3.3.3 Automatic Tuning

With selective operation of the level meter, automatic tuning for f_1 and f_2 permits single-knob frequency tuning. As a result either the level oscillator or level meter can be selected as the controlling device according to the measuring problem in hand.

Automatic Tuning for f1

For this, jack Bu 9 of the controlling device and jack Bu A of the controlled device must be interconnected. Then oscillator 01 delivers via jack Bu 9 the sync line and jack Bu A the control level for the main modulator of the controlled device. At the same time the spectrum oscillator of the controlled device is disconnected via the jack-operated contact with respect to RF.

Automatic Tuning for fo

The automatic tuning system for f_2 operates similarly to that for f_1 . As the output frequencies of the oscillators 02 in the level oscillator (2.403 to 2.387 MHz) and level meter (2.303 to 2.287 MHz) differ by 100 kHz, the second intermediate frequency of the level meter, synchronization is here effected in the frequency position of the oscillator 02' (f_{02} , = 63 to 47 kHz).

When the jack Bu 10 of the controlling device is connected to the jack Bu C of the controlled device the oscillator 02' is switched off.

The level received by jack Bu C now controls the frequency regulating circuit. The output frequency f_{02} of the controlled oscillator II is now offset by exactly 100 kHz from that of the controlling oscillator II.

1.3.3.4 Sweeping

By means of an electronic sweep device it is possible to sweep the level measuring setup within ±25 Hz to ±800 kHz. In this operation the measuring frequency changes in the form of a triangular function. The frequency sweep range, the mid-frequency and the sweep rate can be set according to the measuring problem in hand. The sweep equipment consists of a sweep attachment W 935/G 2022 ans various sweep oscillator slide-in chassis for adaptation to various level measuring setups. Two slide-in chassis are provided for the 1.6-MHz level measuring setup W 231/D 354:

sweep oscillator I $\,$ W 940 for sweeping the oscillators I $\,$ W 233/D 369 within a range of

 \pm 3 to \pm 800 kHz and

sweep oscillator II W 941 for sweeping the oscillators II W 234/D 370 within a range of

+ 25 Hz to + 3 kHz.

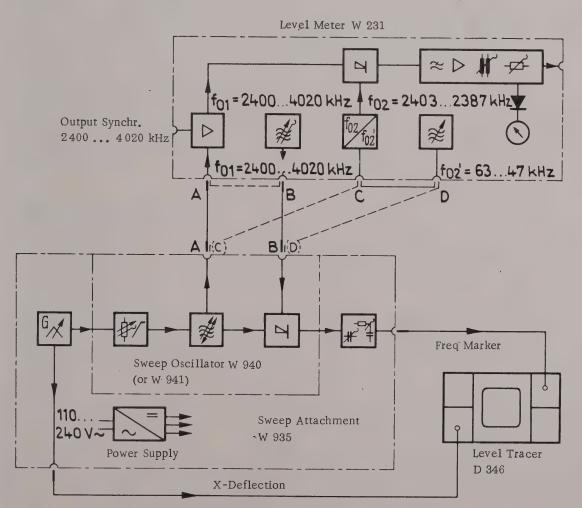


Fig. 3 Carrier-Frequency Sweep Measuring Setup
Functional Circuit Diagram

Fig. 3 shows the sweeping of the level oscillator. For wide sweeps of ±3 to ±800 kHz the sweep oscillator I W 940 delivers its output voltage at the jack Bu A of the level oscillator and thereby controls the main modulator of the oscillator. For RF, the level-oscillator spectrum-oscillator is separated from its basic device by the switching contact at jack Bu A, but still delivers its RF voltage via the jack Bu B into the sweep oscillator to produce a frequency marker for the level tracer.

For small sweeps of ±25 Hz to ±3 kHz the sweep functions in a similar way as for wide sweeps. The sweep attachment now contains the sweep oscillator W 941 which is connected to the level oscillator via the sockets Bu C and Bu D.

The frequencies and levels at the sweep terminals A,B,C and D of oscillators I and II of the level oscillator and level meter correspond. Therefore the level meter can be swept with the same sweep oscillators. A level meter extended in this way is said to be a panoramic receiver which, on the level tracer, shows the actual signal coverage on the swept frequency range.

Further information on the operation of the sweep measuring setup is contained in the description M 706.

1.4 Accessories, Dimensions and Weights

Description	Type	Dimensions in mm	Approx. Weight in kg
Level oscillator W 2 200 Hz to 1620 kHz	31		
-75 to +10 dB/dBm -7.5 to +1 Np/Npm	S45034-W23 1 -B302 S45034-W23 1 -B602		14.3 14.3
Accessories:			
2 coaxial connection cords	V42251-C113-A102	1000	0.3
Necessary for operat	ion:		
Oscillator I W 233 O to 1620 kHz	S45034-W233-A702	-	3
Oscillator II W 234 -3 to +13 kHz	S45034-W234-A702	-	3
Level meter D 354 200 Hz to 1620 kHz			
-130 to +20 dB/dBm -14 to +2 Np/Npm	S45034-D354-B302 S45034-D354-B602	556x326x307 556x326x307	16 16
Necessary for operat	ion:		
Oscillator I D 369 O to 1620 kHz	S45034-D369-A702		3
Oscillator II D 370 -3 to +13 kHz	S45034-D370-A702	-	3
Accessories on reque	<u>st</u>		
Connecting cords, balanced balanced coaxial 1.6/5,6; Z=75Ω	Rel ltg 546a to Rel ltg 703d to 1 V42251-C100-A117	h 1000 to 3000	0.2 0.2 0.3
Sweep attachment W 935,or G 2022 resp Level tracer D 346	see data bul- letin M 706	556x258x307 556x394x517	10 35



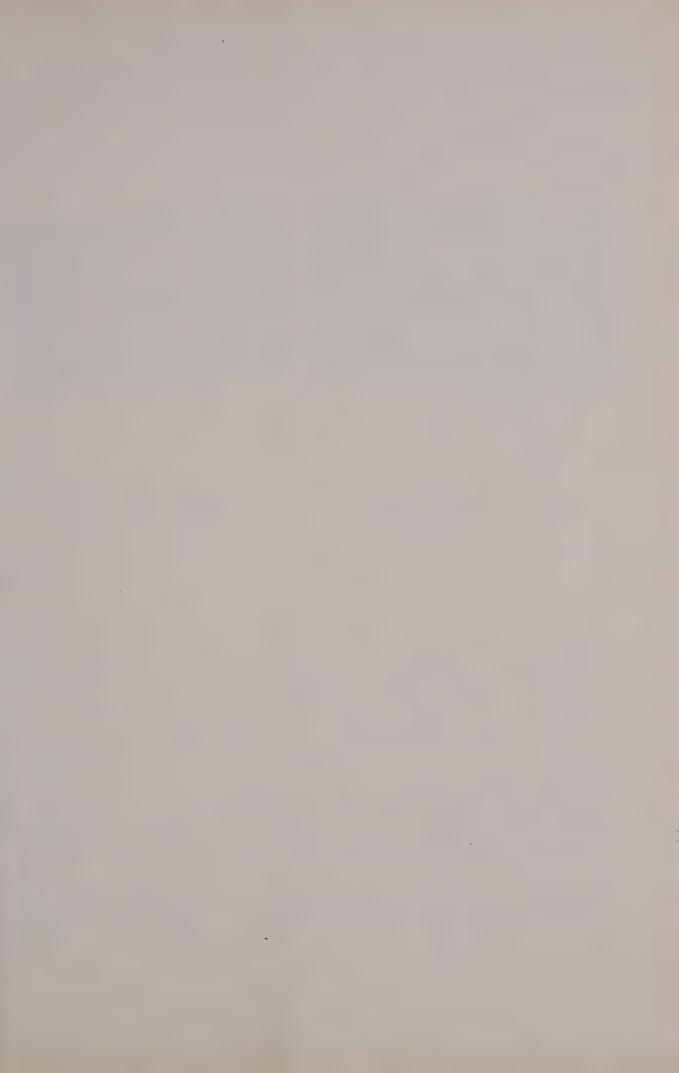






Fig.1 Level oscillator
W 231 with oscillators W 233 and
W 234

Level meter D 354 with oscillators D 369 and D 370

2.1 Preparation

The devices leave the factory for connection to a supply voltage of 200 V ac to 265 V ac, shown at the voltage selector S8 by "200 V". For other supply voltages between 100 V ac and 140 V ac the voltage adjuster S8, contained in the power supply jack, must be set in position "110 V".

If the device is to be used on 110 V, the 0.315-A fuse in the power supply assembly of the level meter should be changed for a 0.63-A fuse. This fuse is in the spares bag fastened to the chassis.

The power socket is on the back panel of the device. The connection to the mains is made via the power cord supplied.

The devices are, in accordance with the protective grounding safety regulations of the VDE (Association of German Electrical Engineers), insulated against excessive touch potentials.

2.2 Assembling the Measuring Setup

The measuring setup is preferably assembled as in Fig. 1.

2.3 Calibrating and Setting

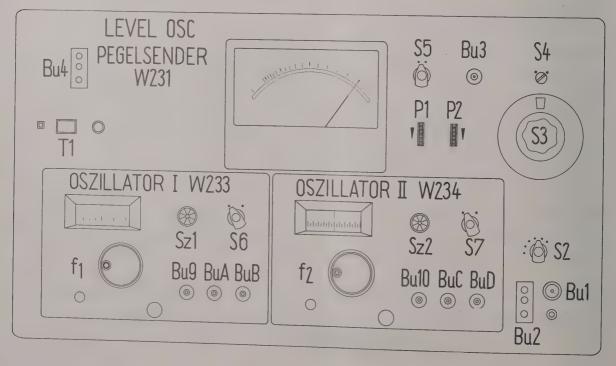
2.3.1 Level Oscillator

Connect the level oscillator to the ac mains and energize it with the power switch T1. The indicating lamp SL1 near T1 lights up for a check. The device is ready for operation immediately.

2.3.1.1 Setting the Frequency

The transmitting frequency is the sum of the settings of f_1 and f_2 of oscillators I and II.

At switch S6 of oscillator I the choice is made between "tuning, locked in spectrum steps n x 10 kHz" (when high frequency stability and accuracy are required) and continuous (for general measurements). At switch S7 of oscillator II the choice is made between continuous control "0 to 10 kHz" and the crystal-accurate spectrum lock-in point "0 kHz".



Then the following adjustments are possible:

S6: with spectrum lock-in n x 10 kHz, S7: 0 to 10 kHz

 f_1 -adjustment to the spectrum lock-in point directly below the transmitting frequency and then adjust f_2 for the total lacking amount.

S6: with spectrum lock-in n x 10 kHz, S7: 0 kHz gives crystal-accurate transmitting frequencies n x 10 kHz in the range 10 to 1620 kHz.

S6: continuous, S7: 0 kHz

With f₁ any frequency in the range 0.2 to 1620 kHz can be set. The variety of settings possible is important for general measurements, i.e. to find the pass band or attenuation poles of unknown specimens. For exact measurements proceed subsequently according to 1.1.

S6: continuous, S7: 0 to 10 kHz Possible settings as in 1.3 but additional fine setting with f_2 is possible.

Visual indicators Sz1 and Sz2 show the operation condition of the oscillators as follows:

Oscillator I		Oscillator II*	
Setting f ₁	Sz1	Setting f ₂ Sz2	
with spectrum lock-in n x 10 kHz on a spec-trum point	green	0 to 10 kHz green	
with spectrum lock-in n x 10 kHz between two spectrum points	red	0 kHz (crystal accurate) green	
continuous	green		

Note: When the devices are turned on or S7 transfers Sz2 attracts for approx. 0.4 s, i.e. shows red.

2.3.1.2 Setting the Internal Impedance

The internal impedance of the level oscillator is set to the Z-value of the specimen by the Z-switch S2. When doing this take note of the range limits of the audio (0.2 to 5 kHz) and carrier-frequency (2 to 1600 kHz) measuring fields.

For various measuring connections, a low-impedance source is advantageous: setting $Z \sim 0$ Ω . Take note that setting $Z \sim 0$ Ω in the carrier-frequency range is loaded with $Z \triangleq 75$ Ω and in the audio range with $Z \triangleq 600$ Ω .

2.3.1.3 Voltage or Power Level

The calibration of the level oscillator can be switched from voltage level (0 dB/Np corresp. to $V_{\Omega}=0.775$ V) to power level (0 dBm/Npm corresp. to $P_{\Omega}=1$ mW/across Z) by means of Switch S4.

2.3.1.4 Setting the Transmitting Level

With S3 the transmitting level can be set in 10-dB (1-Np) steps and with the fine control P1 the intermediate values can be set by reference to the instrument. In the automatic level control mode (S5: ON), "Level Fine" control P2 affords an additional control of the output level over a vernier range of approx. $\pm 0.5 \, \mathrm{dB}/\pm 0.05 \, \mathrm{Np}$.

2.3.1.5 Level Regulation

The built-in level control can be disconnected at switch S5: necessary for measurements with amplitude modulation. For all other measurements set S5 on "On".

2.3.1.6 Modulation

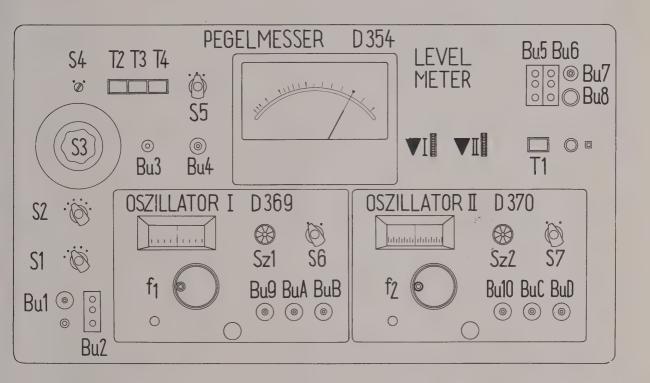
By applying an ac voltage having a frequency of up to 20 kHz to jack 4 the output signal can be amplitude modulated. For this S5 should be in position "Off". A modulating voltage of approximately 3 V rms is required for 100% modulation. The input impedance of the external modulation device is about 5 k Ω .

2.3.1.7 Connection of a Frequency Counter

Jack 3 is provided for the connection of a frequency counter. With a load of $\stackrel{>}{=}$ 10 k Ω and zero instrument indication there is an output voltage of approx. 1 V rms at jack 3.

2.3.1.8 Expansion to the Sweep Measuring Setup

For the required details refer to the Full Information on the attachments.



2.3.2 Level Meter

Connect the level meter to the ac mains and energize it with the power button T1. For verification the indicating lamp SL1 near T1 lights up. The device is immediately ready for operation.

2.3.2.1 Level Calibration

The settings for wideband and selective calibration are independent of each other, without any interaction. Before calibration the mechanical zero of the instrument (- ∞ on the scale) should be checked with the device energized.

Calibration " ▼I" for Wideband Measurements

S3: left stop in position "▼"

T2: depressed

Then adjust the instrument pointer with the knurled knob " ▼I" (near the instrument) to the red calibrating mark.

Calibration " ▼II" for Selective Measurements

During the calibrating procedure no plugs must be in the jacks A and C.

S3: left stop in position "▼"

S5: choose desired pass band width, see 2.3.2.4.

S6: with spectrum lock-in n x 10 kHz

f₁: with spectrum lock-in 100 kHz S7: "VII, 0 to 10 kHz"

T3 or T4: depress

With the frequency control for maximize the meter reading (calibration 100 kHz), then adjust the knurled knob "▼ II" for deflection to the red calibrating mark.

2.3.2.2 Input Impedance of the Level Meter and Termination of the Specimen

By means of switches S1 and 32 the input impedance of the level meter can be selected and matched to the Z-value of the specimen. With S1 either the coaxial input jack 1 or the balanced input jack 2 is selected. In the positions "Z" of S1 the inputs are terminated into the values set at the Z-switch S2. In a further position of the switch S1 the input impedance of the level meter is 10 k Ω | 60 pF with coaxial input and > 10 k Ω with balanced input (see electrical values, page 5).

These positions are used for measurements on specimens or systems which are already terminated into their characteristic impedances.

2.3.2.3 Voltage or Power Level

The calibration of the level meter can be switched from voltage level (0 dB/Np corresp. to $V_0 = 0.775$ V) to power level (0 dBm/Npm corresp. to $P_0 = 1 \text{ mW/across Z}$) by means of switch S4.

2.3.2.4 Choice of Pass Band Width

For adaptation to various measuring problems three band widths can be selected by means of switch S5.

Bandwidth 1600 Hz (3-dB-down bandwidth ~ 3.1 kHz) for general and sweep measurements in the frequency range 10 to 1620 kHz;

Bandwidth 40 Hz (3-dB-down bandwidth ~80 Hz) for exact measurements and for suppression of interfering voltages when utilizing full sensitivity with sweeping in the frequency range 2 to 1620 kHz;

Bandwidth 10 Hz (3-dB-down bandwidth 20 Hz) for separating frequencies lying very close together, e.g. pilot level measurements and for measurements in the VF channels.

Frequency range 200 Hz to 1620 kHz.

2.3.2.5 Signal-to-Noise Ratio (T3: low-distortion, T4: low-noise)

Special applications, such as the presentation of curves on the screen of a level tracer or the increasing of the relative measuring accuracy by means of a scale-spread attachment B 977 require a signal-to-noise ratio as large as possible. It is at its largest when key T4 "low-noise" is depressed. This position should be used for all customary measurements. Depress key T3 "low-distortion" only when the sensitivity is to be further increased (a lamp no longer lights up in the "Koramat" unit) or when measuring distortion. In the low distortion mode, a pass band width of 40 Hz, or for the audio range 10 Hz, should be selected.

2.4 Measuring

2.4.1 Wideband Level Measurements

Level oscillator: set as in 2.3

Level meter: after setting the switches S1 and S2 to the required input impedance and the line system (coax lor balanced) and S4 to the calibration for voltage level (dB,Np) and power level (dBm,Npm), respectively, connect the specimen to the input via a shielded line. Depress T2 "wideband". Set

the range switch S3 to a range in which the pointer of the instrument is well up-scale, if possible. The unknown level is found by adding the value shown in the illuminated window of the level range switch ("Koramat") and the instrument reading. If no lamp of the level range switch lights up any longer, the measuring range for wideband measurements has been exceeded.

2.4.2 Selective Measurements (without automatic tuning)
Level oscillator: setting as in 2.3.

Level meter: settings S1, S2, S3, and S4 as for wideband measurements. Depress key T4 or T3, respectively, when maximum sensitivity is required (see 2.3.2.5).

First set S6 to continuous, S7 to 0 kHz and S5 to bandwidth 1600 Hz (note 2.3.2.4). Slowly turn f₁ through the related frequency range until a deflection appears. Tune frequency for maximum deflection. Set sensitivity with S3 so that the pointer of the instrument is well up-scale.

Level reading as with wideband measurements:

Sum of the values shown on the range switch and the instrument. If the measuring frequency is to be accurately determined set S6 to "with spectrum lock-in n x 10 kHz", S7 to "0 to 10 kHz" and S5 to 40 Hz or 10 Hz. Set the f_1 tuning control to the spectrum point lying directly under the measuring frequency so that Sz1 shows green. Then tune f_2 for maximum instrument indication. The frequency of the unknown voltage then equals the sum of the settings $f_1 + f_2$.

2.4.3 Distortion Attenuation Measurements

In the "selective" range the level meter is also suited for measuring low distortion factors down to 0.1% (60 dB or 7 Np distortion attenuation). If the sensitivity is increased by 60 dB (7 Np) the residual distortion attenuation of the level meter is \$\geq\$ 80 dB (9 Np) and is independent of the fundamental level at the preamplifier and main modulator. Depress key T3

"low-distortion" for measuring distortion attenuation. Select pass band width 40 Hz or, for frequencies below 2 kHz, 10 Hz. For determining the distortion attenuation the fundamental level (f_m) must first be measured. Then the instrument is tuned to the respective harmonics $2\mathbf{x}f_m$, $3\mathbf{x}f_m$ etc. with a corresponding increase in sensitivity by means of switch S3. The difference, in logarithmic measure, between the fundamental level and the harmonic level is the distortion attenuation a_{kn} for the respective (n-th) harmonic.

When measuring the harmonic level it should be noted that the sensitivity must not be increased by more than 60 dB (7 Np) with S3 as compared with the setting for measuring the fundamental level. As long as an increase of the sensitivity with S3 brings about a correspondingly greater deflection on the instrument it is certain that the harmonic shown is really due to the measuring voltage and the instrument is operating in its linear range.

From the distortion attenuation a_{kn} the distortion factor k_n for the n-th harmonic can be calculated as a percentage as follows:

$$k_n = 100 \times 10^{-\frac{a_{kn}}{20}}$$
 in % for a_k in decibel $k_n = 10 - e$ in % for a_k in neper

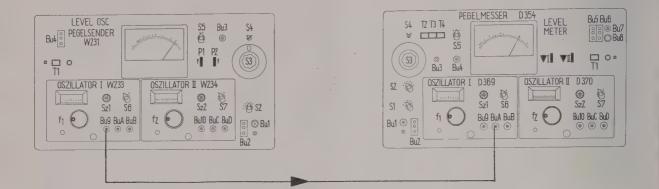
For distortion attenuations of $a_{kn} > 20$ dB the distortion factor of the measuring level is calculated as follows:

$$k = \sqrt{k_2^2 + k_3^2 + \dots k_n^2}$$
 in %

2.4.4 Measurements with Automatic Tuning

Select the bandwidth with S5 according to the measurement problem. If difficulties should arise with the 10-Hz filter in circuit, note point 3.4 in the Maintenance Instructions.

Setting the Frequency on the Level Oscillator Automatic Tuning for f₁

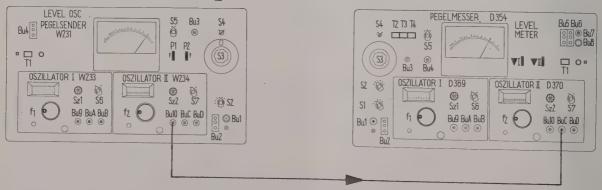


Before beginning measurements set the pointer to a maximum with $\mathbf{f}_2 \, \boldsymbol{\bullet}$

For f₂ = 0 kHz set S7 at the level oscillator and level meter to 0 kHz.

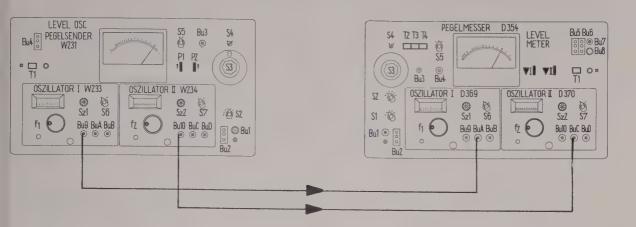
Set the frequency at the level oscillator with f1 only.

Automatic Tuning for f2



For quadripole measurements set f_1 at the level oscillator and level meter to the same frequency and thereby switch S6 to "with spectrum lock-in n x 10 kHz". Set switch S7 at oscillator II of the level meter to position "O to 10 kHz".

Automatic Tuning for f1 and f2



Settings at the level oscillator:

Frequency settings f₁ and f₂

S6: either "with spectrum lock-in n x 10 kHz" or "continuous"

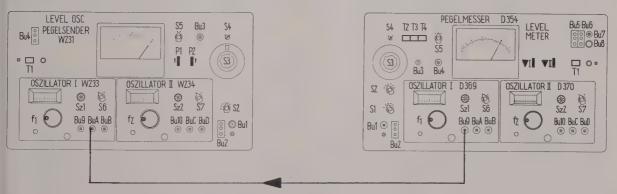
S7: either "O to 10 kHz" or "O kHz"

Settings at the level meter:

S7: "0 to 10 kHz"

Frequency Settings at the Level Meter

Automatic Tuning for f

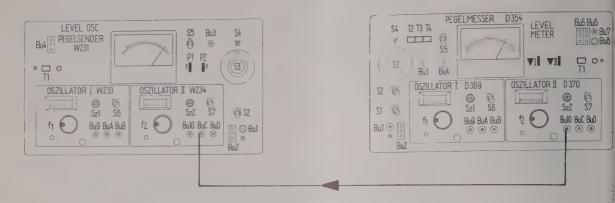


Before beginning measurements adjust f₂ for maximum pointer deflection.

For f₂ = 0 kHz set S7 at the level oscillator and level meter to "0 kHz".

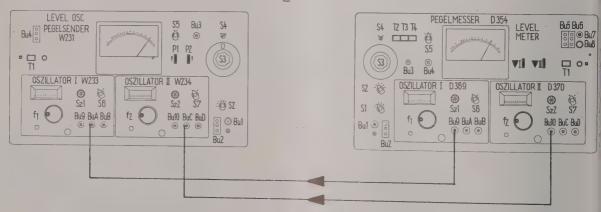
Set the frequency at the level meter with f₁ only.

Automatic Tuning for f2



For quadripole measurements set f_1 at the level oscillator and level meter to the same frequency and thereby switch S6 to "with spectrum lock-in n x 10 kHz". Set switch S7 at oscillator II of the level oscillator to position "0 to 10 kHz".

Automatic Tuning for f1 and f2



Settings at the level meter:

Frequency settings f1 and f2

S6: either "with spectrum lock-in n x 10 kHz" or "continuous"

S7: either "0 to 10 kHz" or "0 kHz"

Settings at the level oscillator:

S7: "0 to 10 kHz"

2.4.5 Automatic Tuning with Other Carrier-frequency Measuring Devices in the Frequency Range up to 1.6 MHz

Automatic Tuning from the Digital Level Oscillator G 2001/G2004

The digital level oscillators G 2001 and G 2004 produce a synchronizing voltage at the jack "Bu 1 f₁ + 2.4 MHz" with which oscillators I of the level oscillator or level meter can be controlled. Oscillators II must be set to "O kHz" by means of switch S7.

Automatic Tuning in the Case of the 1.6-MHz Measuring Setup W 221/D 344

The tuning condition for f₁ of the level oscillator W 221 or level meter D 344 can be controlled by oscillator I of the level oscillator or level meter (jack 9). In level oscillator W 221 jack Bu A is the input jack for the sync voltage, in the level meter the jack "Sync.f₁ + 2.4 MHz".

2.4.6 Using the Level Meter as a Detector Amplifier

The level meter can be used as a wideband or selective detector amplifier. All settings on the level meter are effected as for wideband or selective measurements. At jack Bu 7 with termination into Z = 75 Ω and zero instrument indication there is an output level of 0 dB/Np. With wideband operation the frequencies of the input and output voltage are equal, with selective operation the second intermediate frequency $f_{\rm IF2}$ = 100 kHz is produced.

2.5 Accessories

2.5.1 Voltage Recorder 3 V/30 $k\Omega$ (100 μ for full-scale deflection)

Connect the voltage recorder to the jack Bu 6 "Output" between the a- and c-wires. Insert a dummy plug in the b-wire (to operate a switching contact on the jack).

2.5.2 Current Recorder 77.5 $\mu A/2.5 k\Omega$

Connect the recorder to jack Bu 6 "Output" between the aand b-wires. Wire c is connected to chassis.

UNIREG S is, for example, a suitable recorder, with a terminating resistance R - 2.5 k Ω .

2.5.3 Connection of Scale-spread Device B 977

Connect the scale-spread device B 977 via a balanced cord to jack Bu 6. While the level meter reads -8 to +2 dB/ -0.9 to +0.2 Np adjust the deflection of the scale-spread device also to 0 dB/Np with the zero point control. Level increments between +0.02 and +1 dB (+0.002 and +0.1 Np) can then be read. To improve the signal-to-noise ratio with selective measurements depress key T4 "low-noise".

2.5.4 Headphone Output, Jack Bu 5

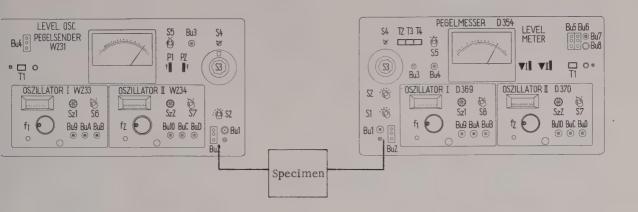
When measuring an amplitude-modulated input voltage there is a demodulated VF signal at jack Bu 5.

2.5.5 Connection of Level Tracer D 346

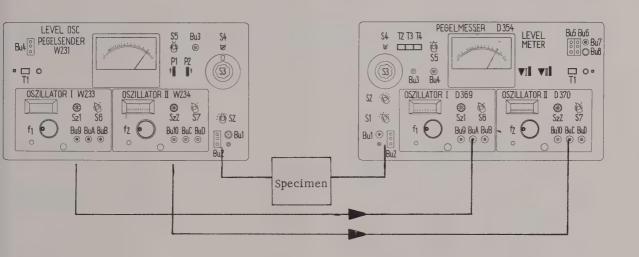
For measurements with level differences up to about 10 dB the wideband amplifier slide-in chassis D 918 of the level tracer is connected via a coaxial cord to jack Bu 7 of the level meter. Level meter and level tracer can be calibrated together so that absolute measurements are also possible.

To display level differences of up to 100 dB/11 Np, the logar-ithmic amplifier D 920 is connected to the ac output Bu4 (IF = 100 kHz). S3 must be set to the positions marked with a red spot.

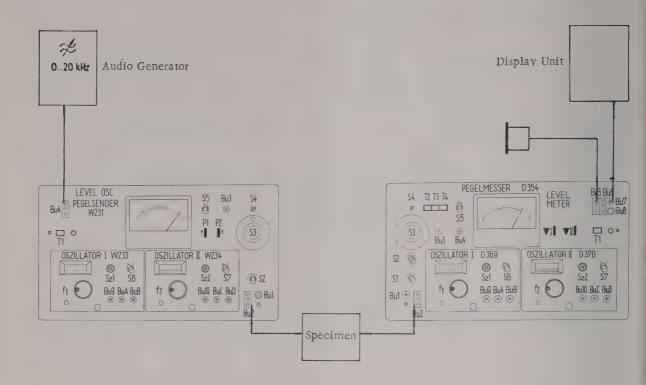
2.6 Typical Measuring Setups



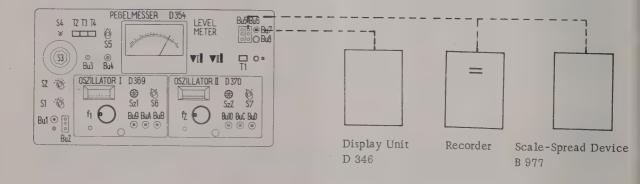
2.6.1 Wideband and Selective Level, Attenuation and Gain Measurements



2.6.2 Selective Level, Attenuation and Gain Measurements with Automatic Tuning f₁ and f₂ from the Level Oscillator



2.6.3 Measurements with Amplitude-modulated Transmitting Level and Monitoring with Headphone and Display Unit



2.6.4 Connection of Accessory Devices to the Level Meter (level tracer, recorder and scale-spread device)

3. NOTES ON MAINTENANCE

The devices contain components of high reliability and long useful life. Silicon transistors are used as active elements. As a result regular maintenance and scheduled supervision are not necessary.

3.1 Switches

The switches used are self-cleaning and require no special maintenance. Contact surfaces should never be treated with fat or grease-dissolving agents.

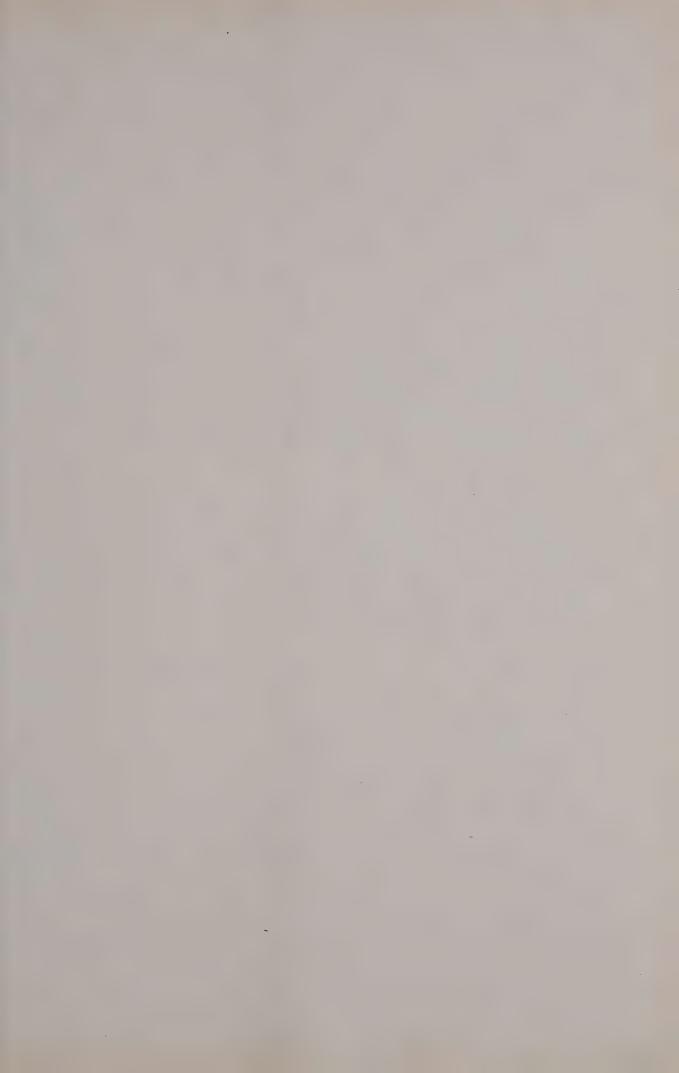
3.2 Replacing Indicating Lamps

for power and measuring-range indication

The indicating lamps have bayonet sockets: they can be removed by pushing in slightly, combined with a slight twist to the left. Use the lamp extractor contained in the spares bag (secured inside the device). All indicating lamps are accessible from the outside.

For replacing lamps in switch S3 unscrew the dial knob and the grey cover plate. When replacing these parts the left red ∇ sign, at the left stop of S3 and S4, must be above the right transparent window.







The film drive is of rugged construction and requires no maintenance. The film tape which carries the scale divisions, individually applied by a photographic process, consists of particularly strong and permanent plastic special foil (Dupont Cronar Film No. 225 B 35) for the purpose of ensuring greatest accuracy in setting the frequency. Under normal conditions therefore, trouble need not be anticipated. Should a fault nevertheless occur, take down the film cassette with care, following the instructions given below and detect the fault. Never attempt to move the drive by using force. Should the film have been damaged, then insert the spare film by following these instructions. We recommend that the piece of negative film supplied with the equipment is forwarded to our works for making a new spare film after the removal of the spare film.

If the transport band (Fig. 4) has been torn, order a replacement under the order description of "Transport Band C44106-A7-C109 with 2 clips C44106-A7-C110". When placing the band in position, make sure that the lettering on the inner surface of the band is legible; insert the two clips into the overlapping perforations

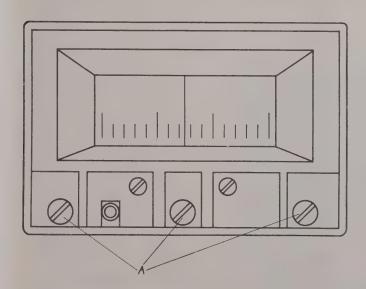


Fig. 1 Film guide

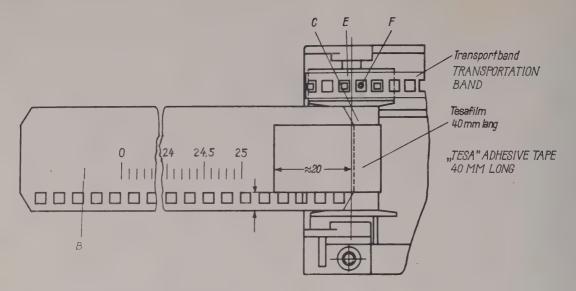


Bild 2 Ankleben des Filmband-Endes

FIG. 2 CEMENTING THE END OF THE FILM BAND IN POSITION

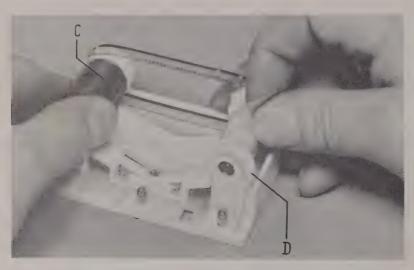


Bild 3 Ankleben des Filmband-Anfangs

FIG.3 CEMENTING THE START OF THE FILM BAND IN POSITION

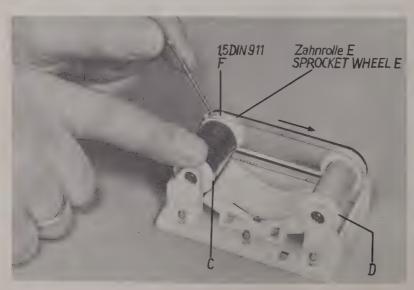


Bild 4 Lösen der Vorspannungs-Arretierung

FIG.4 RELEASING THE DETENT OF THE MECHANICAL BIAS

from inside and bend over. As the initial tension of the film rollers is lost when replacing the transport band, the film must also be inserted again in accordance with the instructions.

Taking Down the Film

- 1. Either the film cassette is accessible from the front of the unit or the unscrewing of only a partial front name plate or front name plate is required.
- 2. Turn film drive, if possible, as far as the left-hand stop (beginning of scale), failing this, roll the film by hand on to the left-hand roller after taking down the film cassette. (point 4).
- 3. Slacken fixing screws (A) of the film guide and pull out the film guide towards the front (Fig. 1).
- 4. Wind film completely on to roller C and detach adhesive strip from roller D (Fig. 3).
- 5. Unwind film from roller C and detach adhesive strip from roller C.Carefully remove any residue of adhesive from the rollers.

Inserting the New Film

The spare film must be rolled in such a manner that the lettering for the high frequencies is legible from the outside. Remove dust particles from the film guide with a soft brush, the proceed as follows:

- 6. Grasp roller C, turn sprocket roller E four turns counterclockwise (the equalizing spring in roller C is tensioned during the process) and lock in this position by tightening the set screw F with an hexagon socket spanner 1.5 DIN 911, Fig. 4.
 - 7. Stick adhesive strip (40 mm x 19 mm), e.g. "Tesafilm" adhesive strip, order No. 5859, Messrs. Beiersdorf, Hamburg, on to the legible end of the film in such a manner that 20 mm are left projecting (Fig. 2).

- 8. Stick end of film on to roller C (Fig. 2). The edge of the film must be parallel with the edge of the roller after glueing.
- 9. Roll film tightly on to roller C (Fig. 3) and grip until point 11 has been carried out.
- 10. Slip end of film (beginning of scale) only as far through the bearing support and stiffening piece until it can be taughtly glued on to the roller D.
- 11. Stick film on to roller D as described under points 7 and 8 (Fig. 3).
- 12. Slacken set screw F (Fig. 4). Spring tension must now be felt. If roller C is gripped and sprocket roller E given a quarter turn anticlockwise, the sprocket roller must return to its initial position when being released.
- 13. Turn one of the sprocket rollers until the first unlettered scale mark coincides exactly with the graduation mark in the scale window. (This mark designates the mechanical stop of the film drive).
- 14. The film drive must be at the left-hand end stop.
- 15. Insert film guide carefully without exerting pressure and note whether the film perforations drop into the sprocket.
- 16. Uniformly tighten the three fixing screws (A) of the film guide.
- 17. Verify for a second time that the film has been inserted correctly by checking the frequency calibration.

4. FAULT LOCATION

4.1 FAULT LOCATION ON THE DEENERGIZED DEVICE

- 4.1.1. As a first step check the measuring setup. Examine all connecting and interconnecting cords for a firm seat of their connectors and satisfactory condition (for instance transition resistance for wires and shield).
- 4.1.2. Check whether possibly an operating error has been committed on one of the equipment units associated with the measuring setup.
- 4.1.3. Make a visual examination.

4.2. FAULT LOCATION ON THE ENERGIZED DEVICE

Caution: When connecting the exposed chassis to the mains, observe the safety regulations (for instance in Germany those of the VDE (Association of German Electrical Engineers) for rooms with electrical equipment)).

Entrust such work to skilled personnel only.

4.2.1. General Information

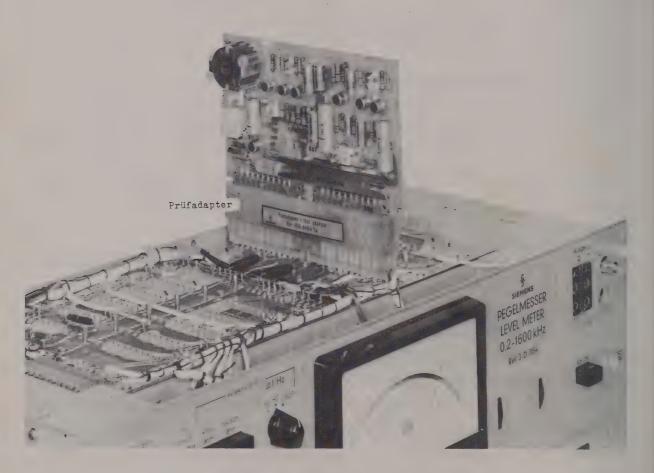
The main information for fault locating includes the circuit diagrams with entered measured values in the Circuit Diagrams part and the 'Fault Elimination' part, as well as the test plan (annexed Figs. 1 and 2). If the actually observed kind of fault is mentioned in the following fault location table, a course of action according to the information given there often considerably reduces the fault location time. Observations made by the user may be entered at the end of these tables. We would appreciate very much to receive such supplements and are gladly prepared to duplicate them for the benefit of others.

All dc and ac voltage values specified in the circuit diagrams are averages taken from measurements with the measuring instruments enumerated on pp. 4-6 of the Fault Elimination. Unless specific tolerances are stated, the error of the indicated measured values is about + 15%.

Finding out the subassemblies, individual components and measuring points is facilitated by the wiring diagrams, marked by "7402" in the last four data positions, e.g. wiring diagram for the

level meter S45034-D354-B602-*-7402.

All plug-in circuit boards in the 'level oscillator' and 'level meter' mainframes and in the oscillator plug-ins can be operated outside the chassis by way of the test adapter D640 contained in the mainframe. For this purpose the circuit board is taken out of the holder and placed onto the test adapter screwed onto the interconnecting conductor board. This greatly facilitates fault locating in a circuit board since good access to the individual components and foil patterns is attained.



Typical application of the test adapter D 640 (Prüfadapter = Test adapter)

The test points marked on the interconnecting adapter boards also greatly facilitate the locating of a defective subassembly. If a detected fault cannot be remedied by the user himself, it will mostly suffice to return the defective circuit board to the factory.

4.2.3. FAULT LOCATION TABLE FOR LEVEL METER D354 WITH OSCILLATOR I D369 AND OSCILLATOR II D370

Type of Fault "VI", "VII" and measuring wideband (T2 pushed) and selective (T3 or T4 pushed) are not possible

Fault Location According to annexed Fig. 1

Measuring selective (T3 or T4 pushed) and "▼II" are not possible

According to annexed Fig. 2

"VI" and "VII" are not possible, but an externally applied test level is correctly indicated

The measuring range switch S3 fails to switch the level steps properly in wideband measuring (T2 pushed)

The measuring range switch S3 fails to switch properly the level steps in selective measuring and in the 'lownoise' measuring mode (T3 pushed)

The measuring range switch S3 fails to switch properly the level steps in selective measuring and in the 'low-noise' fier D647 must have operated measuring mode (T4 pushed), while in wideband and selective 'low-distortion' measurements range switching is in order

Check the circuit board 'calibrating oscillator D641'; the calibrating voltage -40 dB (-5 Np) can be measured at jack Bu3 with a level meter of high impedance

Look for the fault in the measuring panel D630 according to the circuit diagram; in so doing check the resistive input dividers and the feedback preamplifier D636

Look for the fault in the input divider of the input subassembly D631 (A- and B-relays) and on the voltage dividers in the 100-kHz amplifier D647

Relays A and B in the measuring field must have dropped out, relay K in the 100-kHz preampli-

Type of Fault

No output level is present at measuring output jack Bu7 with full-scale deflection of the instrument

Indication depends strongly on the mains voltage

In f₁-synchronization of the level oscillator from the level meter there is no indication on level oscillator and level meter

In f₂-synchronization of the level oscillator from the level meter there is no indication on the level meter

The frequency departure of the fo-scale exceeds 30 Hz

Fault Location

Check board 9 'power amplifier and demodulator D649'

Indication depends strongly Check board 10 'power supply II'

Measure the voltage at jack Bu9 with RF Multizet meter, nominal value: 0.27 V across 75 Ω

Set the frequency tuning control f, on level meter and level oscil lator to the same lock-in point. Measure the voltage at jack Bu10 with the RF Multizet meter. nominal value: 0.78 V across 600 A. Move switch S7 on the level oscillator to the position "0-10 kHz". Select a pass-band width of 40 Hz or 1600 Hz with switch S5 on the level meter. If a pass-band width of 10 Hz is required (frequency range 200 Hz - 2 kHz), observe p. 32, Section 3.4. of the Notes on Maintenance. Set the following on the level meter: S3 OdB (dBm, Np, Npm), T4 pushed, S5 10 Hz, f₁ OkHz, S6 'in spectrum steps', f 0 kHz, S7 0-10 kHz. Alignment by means of C2 for maximum meter deflection.

5. FAULT ELIMINATION

5.1. GENERAL INFORMATION

The basis of the fault elimination work is the circuit diagrams, wiring diagrams and parts lists. Particular care must be exercised in replacing defective parts on etched circuitry. If no soldering iron with suction ficility is available for unsoldering a component, the respective component had better be cut out of the circuit and subsequently unsolder the remaining terminal wires individually. In this way damage of the foil pattern can be avoided. When soldering temperature-sensitive components such as semiconductors, Styroflex capacitors and small carbon-film resistors in the circuit, protect them with flat pliers from thermal destruction.

In addition to individual information the following sections give instructions for aligning and the checks to be carried out in the individual subassembly after repairs.

5.2. TESTING INSTRUCTION AND FAULT ELIMINATION ON THE LEVEL METER D354 WITH OSCILLATOR I D369 AND OSCILLATOR II D370

This instruction describes all essential checks for examining the electrical data and gives the respective information for fault elimination. To remedy a recognized fault, only those sections need to be observed to which reference is made in the FAULT LOCATION part.

Measuring Instruments Required

- 1 frequency counter for up to 4 MHz, error + 1 \times 10⁻⁶
- 1 dc multi-range meter Zi = 50 k Ω /V e.g. Siemens /uA-Multizet meter
- 1 digital voltmeter
- 1 calibrating level meter for checking the O-dB (dBm, Np, Npm) marks
- 1 attenuator, e.g. D120
- 1 variable low-pass filter
- 1 level oscillator 200 Hz 1.6 MHz, e.g. W231
- 1 level oscillator W518 or W2006
- 1 level scale-spread device B 977
- 1 variable power supply for setting the primary input voltage

5.2.1. CHECKS ON THE OSCILLATOR I D369

5.2.1.1. Checking the Frequency Scale

Required settings: push the button T3 or T4

switch S6 "continuous"

all other control elements arbitrary.

Connect the frequency counter by way of a coaxial connecting cord to jack Bu 9. The measuring frequency shall be equal to the sum of the frequency f_1 set on the film drive plus 2.4 MHz. If the need arises, make a correction at f_1 = 1.6 MHz (corresponds to 4 MHz on the frequency counter) by means of trimmer C1.

5.2.1.2. Checking the Output Level at the Jacks Bu 9 and Bu B Required settings: push the button T3 or T4

switch S6 "continuous" all other control elements arbitrary.

Terminate the RF Multizet meter into 75 Ω and measure the output voltage at the jacks Bu 9 and Bu B in the frequency range $f_1 = 0-1.6$ MHz.

Nominal value: 0.27 V + 10 %

5.2.1.3. Checking the Carrier Voltage for the Main Modulator on the Clip-contact Strip e1,2-e3,4 (1)

Required settings: push the button T3 or T4
switch S6 "continuous"
the positions of all other control elements
are arbitrary.

Connect the RF Multizet meter to the clip-contact strip e1,2-e3,4 ($^{\perp}$) and measure the carrier voltage in the frequency range f_1 = 0-1.6 MHz.

Nominal value: 0.27 V + 10%

5.2.1.4. Checking the Synchronization Input Jack Bu A

Required settings: switch S3 at " "

push the button T3 or T4 switch S5 at 1600 Hz $f_1 = 100 \text{ kHz}$ $f_2 = 0 \text{ kHz}$ switch S6 at "in spectrum steps"

switch So at "In spectrum steps" switch S7 "O kHz"

The level meter must now read the calibrating level. Using the calibration control " \P II" set nominal deflection on the instrument. When a coaxial cable is connected to jack A the meter reading must drop to $-\infty$.

When feeding a level of - 9 dB (-1 Np, 0 dBm/75 Ω) with the frequency f = 2.5 MHz into the jack A the level meter D354 must again read the previously set level. If such is not the case, check the contact spring sets at jack A.

5.2.1.5. Checking the Holding and the Pull-in Range

Required settings: push the button T3 or T4
switch S6 at "in spectrum steps"
the positions of all other controls are arbitrary.

The visual indicator Sz1 for lock-in indication must show "green" (no current) when the frequency control f_1 is set to a lock-in point n×10 kHz. If the film drive stands between two lock-in points, the visual indicator Sz1 must show "red" (current flows).

The holding range is that range where during slow rotation of the film drive to the left and right from a lock-in point, the visual indicator remains off, showing "green". Within this range the output frequency is always adjusted to this lock-in point. The holding range shall be about ± 1.8 kHz.

The pull-in range is that range within whose limits the AFC circuit 'pulls-in' the frequency, e.g. the visual indicator Sz1 restores to show "green". The pull-in range shall be about \pm 1.2 kHz symmetrically about the lock-in point. If the need arises, align R 13 in the spectrum oscillator board 2 W 668 in a way that, with the frequency control f_1 between two lock-in points (Sz1 red), a dc voltage of 5.6 V is measured at the collector of transistor Ts5.

5.2.1.6. Accuracy of the 100-kHz Crystal

Required settings: button T3 or T4 pushed

switch S6 at "in spectrum steps"

 $f_1 = 4 \text{ MHz}$

the positions of all other control elements are arbitrary.

The output frequency can be measured with a frequency counter connected to jack Bu 9.

Nominal value: $4,000,000 \pm 40 \text{ Hz}$

If an alignment is necessary, use the trimmer C1 in the spectrum oscillator board 3 W669.

5.2.2. CHECKS ON THE OSCILLATOR II D370

5.2.2.1. Checking the Frequency Scale

Required settings: button T3 or T4 pushed

switch S7 "0 - 10 kHz"

the positions of all other controls are arbitrary.

Connect a frequency counter to jack Bu 10 by way of a coaxial cord. The measuring frequency f_{02}^{\prime} shall be equal to the difference

of 60 kHz and the set frequency f_2 , e.g. $f_2 = 0$ kHz corresponds to $f_{02} = 60$ kHz, $f_2 = 10$ kHz corresponds to $f_{02} = 50$ kHz. In the case of deviations in excess of \pm 30 Hz effect an alignment with trimmer C2, if the need arises a coarse alignment with trimmer C¹O in the interpolator board 1 W671 should be made.

5.2.2.2. Checking the Output Level at the Jacks Bu 10 and Bu D Required settings: button T3 or T4 pushed

switch S7 "0 - 10 kHz"

all other control elements arbitrary.

Terminate the RF Multizet meter into $600\,\text{M}$ and measure the output voltages at the jacks Bu 10 and Bu D in the frequency range $f_2 = -3$ to 13 kHz. Nominal valueß 0.78 V \pm 10%

5.2.2.3. Checking the Carrier Voltage for the Converter 2.4 MHz/100 kHz at the Clip-contact Strip f_{30,31}-f_{28,29}(1)

Required settings: button T3 or T4 pushed

switch S7 "0 - 10 kHz"

the positions of all other controls are arbitrary.

Connect the RF Multizet meter to the clip-contact strip $f_{30,31}$ - $f_{28,29}$ (1) and measure the carrier voltage (f_{02} = 2.303 - 2.287 MHz) in the frequency range f_2 = -3 to 13 kHz. Nominal value: 0.27 V \pm 10%

5.2.2.4. Checking the Synchronization Input Jack Bu C

Required settings: button T3 or T4 pushed

switch S7 "0 - 10 kHz"

the positions of all other controls are arbitrary.

When a coaxial cable is connected to jack C, the visual indicator Sz 2 must operate, i.e. show "red".

When feeding a level of 0 dB (0 Np, 0 dBm/600 Ω) at a frequency of 60 kHz the visual indicator Sz2 must restore, e.g. the display becomes "green".

5.2.2.5. Checking the AFC Circuit

Required settings: button T3 or T4 pushed switch S7 "0 - 10 kHz"

the positions of all other controls are arbitrary.

When feeding a level of 0 dB (0 Np, 0 dBm/6001) in the frequency range of 40 - 70 kHz the visual indicator Sz 2 must remain off (green).

5.2.2.6. Checking the Lock-in Point O kHz

Required settings: button T3 or T4 pushed

switch S7 "0 - 10 kHz"

the positions of all other controls are arbitrary.

Connect the frequency counter to jack Bu 10 and measure the output frequency.

Nominal value: 60,000 + 0.6 Hz

In measuring, the time basis on the frequency counter must be set to 10 sec.

When the above tolerance is exceeded, proceed as under Item 5.2.1.6.

5.2.3. CHECKS ON THE LEVEL METER D354

5.2.3.1. Checking the Level Steps

For a better understanding of the switching of the measuring ranges with S3 by the attenuator networks brought into circuit in various combinations and the different gains let us give the following explanations.

Measuring Range Switching in the 'Wideband' Mode (button T2 pushed)

When the button T2 is pushed, the contacts of relay E and L establish a connection between the output of the measuring field and the input of the wideband amplifier with the superheterodyne section bypassed.

The measuring ranges are switched as follows: by the 30-dB (4-Np) divider with the relays A and B by the 40-, 20-, 0-dB (6-, 4-, 2-, 0-Np) divider with switches $53^{\rm III}$ and $53^{\rm IV}$,

by stepwise changes of the feedback in the preamplifier D636 with switch $S3^{
m VI}$.

Measuring Range Switching in the "Selective/Low-distortion" Measuring Mode (button T3 pushed)

When the button T3 is pushed, relays E and L are not energized so that the heterodyne section is interposed between the output of the measuring field and the wideband amplifier.

The measuring ranges are switched as follows:

by the 30-db (4-Np) divider with the relays A and B, by 40-, 20-, 0-dB (6-, 4-, 2-, 0-Np) divider with switches $S3^{III}$ and $S3^{IV}$,

by stepwise changes of the negative feedback in the preamplifier D636 with switch S3^{VII},

by switching the 20-, 10-, 0-dB (2-, 1-, 0-Np) divider with the relays H and J in the 100-kHz amplifier D647.

Measuring Range Switching in the "Selective/Low-noise" Measuring Mcde (button T4 pushed)

The relays E and L are connected in the same way as in the "selective/low-noise" mode, e.g. the heterodyne section is interposed between the output of the measuring field and the wideband amplifier.

The measuring ranges are switched as follows:

by the 30-dB (4-Np) divider with relays A and B, by the 40-, 20-, 0-dB (6-, 4-, 2-, 0-Np) divider with switches $S3^{III}$ and $S3^{IV}$,

by stepwise changes of the feedback in the preamplifier D636 with switch S3^{VII},

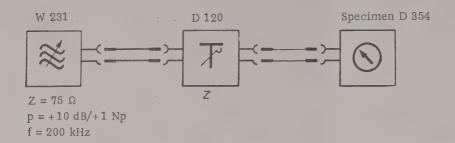
by switching the 20-, 10-, 0-dB (2-, 1-, 0-Np) divider with the relays H and J in the 100-kHz amplifier D647,

by switching the 30-dB (4-Np) divider with the relay K in the 100-kHz amplifier D647.

Note

The circuit diagrams show all relays in a deenergized condition. The windings of the relays are marked with capital letters (e.g. A, B, C), and the related contacts with lower-case letters (e.g. a, b, c).

Measuring Circuit for Checking the Level Steps



Settings required on the specimen D 354:

S1: Z, coaxial

S2: 75 1

S3: according to checking table

S4: dB/Np S5: 40 Hz

f₁= 200 kHz, S6: in spectrum steps

 $f_2 = 0$ kHz, S7: 0 kHz

The level steps of dB/dBm equipment are checked by reference to checking table 1, those of Np/Npm equipment according to checking table 2. When it is found that limits are exceeded, the dividers mentioned under "Notes" and the setting of the stepwise control feedback in the preamplifier, respectively, must be checked. If the specified individual tolerances are not exceeded, it is ensured that all level steps meet the databulletin value \pm 0.1 dB/ \pm 0.01 Np (in the most sensitive range \pm 0.3 dB/ \pm 0.03 Np).

Conse- cutive No.	Attenu- ator a (dB)	But- ton T pushed	Measur- ing range (dB)	Indication on level meter (dB)	Notes	
1	50	T2	-40	0	set with ▼I	
2	60	Т2	- 50	0 <u>+</u> 0.05	preamplifier v=20dB, alignment with R70 is possible	
3	70	Т2	- 60	0 <u>+</u> 0.05	preamplifier v=30dB, alignment with R74 is possible	
4	30	T2	-20	0 <u>+</u> 0.05	20-dB divider R20/R21	
5	10	T2	0 -	0 <u>+</u> 0.05	40-dB divider R22/R23	
6 .	0	T2	+10	0 <u>+</u> 0.05	30-dB divider R15/R16 relays A and B	
7	40*	T 3	- 90 ··	0 .	set with ▼II	
8	. 10* ,	T4	- 60	0 <u>+</u> 0.05	30-dB divider R27/R28 in the 100-kHz amplifier, relay K	
9	70	Т4	-60	0	set with ▼II	
10	60	T4	- 50	0 <u>+</u> 0.05	10-, 20-dB divider R13/R14/R31 in the 100-kHz amplifier, relays H, J	
11	50	T4	-40	0 + 0.05		
12	40*	Т3	- 90	0	set with ▼II	
13	70*	Т3	- 120	0 <u>+</u> 0.25	preamplifier v=40dB, alignment with R78 is possible	

^{*}lower the transmitting level to -50 dB

Table 1: Checking the level steps with information for fault location in the level meter D354 of the dB/dBm-model.

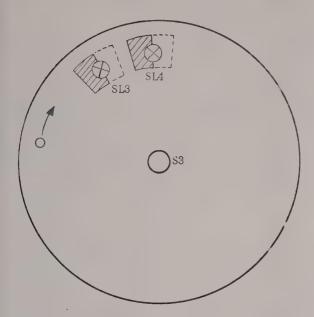
Conse- cutive No.	Attenu- ator a (Np)	But- ton T pushed	Measur- ing range (Np)	Indication on level meter (Np)	Notes	
1	6	Т2	- 5	0	set with ▼I	
2 .	7	T2	- 6	0 <u>+</u> 0.005	preamplifier v=2.6Np, alignment with R74 is possible	
3	7*	T2	- 7	0 <u>+</u> 0.01	preamplifier v=3.6Np, alignment with R78 is possible	
4 -	4	T2	- 3	0 <u>+</u> 0.005	2-Np divider R18/R19	
5	2	T2	-1	0 <u>+</u> 0.005	4-Np divider R20/R21	
6	1	T2	0	0 <u>+</u> 0.005	6-Np divider R22/R23	
7	0	T2	+1	0 <u>+</u> 0.005	4-Np divider R15/R16, relays A, B	
8	5**	Т3	- 9	0	set with ▼II	
9	1**	.T4 ======	- 5	0 ± 0.005	4-Np divider R27/R28 in the 100-kHz ampli-fier, relay K	
10	3**	Т4	- 7	0	set with ▼II	
11	2**	Т4	- 6	0 <u>+</u> 0.005	1-, 2-Np divider R13/R14/R31 in the	
12	1**	Т4	- 5	0 ± 0.005	100-kHz amplifier, relays H, J	

^{*}lower the transmitting level to 0 Np and repeat the measurement described in No. 1 at a = 5 Np ahead of point 3

Table 2: Checking the level steps with information for fault location in the level meter D354 of model Np/Npm.

^{**}lower the transmitting level to -4 Np

5.2.3.2. Automatic Correction System (Koramat) of the Measuring Range Switch S3



Arrangement of the lamps of the automatic correction system

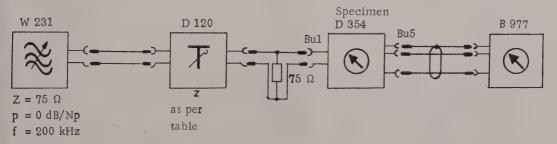
The lamps SL3 and SL4 in the 'Koramat' serve for distinct indication of the set measuring range. For each possible measuring range of the coaxial input (jack Bu 1) the lamp SL3 lights, and for each possible measuring range of the balanced input (jack Bu 2) and for the calibrating position "▼I, ▼II" the lamp SL4 is energized.

If the lamps are correctly controlled by the automatic correction system, the indication of the measuring range must agree with the tables

in the circuit diagram on sheet 1. If they are not, first check the lamps and subsequently the wiring of the switches ${\rm S1}^{II}$, ${\rm S3}^{I}$, ${\rm S4}$ and the pushbuttons T2, T3, T4 by reference to the circuit and wiring diagrams for possible interruptions.

When switch S4 is set to power level dBm/Npm the linkage system on the switches S3/S4 rotates the disk with the two transparent scale windows by one detent position in the direction of the arrow (see Fig.). This brings into view a measuring range whose sensitivity is lower by 10 dBm/1 Npm.

5.2.3.3. Checking the Divider for the Power Levels Measuring Circuit for Checking the Divider



Settings required on specimen D354:

S1: 10 kΩ | 60 pF

S2: according to checking table

S3: -50 dB/-6 Np

S4: by reference to checking table

T2 pushed

The check must be carried out on the equipment of model dB/dBm by reference to checking table 1, and on equipment of model Np/Npm by reference to checking table 2. When limits are exceeded, check the divider resistance R35 to R42 in the preamplifier D636.

Note: If no attenuator with attenuation 0.01-dB (0.001-Np) steps is available, these residual values must be read on the scale-spread device and correspondingly be taken into account in the measurement result. For instance, a setting of the attenuator for $Z = 150\Omega$ a = 46.0 dB instead of a = 46.02 dB results in a nominal value on the scale-spread device of +0.02 dB instead of 0.00 dB.

Attenu- ator a	Switch S2	~ 7	position S4	Indication on the scale- spread device B977	Note
50.00 dB	600 L	-50dB	dВ	O dB	to be set on the scale-spread device
40.00 dB	600 N	-40dBm	dBm	≤ 0.08dB	
46.02 dB	150 sc				
46.32 dB	140 1				
46.48 dB	135 Ω	,			
46.81 dB	125 1				
49.03 dB	75 Ω				

Table 1: Checking the divider for power levels in the level meter D354 of model dB/dBm.

Attenuator a	Switch S2	Sin S3	the position S4	n Indica- tion on the scale spread de vice B977	; -
6.000Np	1 000	-6Np	Np	ONP	to be set on the scale- spread device
5.000Np	600s	-5Npm	Npm	≦0.008Np	
5.691Np	150Ω				
5.725Np	140Ω				
5.750Np	135Ω				
5.783Np	125 🕰				
6.036Np	75 Q				

Table 2: Checking the divider for power levels in the level meter D354 of model Np/Npm.

5.2.3.4. Checking the Measuring Circuit

Calibrate the level meter in the wideband mode (\blacktriangledown I) and measure the dc voltage with nominal deflection (zero mark on the instrument) with a digital voltmeter at the dc output jack Bu 6 between the wires a and b with termination into 2.5 k Ω + 0.5%. Nominal value: 194 mV + 2%

If the need arises, make an alignment with R15 in board 9 'power amplifier and demodulator D649'.

With the above setting an output level of 0 ± 0.1 dB (0 ± 0.01 Np) must be measured when a calibrating level meter with $Z = 75\,\Omega$ is connected to the measuring output jack Bu7. If the need arises make an alignment with R35 in board 9 'power amplifier and demodulator D649'.

5.2.3.5. Checking and Aligning the Calibrating Voltages

5.2.3.5.1. Checking the Calibrating Voltage for Wideband Measurements

Settings required on the specimen D354:

S1: 10 kΩ | 60 pF

S2: 600 1

S3: 0 dB/Np

S4: dB or dBm, Np or Npm

S5: 40 Hz

T2 pushed

Measuring circuit:

Connect the calibrating level meter across the coaxial input (Bu 1) of the level meter and feed a signal of accurately 0 dB/Np with the level oscillator ($Z \sim 0 \Omega$, f = 100 kHz). Adjust the level meter deflection to the 0 dB/Np (\P) division with the control " \P I".

Checking and aligning:

Operate the range switch S3 to position " ∇ ". The calibrating voltage is in order when the instrument pointer likewise is at the calibrating mark " ∇ " 0 dB/Np.

If deviations are detected, adjust the deflection on the meter to the calibrating mark with R2O in board 2 'calibrating os-cillator D641'.

5.2.3.5.2. Checking the Calibrating Voltage for Selective Measurement

Settings required on level meter and measuring circuit: Settings and feed-in as under 5.3.3.5.1; push the button T4, frequency control $f_1 = 100$ kHz with lock-in and tune f_2 for maximum indication, adjust the control " \P II" for a deflection of 0 dB/Np on the instrument.

Check:

Operate the measuring range switch S3 to position " ∇ " and align the frequency control f_2 for maximum meter deflection. If the divider for the calibrating voltage is correct, the instrument pointer returns to the calibrating mark ∇ (0 dB/Np).

If the deviations exceed 0.05 dB(0.005 N_P) check the divider resistors R28,29,31,32,33,34 in the calibrating oscillator D641.

5.2.3.6. Checking the Level at the Dynamic Output, Jack Bu 4
Feed a level-oscillator signal of -20 dB/dBm and -2 Np/Npm,
respectively, and f = 100 kHz into the coaxial or balanced input.
Settings required on the level meter D354:

S1: at option Z coaxial or balanced

S2: corresponding to the Z-value on the level oscillator

S4: dB or dBm, Np or Npm

S5: 1600 Hz

T3 or T4 pushed

 $f_1 = 100 \text{ kHz}$, S6: with lock-in

 $f_2 = 0$ kHz, S7: 0 kHz

S3: to be set to the red dot

Connect the level meter with Z = 600Ω to jack Bu 4 and measure the IF-level at 100 kHz.

Nominal value: -20 ± 0.1 dB/-2 Np ± 0.01 Np The nominal value can be set with control P3.

5.2.3.7. Checking the Input Balance

Effect a selective calibration (VII) of the level meter and select with switch S1 the balanced input of high impedance, set 600 Ω with switch S2, short-circuit the a- and b-wires of the balanced input Bu 2 and feed between a/b and the c-wire a level-oscillator signal ($Z\sim0$) of 0 dB/Np and 600 kHz.

Increase the level meter sensitivity with S3 until a well-readable meter deflection results. The magnitude of the indicated level equals the common-mode suppression of the balanced input.

Nominal value: $a_s = 40 \text{ dB/4.6 Np}$

The nominal value must be met with wideband and selective measurement (T2, T3 or T4 pushed). The common-mode suppression can be optimized with L1, L2 and R11 in the input subassembly D631.

5.2.3.8. Checking the Residual Distortion Attenuation

The residual distortion attenuation can only be checked when a measuring voltage of low distortion is available. The harmonics should be down by at least = 100 dB, or otherwise the measurement result will be falsified.

Feed a transmitting level of 0 dB (dBm, Npm) and low distortion into the input of the level meter. Push the button T3 "low-distortion". Measure the level of the fundamental wave; subsequently tune the level meter in succession to the double and the triple of the generator frequency and measure the respective levels of these harmonics (a_{k2}, a_{k3}) . In so doing increase the sensitivity with the range switch S3, but by not more than 60 dB (7 Np). The difference between the fundamental and the harmonic levels (a_{k2}, a_{k3}) shall be \geq 80 dB (9 Np).

Note: If no source of measuring current with sufficiently low distortion is available, interpose a low-pass filter between level oscillator and level meter.

5.2.3.9. Checking the 100-kHz IF Filter

5.2.3.9.1. Curve Shape

Feed from level oscillator W231 a signal of 0 dB/Np, $f_1 = 100$ kHz, S6: with lock-in, $f_2 = 0$ kHz, S7: 0 - 10 kHz and tune for maximum indication of the level meter D354 with a pass band width of 10 Hz selected with switch S5.

Now change the level oscillator tuning condition and check the shape of the selectivity curves with S5 set to 10 Hz, 40 Hz and 1600 Hz, corresponding to the electrical data on p.8 in the pass band and in the stop band. In so doing, do not change the tuning condition of the level meter. For the measurements in the stop band the sensitivity must be increased with the measuring range switch S3 to an extent that the level meter shows a well readable deflection.

5.2.3.9.2. Level Control

With a pass-band width of 10 Hz selected with S5, effect the calibration "▼II", subsequently switch S5 to 40 Hz and 1600 Hz and read the corresponding deflections on the meter. It shall remain uniform with the three pass-band filters. In the case of level differences in excess of 0.05 dB (0.005 Np) as referred to the 40-Hz filter, the nominal level must be set in the crystal filter I D644 (10 Hz) and in the inductor type filter D646 with the potentiometer R3.



Setting:

■ II in mid-position $f_1 = 100 \text{ kHz}$, S6: with lock-in $f_2 = 0 \text{ kHz}$, S7: 0 Hz and connecting points see T4: 2, B602-x-7411
S3: 2-x-7402
S4:

S5:

Board 3 Measuring field D 630 Converter 2. 4 MHz/100 kHz D643 Wideband amplifier D 648 Feed a level of -38 dB/-4.2 Np and 2.4 MHz between measuring point 43 and ground Are the relays E and L restored? Is a reading of 0 dB/Np present on the instrument? Check the relays and the wiring Check the converter 2.4 MHz/ by reference to the circuit 100 kHz by reference to the cirdiagram cuit diagram Is the fault cleared? Is the fault cleared? Oscillator I D 369 Measure the carrier voltage 0.27 V and 2.5 MHz between measuring point 45 and chassis ground Is the voltage present? Look for the fault in the oscillator I D 369 Is the fault cleared?

selective (T3 or T4 pushed) idths (10 Hz, 40 Hz, 1600 Hz)

Feed a transmitting level of 0 dB (dBm, Npm) and low distortion into the input of the level meter. Push the button T3 "low-distortion". Measure the level of the fundamental wave; subsequently tune the level meter in succession to the double and the triple of the generator frequency and measure the respective levels of these harmonics (a_{k2}, a_{k3}) . In so doing increase the sensitivity with the range switch S3, but by not more than 60 dB (7 Np). The difference between the fundamental and the harmonic levels (a_{k2}, a_{k3}) shall be \geq 80 dB (9 Np).

Note: If no source of measuring current with sufficiently low distortion is available, interpose a low-pass filter between level oscillator and level meter.

5.2.3.9. Checking the 100-kHz IF Filter

5.2.3.9.1. Curve Shape

Feed from level oscillator W231 a signal of 0 dB/Np, $f_1 = 100$ kHz S6: with lock-in, $f_2 = 0$ kHz, S7: 0 - 10 kHz and tune for maximum indication of the level meter D354 with a pass band width of 10 Hz selected with switch S5.

Now change the level oscillator tuning condition and check the shape of the selectivity curves with S5 set to 10 Hz, 40 Hz and 1600 Hz, corresponding to the electrical data on p.8 in the pass band and in the stop band. In so doing, do not change the tuning condition of the level meter. For the measurements in the stop band the sensitivity must be increased with the measuring range switch S3 to an extent that the level meter shows a well readable deflection.

5.2.3.9.2. Level Control

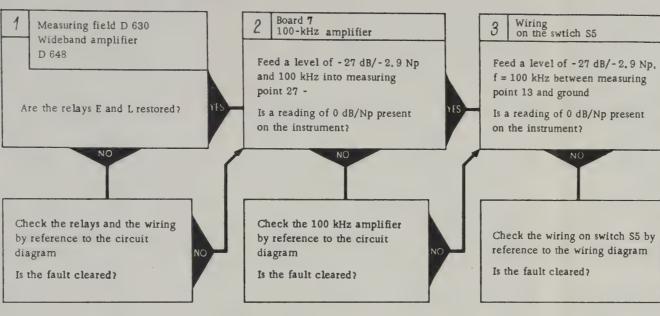
With a pass-band width of 10 Hz selected with S5, effect the calibration "▼II", subsequently switch S5 to 40 Hz and 1600 Hz and read the corresponding deflections on the meter. It shall remain uniform with the three pass-band filters. In the case of level differences in excess of 0.05 dB (0.005 Np) as referred to the 40-Hz filter, the nominal level must be set in the crystal filter I D644 (10 Hz) and in the inductor type filter D646 with the potentiometer R3.

Setting:

W II in mid-position $f_1 = 100 \text{ kHz}$, S6: with lock-in $f_0 = 0 \text{ kHz}; S7: 0 \text{ Hz}$

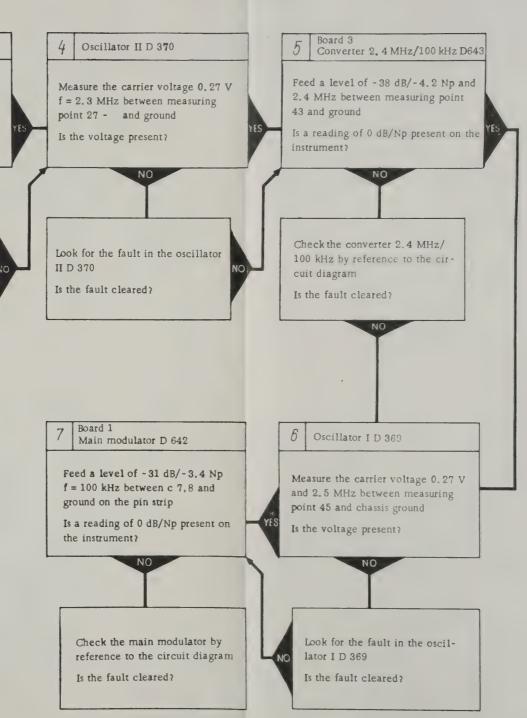
T4: pushed S3: 0 dB/Np S4: dB/Np

S5: 1600 kHz



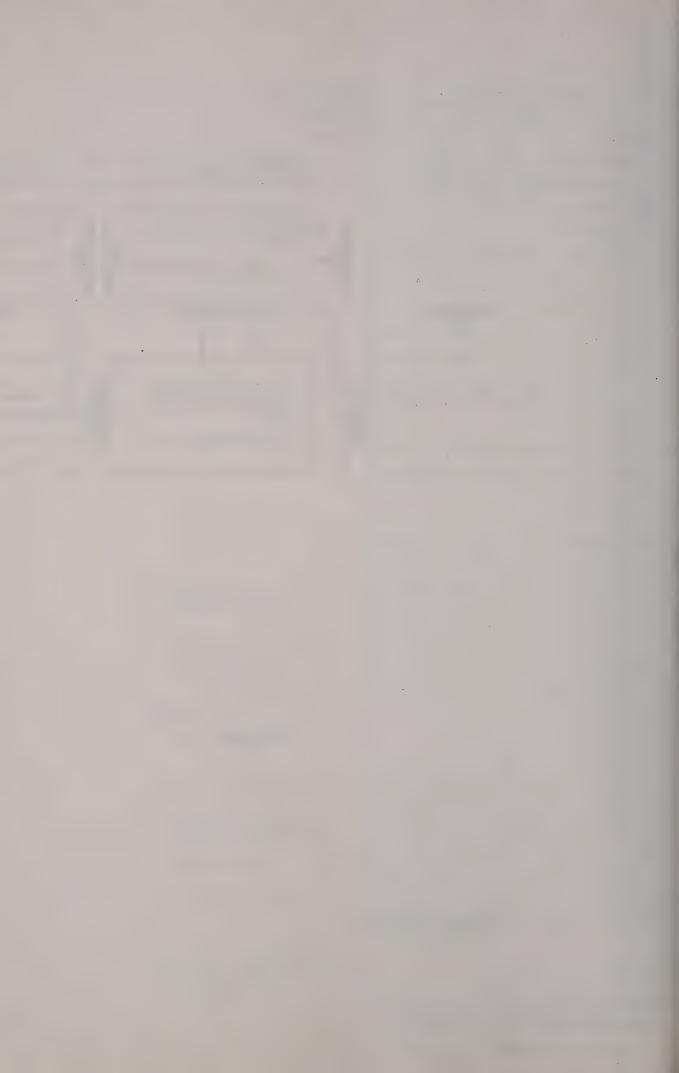
Wiring on the swtich S5

For the measuring and connecting points see \$45034-D354-B302, B602-x-7411 S45034-D354-B602-x-7402



Fault location, symptoms: Measuring selective (T3 or T4 pushed) is not possible with all 3 pass-band widths (10 Hz, 40 Hz, 1600 Hz) and with TI.

SIEMEN

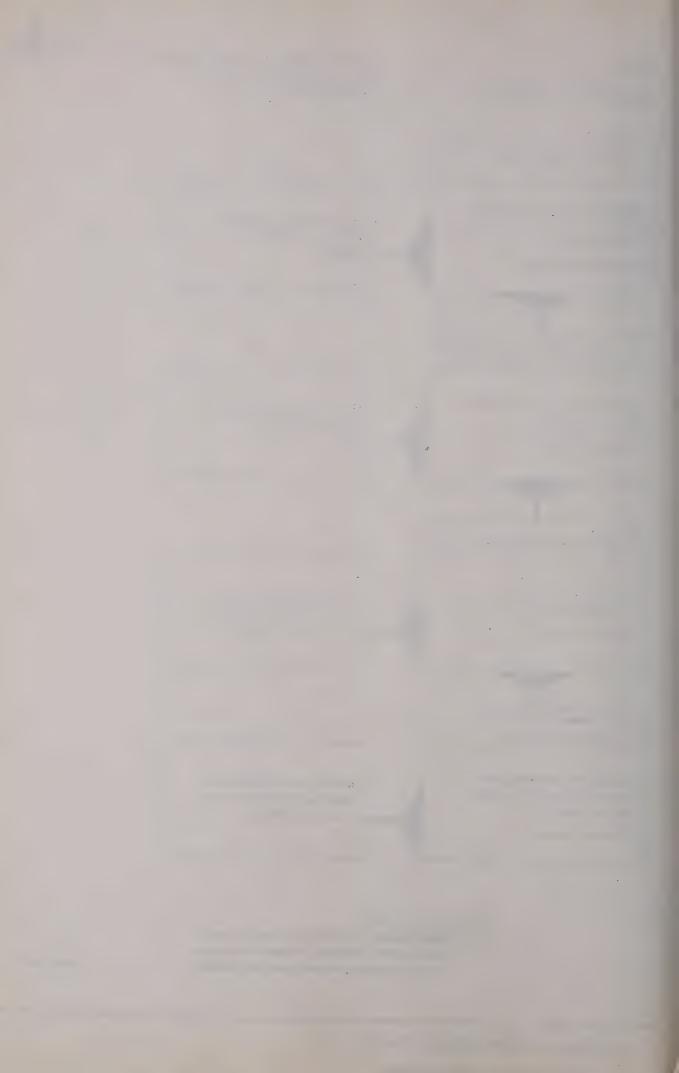




For the measuring and connecting points see Setting: S45034-D354-B302, B 602-x-7411 Control " I" in mid-position \$45034-D354-B602-x-7402 Push button T2 Power Supply I D 650 Measure the dc voltage +38 V at Check the power supply by the capacitors C1, 2 with respect reference to the circuit to chassis ground diagram NO Is the voltage present? Board 8 wideband amplifier D 648 Board 9 power amplifier D 649 Measure at jack Bu7 with termin-Check the measuring circuit ation into $Z = 75 \Omega$ in boards 8 and 9 YES Is the level present? Board 8 wideband amplifier D 648 Check the level -40 dB, Look for the fault by refer $f = 100 \text{ kHz at point } 73 - 74 (\bot)$ ence to the circuit diagram Is the level present? in the wideband amplifier NO Measuring field D 630 Preamplifier D 636 Measure the calibrating level Look for the fault in the pre--40 dB/-5 Np at the preampliamplifier D 636 by reference fier input point 9 - 1 to the circuit diagram Is the level present?

Fault location, symtoms: calibrating I and II, measurement wideband, selective low-distortion and selective low-noise are not possible

Annexed Fig. 1



5. STÜCKLISTE

Vorbemerkung

Unter Symbol stehen die in den Stromläufen verwendeten Abkürzungen für die Bauteile in alphabetischer und - soweit möglich - in numerischer Reihenfolge. Mit Stück ist die Anzahl der gleichen Bauteile innerhalb der Geräte oder der Baugruppe bezeichnet. In der Spalte Gegenstand sind ausser dem Namen des Bauteils auch seine Hauptkennwerte angegeben. Mit der Bestellnummer ist das Bauteil durch einen Abkürzungs-Code oder eine Bauvorschrift eindeutig gekennzeichnet.

bei einem Widerstand: 300 k Ω +5 %: 0.5 W

Es bedeuten:

<u>+</u> 5 %	Nennwert des Widerstandes Toleranz des Nennwiderstandes Belastbarkeit bezogen auf Umgebungstempe- ratur 20°C
1000 pF	1000 pF ±20 %; 125 V- Nennwert der Kapazität (1 pF = µµF = 10 ⁻¹² F) Toleranz der Nennkapazität zulässige Betriebsgleichspannung
bei einem Übertrager:	Wicklg.I (1a,2a,3a) Wicklg.II (rtsw,gesw, 440 Wdg 0,1 Cul 75 Ω rtgn,gegnsw) ⁺ 228 μH +2 % 720 Wdg HFL SS 60x0,03 35Ω Abgriff(2a): 210 Wdg 1.Abgriff (gesw): 46 Wdg 2.Abgriff (rtgn): 190 Wdg
0,1 CuL	440 Windungen, Anfang Lötöse 1a, Ende 3a; aus Kupferdraht (Cu); 0,1 mm Ø; lackisoliert (L) Gleichstromwiderstand der Wicklung I Induktivität Abgriff bei der 210.Windung, Lötöse 2a
Wicklg.II HFL SS 60x0,03	sinngemäss wie bei Wicklung I Hochfrequenzlitze 2fach seidenumsponnen (SS), aus Kupferdraht 60x0,03 mmØ
	50 V/250 mA Anschluss-Wechselspannung entnehmbarer Betriebsstrom

Farbkurzzeichen
bl = blau ge = gelb gr = grau sw = schwarz rs = rosa
br = braun gn = grün rt = rot ws = weiss rtsw = rot/schwarz

Introductory remark

with a resistor:

The "SYMBOL" column shows the abbreviations used in the circuit diagrams in alphabetic and, to the extent possible, numerical order. "QTY" denotes the number of identical components within the devices or the subassembly. The "DESCRIPTION" column gives, apart from the designation of the components, its principal characteristic data. The "ORDER NUMBER" column designates the component nonambiguously by an abbreviation code or a component specification.

300 kΩ + 5%: 0,5 W

There denotes, for instance

```
Nominal value of the resistance
  300 kΩ . . . . .
                      Tolerance of the nominal resistance
  +5% . .
                      Wattage rating, as referred to an ambient temperature of 20°C
                      temperature of 20°
                      1000 pF +20%; 125 V-
with a capacitor:
                      Nominal value of the capacitance (1 pF = 1 \mu\muF = 10<sup>-12</sup> F
  1000 pF +20% . .
                      Tolerance of the nominal capacitance
  125 V- .
                      Permissible DC operating voltage
                      Wicklg. I(1a,2a,3a)
                                               Wicklg. II(rtsw,gesw,
with a transformer:
                                                          rtgn, gegnsw) +
                      440 Wdg 0,1 CuL 75 Ω
                                               720 Wdg HFL SS 60x0,03 35 Q
                      228 μH <u>+</u>2%
                                               1.Abgriff(gesw): 46 Wdg
                      Abgriff(2a): 210 Wdg
                                               2.Abgriff(rtgn): 190 Wdg
  Wicklg. I(1a, 2a, 3a)
                      440 turns, start soldering lug 1a, end 3a
  440 Wdg . . . .
                      of copper wire (Cu); 0.1 mm dia., enamelled (L)
  0,1 CuL . . . .
  75 Ω . . . . .
                      DC resistance of winding I
                      Inductance
  228 μΗ .
  Abgriff(2a):210Wdg Tap at soldering lug 2a at the 210th turn
                      Analogously to winding I
  Wicklg. II . . .
                      RF copper Litz wire, with double silk covering,
  HFL SS 60x0,03 .
                      60x0.03 mm dia.
with a rectifier:
                      50 V/250 mA
  50 V . . . . . .
                      Primary AC voltage
  250 mA . . . .
                      Available operating current
```

^{*}Color symbols
bl = blue ge = yellow gr = gray sw = black rs = pink
br = brown gn = green rt = red ws = white rtsw = red/black

FANDWIDTH-SWITCH Pl.1 1	
Symbol Stake	C44334-Z11-C1 C42334-A76-A34 C42334-F3-C1 V45030-T1 V45594-F4-A522 V42257-R17-C13
### STREAM OF THE PROPERTY OF SERRING DATA PAGE TOTAL AUSGRAPH PAGE PAGE PAGE PAGE	C42334-A76-A34 C42334-F3-C1 V45030-T1 V45594-F4-A522 V42257-R17-C13
Fir Amerg.	C42334-A76-A34 C42334-F3-C1 V45030-T1 V45594-F4-A522 V42257-R17-C13
PON MODEL	C42334-F3-C1 V45030-T1 V45594-F4-A522 V42257-R17-C13 UMENT (RED)
1 Verdrahtungsleiter S45035-D654-B701 1 Flachbeutel f.Kabel CARLE-CONTAINER 1 Verdrahtungsleiter S45035-D655-A701 1 Netzamschlußleitung FOWER CORD 1 Verdrahtungsleiter S45035-D655-A701 1 Netzamschlußleitung FOWER CORD 1 Nesfeld S45035-D630-B301 5.3 1 Anschlußleitung FOWER CORD 1 Mesfeld S45035-D630-B301 5.3 1 Anschlußleitung FOWER CORD 1 Mesfeld S45035-D630-B601 5.3 1 Anschlußleitung FOWER CORD FOR INSTRUCTION 1 Mesfeld S45035-D640-A702 S5 1 Bandbreitenschalter COUNSECTING CORD FOR INSTRUCTION 1 Mesfeld S45035-D640-A702 S5 1 Bandbreitenschalter COUNSECTING CORD FOR INSTRUCTION 1 Multimodulator S45035-D642-A701 5.5 J 1 Bandbreitenschalter CARLE-COUNSECTING CORD FOR INSTRUCTION 1 Multimodulator S45035-D642-A701 5.6 S S S S 1 Schossillator S45035-D641-B101 5.6 S S S S S 1 Multimodulator S45035-D641-B401 5.6 S S S S S S S S 1 Muster 2,4 MHz/ S45035-D643-A401 5.6 S S S S S S S S S 1 Muster 2,4 MHz/ S45035-D643-A401 5.6 S S S S S S S S S	V45030-T1 V45594-F4-A522 V42257-R17-C13 UMENT (RED)
Plate I	V45594-F4-A522 V42257-R17-C13 UMENT (RED)
1 Verdrahtungaleiter- S45035-D630-B701 FOWER CORD	V42257-R17-C13
Me8feld	UMENT (RED)
1 Me8feld S45035-D630-B601 5.3 1 1 Anschlüßleitung für Instr. (20cmm blau) CONNECTING CORD FOR INSTRUCT 1 1 Adapter S45035-D640-A702 S5 1 1 Eardbreitenschalter C4 Eardbreitenschalter C4 Eardbreitenschalter C4 Eardbreitenschalter C4 Eardbreitenschalter C4 Eardbreitenschalter C4 Eardbreitenschalter C5 Eardbreit	W40057 D47
P1.1	V42257-R17-D13 UMENT (BLUE)
Pl.1	44315-A14-A6
### Pi.2 1	70349-A578-A1
Calibrating Oscillator	
Pl.3 Umsetzer 2,4 MHz/ S45035-D643-A101 2.0	11571-M630-C2
P1.3 1 Umsetzer 2,4 MHz/ S45035-D643-A401 -5.6 P1.4 1 1 Quarz-Filter I S45035-D644-A701 -5.7 P1.5 1 1 Quarz-Filter II S45035-D645-A701 -5.7 P1.6 1 1 100-kHz-Pilter S45035-D646-B701 -5.8 P1.7 1 100-kHz-Verstärker S45035-D647-B101 -5.8 P1.8 1 1 Breitbandverstärker S45035-D647-B401 -5.8 P1.8 1 1 Breitbandverstärker S45035-D648-B701 -5.8 P1.8 1 1 Breitbandverstärker S45035-D648-B701 -5.8 P1.8 2 2 C4 P1.8 1 1 Breitbandverstärker S45035-D648-B701 -5.8 P1.8 2 2 C4 P1.8 1 1 Breitbandverstärker S45035-D648-B701 -5.8 P1.8 2 2 C4 P1.8 2 2 C4 P1.8 2 2 C4 P1.8 3 2 2 C4 P1.8 4 Breitbandverstärker S45035-D648-B701 -5.8 P1.8 5 C AV P1.8 5 C AV P1.8 5 C AV P1.8 6 C4 P1.8 6 C4 P1.8 7 CAP P1.8 7 CAP P1.8 7 CAP P1.8 7 CAP P1.8 8 C4 P1.8 8 C4 P1.8 9 C4	41571-M315-C2
Fl.4 1 Quarz-Filter I	g lp 62be
CRYSTAL FILTER I P1.5 1 1 Quarz-Filter II S45035-D645-A701 5.7 1 1 Sechskanstiftschlüßesel D9 HEXAGONAL SOCKET-WRENCH P1.6 1 1 100-kHz-Filter S45035-D646-B701 5.8 1 1 Blende farblos, matt. Fg LAMF CAP COLOURLESS, FROSTE P1.7 1 100-kHz-Verstärker S45035-D647-B101 5.8 2 2 Blende CAP P1.7 1 100-kHz-Verstärker S45035-D647-B401 5.8 2 2 Blende CAP P1.7 1 100-kHz-Verstärker S45035-D647-B401 5.8 Drehknopf ROTARY KNOB P1.8 1 1 Breitbandverstärker S45035-D648-B701 5.8 2 2 C4	
P1.6 1 1 100-kHz-Filter S45035-D646-B701 5.8 1 1 Blende farblos, matt. Fg LAMP CAP COLOURLESS, FROSTE P1.7 1 100-kHz-Verstärker S45035-D647-B101 5.8 2 2 Blende CAP P1.7 1 100-kHz-Verstärker S45035-D647-B101 5.8 2 2 Blende CAP P1.7 1 100-kHz-Verstärker S45035-D647-B401 5.8 Drehknopf ROTARY KNOB P1.8 1 1 Breitbandverstärker S45035-D648-B701 5.8 2 2 C4 WIDEBAND AMPLIFIER	14121-A9-C1
P1.7 1 100-kHz-Verstärker	911-≜15
P1.7 1 100-kHz-PreamPliPIER	g 1p 68a ED
P1.8 1 1 Breitbandverstärker 345035-u648-B701 5.8 2 2 C4 WIDDEARD AMPLIFIER	14300-A7-C4
WIDERD AMPLIFIER	
1 1	14106-A1-A2 14326-A6-B11
Pl.9 1 1 Leistungsverstärker S45035-D649-A701 5.8	el antr 93c
POWER SUPPLY UNIT I CLIP-CONTACT STRIP	12334-A56-A1
731p P1.10 1 1 Netzteil II S45C35-D651-A701 5.10 POWER SUPPLY UNIT II 1 Keram. Lötstützpunkt Re CERAMIC SOLDERING	el ltg 519i
1 1 (szillator I S45034-D369-A702 5.11 CONNECTION POINT OSCILLATOR I 01600 kHz MeBfeld S45035-D630-B301, B601	
1 1 Oszillator II S45034-D370-A702 5:14 MEASURING FIELD #	
OSCILLATOR II für Ausfg. O10 kHz FOR MODEL	
1 1 Platte für koax- C44326-a14-098 -B301 -B601 Stecker 2,5/6 (Bu1) 1 Eingangsbaugruppe S4	45035-D631-A101
MOUNTING FOR JACK 2,7/0 (But) in Ersatzteilbehälter enth. INFUT SUBASSEMBLY INFUT SUBASSEMBLY	
1 1 Metallgehäuse C44165-A12-A3 INFUT SUBASSEMBLY	45035-D631- ≜ 401
2 2 Druckstück Rel bschl 29c LEVEL RANGE SWITCH	45035-D634-B101
Schichtwiderstand LEVEL RANGE SWITCH	45035-D634-B401
LAYER-TYPE RESISTOR 1 Trennstufe S4 R1 1 330 Ohm ±5%; 0,33W B54413-A2331-J BUFFER STAGE	45035-D635-A101
	45035-D635-A401
Schichtdrehwiderstand 1 Vorverstärker 54 LATER-TIPE VAR RESISTOR PREAMPLIFIER	45035-D636-A101
PREAMPLIFIER	45035-D636-A401
P3 1 1 500 0hm +20%; 0,1W; lin W40951-B8501-M001 1 Relaisplatte S4 1 1 Kappe Rel mse 348, T216 RELAY BOARD	
CAP 1 Relaisplatte S4	45035-D637- ▲ 101
MKL-CAPACITOR 0,68,uF +20; 63V 1 1 Beleuchtungsfeld C4	45035-D637-A101 45035-D637-A401
C2,3 3 Tantal-Elko B45170-A4475-M 2 Lampenfassung C4 4,7/uF +20%; 35V LAMP HOLDER	

T2/3 T4	1	1	Druck tas tenschal ter PUSHBUTTON SWITCH	C44315-Z2-G2	C10	1	1	Tantal-Elko TANTALUM ELECTRLYTIC CAP.	B45170-A4475-M
84	1	1	Drehschalter ROTARY SWITCH	C42315-A17-A40				4,7/uF ±20%; 35V Lufttrimmer AIR-DIELECTRIC TRIMMER	
SL3,4	2	2	Signallampe SIGNAL LAMP	Fg lp 62be	C3	1	1	2,011pF	Rel ko 131ad
			24V/0,6W		c6	1	1	2,113pF	Rel ko 1311
			Keramik-Kondensator CERAMIC CAPACITOR					1) = Wert wie eingebaut VALUE AS MOUNTED	
C9	1	1	pF Wert wie eingebaut VALUE AS MOUNTED	В38212-		1	1	Buchseneinheit JACK PLATE	Rel kli 6a
C13	1	1	5pF +0,5pF; 500V	B38212-J5050-D 1)		1	1	Buchse	C42334-A76-A14
43 3	1		5pF ±0,5pF; 500V	B38212-J5050-D 1)				JACK 1,6/5,6	
C17		1	10pF ±0,5pF; 500V	B38212-J5100-D 1)	A,B	2	2	S-G-Relais	Rel Bv 662 E 31
C 20		1	5pF ±0,5pF; 500V 1) = Wert wie eingebaut VALUE AS MOUNTED	В38212-Ј5050-D 1)	Gr1	1	1	DRY-REED RELAY Rel rls 28a Diode	Q60101-x118
C46 C51	6	6	Tantal-Elko TANTALUM ELEC TIC C.	B45170-A4475-M APACITOR			Fina	DIODE AA 118	
C52	1	1	4,7 /UF +20%; 35V MKL-Kondens	В32110-Е9105-М			INPUT	ngswahlschalter S1 S45035- SELECTOR SWITCH S1	- <u>J072-4701</u>
			MKL-CAPAC		§1	1		Drehschalter ROTARY SWITCH	C40315-M302-B2
C8,12 C16	3	3	Luft-Trimm-r AIR DIR EC IC TRIMMER 2,113pF	Rel ko 131i				er S2 S45035-D633-A701 E SWITCH S2	
C11		1	2,113pF	Rel ko 131i	S2	1		Drehschalter ROTARY SWITCH	U44315-A14-A4
Gr7,8	2	2	Silizium-Diode SILICON DIODE DX 6393	Q62702-A110-F7				Schichtwiderstand LAYER-TYPE RESISTOR	
	E	ingang	sbaugruppe S45035-D631-A	101. A401	R1	1		75,6 Ohm +0,5%; 1\	B54415-A9750-D600
	Ī	NPUT S	UBASSEMBLY		R2	1		125 Uhm +0,5%; 0,5W	B54414-A9121-D500
	FOR M	usfg.			R3	1		135 Ohm ±0,5%; 0,5W	B54414-A9131-D500
		-A401			R4	1		140 Ohm +0,5%; 0,5W	B54414-A9141-D
S1	1	1	Eingangswahlschalter INPUT SELECTOR SWITCH	\$45035-D632-A701	R5	1		150 Ohm +0,5%; 0,5W	B54414-A9151-D
\$2	1	1	Z-Schal ter	S45035-D633-A701	R6	1		600 Ohm +0,5%; 0,33W	B54413-A9601-D
	1	1	IMPEDANCE SWITCH Schaltebene	C42315-A400-B2	R7	1		1,7 Ohm +5%; 0,5W	B54414-A2010-J700
			DECK	D5.1447 10400 7 4\	R8	1		2,15 Ohm +5%; 0,5W	B54414-A2020-J150
R10	1	1	Schichtwiderstand LAYER-TYPE RESISTOR 12 Ohm +5%; 0,33W	B54413-A2120-J 1)	R9	1		39 Ohm <u>+</u> 5%; 0,5W	B54414-A2390-J
R14	1	1	350 Ohm +5%; 0,33W 1)= Wert wie eingebaut VALUE AS MOUNTED	B54413-A2351-J 1)		Mei	Bbereic VEL RAN	hschalter S3 S45035-D634- GE SWITCH S3	B101, B401
			Schichtwiderstand LAYER-TYPE RESISTOR		F	OR MO	usfg. ODEL -B401		
R15	1		9,684kOhm +0,2%; 0,15W		S3	1	1	Schalter	C44315-A12-A23
R15		1	9,817kOhm ±0,2%; 0,15W 326,2 Ohm +0,2%; 0,15W	B51264-A9982-C170 B51264-A9321-C620				SWITCH	
R16	1	1	186,6 Ohm +0,2%; 0,15W					Schichtwiderstand LAYER-TYPE RESISTOR	
R11	1	1	Drahtdrehwiders tand	W40109-B8250-J008	R18		1	8,647kOhm ±0,2%; 0,15W	B51264-A9862-C470
			WIRE-WOUND VAR RESISTOR 25 Ohm +5%; 1W		R20	1		9k0hm +0,2%; 0,15W	B51264-A9902-C
			Eingangs-Übertrager INPUT - TRANSFORMER		R20		1	9,817kOhm +0,2%; 0,15W	B51264-A9982-C170
ti1	1		Wicklg. I (1a,7a) 29 Wdg. 3x0,21 CuL	Rel Bv 621 E 3316	R22	1		9,9k0hm ±0,2%; 0,15W	B51264-A9992-C
			paral.; 0,31 Ohm		R22		1	9,975kOhm <u>+</u> 0,2%; 0,15W	B51264-A9992-C750
			Wicklg.II (1b,7b) 280 Wdg. 0,06 CuL; 140 Ohm		Gr5,6		2	Silizium-Diode SILICON DIODE DX 6393	Q62702-A110-F7
Ü1		1	Wicklg. I (1a,7a) 39 Wdg. 3x0,15 CuL paral.; 0,93 Ohm	Rel Bv 621 E 3315		BUF	FFER ST	e S45035-D635-A101, A401 AGE	
			Wicklg.II (1b,7b) 280 Wdg. 0,06 CuL; 140 Ohm		F	ür Au OR MC			
L1,L2	2	2	Spule	Rel Bv 623 M 3060				Schich twiders tand	
			COIL Rel sp 71b		R19		1	LAYER-TYPE RESISTOR	
C1	1	1	Kf-Kondensator PLASTIC-FOIL CAPACITOR	B31141-A5500-F 1)	R21	1 -	·	1,565kOhm +0,2%; 0,15W	B51264-A9152-C650
			50pF ±1%; 500V		R21		1.	1,111kOhm ±0,2%; 0,15W 186,6 Ohm ±0,2%; 0,15W	B51264-A9112-C110 B51264-A9181-C660
C2	1	1	MKL-Kondensator MKL-CAPACITOR	В32110-Е9475-М	R23	1		101 Ohm +0,2%; 0,15W	B51264-A9101-C100
			4,7 /uF +20%; 63V 1)= Wert wie eingebaut		R23		1	24,85 Ohm +0,2%; 0,15w	B51264-A9101-0100
			VALUE AS MOUNTED		R27,28	2	· 2	20kOhm +1%; 0, iW	B51263-A9203-F
C4	1	1	Keramik-Kondensator CERAMIC CAPACITOR	B38212-A5050-D 1)	R30,33	2	2	220 Ohm +5%; 0,33W	B54413-A2221-J
			5pF ±0,5pF; 500V		R31	1	1	3,9k0hm +5%; 0,25W	B51263-A2392-J
05	1	1	Glimmer-Kondensator MICA-CAPACITOR	B34212-A5431-G	R32	1	1	150 Ohm +5%; 0,33W	B54413-A2151-J
			430pF ±2%; 500V Keramik-Kondensator CERAMIC CAPACITOR		R29	1	1	Schichtdrehwiderstand LAYER-TYPE VAR RESISTOR	W40955-A8202-M001
C7	1		18pF <u>+</u> 5%; 500V	B38216-J5180-J 1)		1	1	2k0hm +20%; 1W; lin	C44409 77 75
C7		1	27pF <u>+</u> 5%; 500V	B38216-J5270-J 1)				Staubschutzkappe PROTECTION CAP	C44408-Z3-C3

C15	1		Keramik-Kondensator CERAMIC CAPACITOR 80pF +5%; 500V	в38226-Ј5800-Ј		1	1	Staubschutzkappe PROTECTION CAP	C44408-Z3-C3
C15		1	Glimmer-Kondensator MICA CAPACITOR	B34212-A5471-J	C26,37	2	2	MKL-Kendensator MKL-CAPACITOR 2,2/uF +20%; 63V	B32110-E9225-M
			470pF ±5%; 500V Glimmer-Kondensator MICA CAPACITOR		C27	1	1	Keramik-Kondensator CERAMIC CAPACITOR 6pf +0,5pf; 500V	В38222-А5060-D
019	1		900pF +2%; 300V	B34212-A3901-G	028,32	2	2	MKL-Kondensator	В32110-E9475-M
019		1	2600pF +2%; 500V	B34214-A5262-G				MKL-CAPACITOR 4,7/uF +20%; 63V	
C21		1	Keramik-Kondensator CERAMIC CAPACITOR 50pF +5%; 500V	B38226-J5500-J	C 29	1	1	Tantal-Elko TANTALUM ELECTROLYTIC (68 /uF +20%; 15V	B45170-A2686-M CAPACITOR
C22	1	1	MKL-Kondensator MKL-CAPACITOR 4,7/uF +20%; 63V	В32110-Е9475-М	c 30	1	1	Keramik-Kondensator CERAMIC CAPACITOR	B38215-J5330-J
C23	1	1	Keramik-Kondensator CERAMIC CAPACITOR 6pF +0,5pF; 500V	B38212-A5060-D	031,39	2	2	33pF ±5%; 500V Tantal-Elko TANTALUM ELECTROLYTIC (B45170-A3686-M SAPACITOR
C24	1	1	Tantal-Elko	B45170-A3476-M	C33	1	1	68/uF ±20%; 20V	B45170-A1106-M
			TANTALUM ELECTROLYTIC C. 47 uF ±20%; 20V	APACITOR	036	1	1	150/uF ±20%; 15V	B45170-A2157-M
			Lufttrimmer AIR-DIELECTRIC TRIMMER		C38	1	1	Keramik-Kondensator	B38215-J5300-J
C14,18	2	2	2,511pF	Rel ko 131f				CERAMIC CAPACITOR 30PF +5%; 500V	
∪25		1	2,511pF	Rel ko 131f	C40	1	1	Tantal-Elko	B45170-A2107-M
Ts1,2	2	2	Transistor	Q62702-S0003				TANTALUM ELECTROLYTIC O	APACITOR
	2	2	TRANSISTOR 2 N 2219 Halterung	C42121-A11-C6	041	1	1	Lufttrimmer AIR-DIELECTRIC TRIMME 2,511pF	Rel ko 131f R
			MOUN TING	042121-A11-00	C,D	2	2	S-G-Relais	Rel Bv 662 E 56
	4	4	Isolierperle BEAD	C42187-Z7-C2				DRY-REED RELAY Rel rls 24a	
	V F	orverst PREAMPLI	Erker S45035-D636-A101, A	<u>401</u>				Transistor TRANSISTOR	
			Schichtwiderstand		ТвЗ	1	1	2 N 2219	Q62702-S0003
			LAYER-TYPE RESISTOR		Ts4 ••8	5	5	2 N 2218	Q62702-S0002
R35	1		32,8 Ohm +0,2%; 0,15W	B51264-A9320-0800		6	6	Halterung MOUNTING	C42121-A11-C6
R36 R36	'	1	57,4 Ohm ±0,2%; 0,15W	B51264-A9570-C4C0	Gr2,4	2	2	. Diode	Q60101-X118
R37	1	'	32,63 Ohm ±0,2%; 0,15W	B51264-A9320-C630				DIODE AA 118	
R37	·	1	188 Ohm ±0,2%; 0,15W	B51264-A9181-C800 B51264-A9161-C700		6	6	Isolierperle BEAD	C42187-Z7-C2
R38	1		25,7 Ohm ±0,2%; 0,15W	B51264-A9250-C700					
R38		1	27,72 Chm ±0,2%; 0,15W	B51264-A9270-C720		RI	elaispla ELAY- BO	tte S45035-D637-A101, A	<u>401</u>
R39	1		12,2:0hm +6,2%; 0,15W	B51264-A9120-C200		für Aı	ısfg.		
R39		1	12,93 Ohm +0,2%; 0,15W	B51264-A9120-C930		FOR MO	DEL		
R40	1 '		22 Ohm +0,2%; 0,15W	B51264-A9220-C		A101-#	1401	Schichtwiderstand	
R40		1	24 Ohm +0,2%; 0,15W	B51264-A9240-C				LAYER-TYPE RESISTOR	
R41		1	365 Ohm +0,2%; 0,15W	B51264-A9361-C500	R6 9	1		220 Ohm +1%; 0,33W	B54413-A9221-F
R41,42	2		331 Ohm +0,2%; 0,15W	B51264-A9331-C100	R72		1	100 Ohm +1%; 0,33W	B54413-A9101-F
R42		1	370,7 Ohm +0,2%; 0,15W	B51264-A9371-C070	R73	1		180 Ohm +1%; 0,33W	B54413-A9181-F
R44,45	2	2	10k0hm +1%; 0,1W	B51263-A9103-F	R73		1	120 Ohm ±1%; 0,33W	B54413-A9121-F
R46,54	3	3	220 Ohm +5%; 0,33W	B54413-A2221-J	R76,77	2		30 Ohm ±1%; 0,33W	B54413-A9300-F
R66 R47,53	2		3,9kOhm +5%; 0,25W	B51263-A2392-J	R76,77		2	100 Ohm +1%; 0,33W	B54413-A9101-F
R47,49		3	3,9k0hm +5%; 0,25W	B51263-A2392-J	R70	1		100 Ohm +20%; 1W; lin	W40955-D8101-M001
R53 R48	1	1	27kOhm +5%; 0,25W	B51263-A2273-J	R74,76	2	2	100 Ohm +20%; 1W; lin	W40955-D8101-M001
R49		1	4,7kOhm +5%; 0,25W	B51263-A2472-J				Keramik-Kondensator CERAMIC CAPACITOR	
R 50	1	1	2,7kOhm +5%; 0,25W	B51263-A2272-J	C42	1		150pF +5%; 500∇	R38227_T6161 T
R51	1		800 Ohm +1%; 0,33W	B54413-A9801-F	C42		1	22pF +5%; 500V	B38227-J5151-J x) B38226-J5220-J x)
R51		1	500 Ohm ±1%; 0,33W	B54413-A9501-F	C43	1		1000pF +30-20%; 500V	B38226-J5220-J x) B37638-B5102-R000
R55,64	2	2	18k0hm +5%; 0,25\	B51263-A2183-J	C43		1	150pF +5%; 500V	B38227-J5151-J x)
R56	1	1	5,6k0hm +5%; 0,25W	B51263-A2562-J	C44		1	39pF +2%; 500V	B38226-J5390-G x)
R57,63	2	2	1,8k0hm +5%; 0,25W	B51263-A2182-J				x) = Wert wie eingebau	
R58	1	1	150 Ohm ±5%; 0,33W	B54413-A2151-J				VALUE AS MOUNTED	
R59	1	1	470 Ohm ±5%; 0,33W	B54413-A2471-J	E	1	1	S-G-Relais DRY-REED RELAY	Rel Bv 662 E 56
R60	1		2kOhm +1%; 0,1W	B51263-A9202-F			r.	Rel rls 24a	
R60		1	2,2kOhm +1%; 0,1W	B51263-A9222-F			2	Isolierperle BEAD	C42187-Z7-C2
R65	1	1	39kOhm ±5%; 0,25W	B51263-A2393-J	Pl.1	H	aup tmod	ulator S45035-D642-A701	
R67	1	1	2,2k0hm ±5%; 0,25W	B51263-A2222-J		M	AIN MOD		
R68	1	1	100 Ohm ±5%; 0,33W	B54413-A2101-J				Schichtwiderstand LAYER-TYPE RESISTOR	
R52									
	1	1	Schichtdrehwiderstand LAYER-TYPE VAR RESISTOR	W40955-A8101-M001	R1	1		1k0hm +1%; 0,33W	B54413-A9102-F
	1	1		W40955-A8101-M001	R1 R2	1		1k0hm ±1%; 0,33W 12k0hm ±1%; 0,1W	B54413-A9102-F B51263-A9123-F
	1	1	LAYER-TYPE VAR RESISTOR	W40955-A8101-M001				-	

## 1	(0500 5720 74
R4,5 2 4kOhm ±7%; 0,25W B51263-A2103-J 1 Ralterung C4 R6,22 4 10kohm ±7%; 0,25W B51263-A2222-J P1.2 Richoszillator S45035-D641-B101, B401 R8,9,12,14 7 220 0hm ±7%; 0,33W B54413-A2221-J P1.2 Richoszillator S45035-D641-B101, B401 R10,11 2 47 0hm ±7%; 0,33W B54413-A2270-J F0R MODEL R13 1 27 0hm ±7%; 0,53W B54413-A2270-J -B101-B401 R15 1 1kohm ±7%; 0,53W B54413-A2270-J -B101-B401 R17,18 2 1,4kohm ±1%; 0,1W B51263-A9142-F 1 F0rmdraht, Brücke A WIRINO-LINK A S4 R17,18 2 1,4kohm ±1%; 0,1W B51263-A9152-F 1 F0rmdraht, Brücke B S4 R24 1 330 0hm ±7%; 0,33W B54413-A2331-J Sohichtwiderstand LAYER-TYPE R53ISTOR R25 1 900 0hm ±7%; 0,33W B54413-A2390-J R15, 25 2 2 220 0hm ±7%; 0,35W B5 R29 1 39 0hm ±7%; 0,33W B54413-A2390-J R16 1 1 11kohm ±7%; 0,25W B5 R26 1 2,7kohm ±7%; 0,33W B54413-A2390-J R16 1 1 11kohm ±7%; 0,25W B5 R27 1 Sohichtwiderstand LAYER-TYPE VAR RSSISTOR 200 0hm ±2%; 0,33W B54413-A2390-J R16 1 1 11kohm ±7%; 0,25W B5 R28 1 Sohichtwiderstand LAYER-TYPE VAR RSSISTOR 200 0hm ±2%; 0,33W B54413-A2390-J R16 1 1 10 0hm ±5%; 0,25W B5 R27 1 Hel ap 75n Rel BV 622 T 3075 R24 1 1 9,1kohm ±5%; 0,25W B5 R28 1 9 Rel ap 6h Rel BV 622 T 3075 R24 1 1 9,1kohm ±5%; 0,25W B5 R29 1 9 Rel ap 6h Rel BV 622 F 3420 R26 1 1 1,2kohm ±5%; 0,25W B5 R29 1 9 Rel ap 6h Rel BV 622 F 3420 R26 1 1 1,2kohm ±5%; 0,25W B5 R29 1 9 Rel ap 6h Rel BV 622 F 3420 R26 1 1 1,2kohm ±5%; 0,25W B5 R29 1 9 Rel ap 6h Rel BV 622 F 3420 R26 1 1 1,2kohm ±5%; 0,25W B5 R29 1 9 Rel ap 6h Rel BV 622 F 3420 R26 1 1 1,2kohm ±5%; 0,25W B5 R29 1 9 Rel ap 6h Rel BV 622 F 3420 R26 1 1 1,2kohm ±5%; 0,25W B5 R29 1 9 Rel ap 6h Rel BV 622 F 3420 R26 1 1 1,2kohm ±5%; 0,25W B5 R29 1 1 9 Rel ap 6h Rel BV 622 F 3420 R26 1 1 1,2kohm ±5%; 0,25W B5 R29 1 1 9 Rel ap 6h Rel BV 622 F 3420 R26 1 1 1,5kohm ±5%; 0,25W B5	62702 - 2339 - F4
R6,22 R7 1 2,2kohm +5%; 0,25W B51263-A2703-J R8,9,12,14 R8,9,12,14 R8,9,12,14 R13 1 2,7 chm +5%; 0,33W B54413-A2270-J R15 R15 1 1kohm +5%; 0,33W B54413-A2270-J R17,18 R17 R19,20 R19,20 R2 R2 R2 R2 R3 R2 R3 R2 R3	40101 40 44
R8, 9, 12, 14 7 220 Ohm ±5%; 0, 25W B51265-A2222-J P1.2 Bichoszillator S45035-D641-B101, B401 A21, 26, 30 R10, 11 2 47 Ohm ±5%; 0, 33W B54413-A2270-J F1.2 R13 1 27 Ohm ±5%; 0, 33W B54413-A2270-J -B101-B401 R15 1 1kOhm ±5%; 0, 33W B54413-A2270-J -B101-B401 R15 1 1kOhm ±5%; 0, 33W B54413-A2270-J -B101-B401 R17, 18 2 1, 4kOhm ±1%; 0, 1W B51263-A9142-F 1 Formdraht, Brücke A WIRING-LINK A RIZENDE A R19, 20 2 1,5kOhm ±1%; 0, 1W B51263-A9152-F 1 Formdraht, Brücke B WIRING-LINK B R24 1 330 Ohm ±5%; 0, 33W B54413-A2331-J Schichtwiderstand LAYBR-TYPE RSSISTOR R26 1 2,7kOhm ±5%; 0, 25W B51263-A2272-J R15, 2 2 220 Ohm ±5%; 0, 33W B54413-A2390-J R16 1 11kOhm ±5%; 0, 25W B5 R27 1 39 Ohm ±5%; 0, 33W B54413-A2390-J R16 1 1 11kOhm ±5%; 0, 25W B5 R16 1 Schichtwirehreiderstand LAYBR-TYPE VAR RESISTOR 200 Ohm ±0%; 0, 135W B5 Ubertrager TRANSFORMER R19 1 1 10 Ohm ±5%; 0, 25W B5 U1 1 1 kel sp 75n Rel Ev 622 T 3075 R24 1 1 9, 1kOhm ±5%; 0, 25W B5 Spule COIL	42121-A9-A1
R6,9,12,14 7 220 0hm ±5%; 0,33W B54413-A2221-J CALIBRATING OSCILLATOR R10,11 2 47 0hm ±5%; 0,33W B54413-A2270-J FOR MODEL R13	
R10,11 2 47 Ohm ±5%; 0,33W B54413-A2470-J FOR MODEL R13 1 27 Ohm ±5%; 0,33W B54413-A2270-J -B101-B401 R15 1 1kohm ±5%; 0,33W B54413-A2270-J -B101-B401 R15 1 1kohm ±1%; 0,33W B54413-A2102-J 1 下ormdraht, Brücke A WIRING-LINK A S4 WIRING-LINK A S4 WIRING-LINK A WIRING-LINK A WIRING-LINK B S4 WIRING-LINK B S5 WIRING-LINK B S6	
R15 1 1kOhm ±5%; 0,33W B54413-A2102-J 1 Formdraht, Brücke A WIRING-LINK A S4 R17,18 2 1,4kOhm ±1%; 0,1W B51263-A9142-F 1 Formdraht, Brücke B S4 WIRING-LINK B S1263-A9152-F 1 Formdraht, Brücke B S4 WIRING-LINK B S0hichtwiderstand LAYER-TYPE RESISTOR S0hichtwiderstand LAYER-TYPE RESISTOR LAYER-TYPE RESISTOR B51263-A2272-J R15,25 2 2 200 0hm ±5%; 0,33W B54413-A2390-J R16 1 1 11kOhm ±5%; 0,25W B51263-A2272-J R15,25 2 2 200 0hm ±5%; 0,25W B51263-A2272-J R16 1 1 11kOhm ±5%; 0,25W B51263-A2272-J R16 1 1 10 0hm ±5%; 0,25W B51263-A2	
R17,18 2 1,4kOhm ±1%; 0,1W B51263-A9142-F R19,20 2 1,5kOhm ±1%; 0,1W B51263-A9152-F R24 1 330 Ohm ±5%; 0,33W B54413-A2331-J R25 1 900 Chm ±5%; 0,25W B51263-A2272-J R28 1 2,7kOhm ±5%; 0,25W B51263-A2272-J R29 1 39 Ohm ±5%; 0,33W B54413-A2390-J R16 1 11kOhm ±5%; 0,25W B51263-A2272-J R16 1 2chichttarehwiderstand LAYRR-TYPE NSISTOR 200 Ohm ±20%; 1W; lin Ubertrager TRANSFORMER U1 1 kel sp 75n Rel Ev 622 T 3075 R24 1 1 9,1kOhm ±5%; 0,25W B5 Spule COLL R28 1 1,2kOhm ±5%; 0,25W B5 R29 2 2 20 Ohm ±5%; 0,33W B54413-A2390-J R16 3 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1	
R17,18 2 1,4k0hm ±1%; 0,1W B51263-A9142-F R19,20 2 1,5k0hm ±1%; 0,1W B51263-A9152-F R24 1 330 0hm ±5%; 0,33W B54413-A2331-J R25 1 900 0hm ±5%; 0,33W B54413-A2901-J R28 1 2,7k0hm ±5%; 0,25W B51263-A2272-J R29 1 39 0hm ±5%; 0,33W B54413-A2390-J R16 1 11k0hm ±5%; 0,25W B51263-A2270-J R16 1 2k0hm ±5%; 0,25W B54413-A2390-J R16 1 1 1k0hm ±5%; 0,25W B5 R29 1 39 0hm ±5%; 0,33W B54413-A2390-J R16 1 1 2k0hm ±5%; 0,25W B5 R16 1 Schichtwiderstand LAYER-TYPE VAIRESISTOR 200 0hm ±20%; 1W; 1in R18 1 1 470 0hm ±5%; 0,25W B5 Ubertrager TRANSFORMER R29 1 1 0 0hm ±5%; 0,33W B5 Ubertrager TRANSFORMER R20 1 1 9 Rel sp 6h Rel Ev 622 T 3075 R24 1 1 9,1k0hm ±5%; 0,25W B5 Spule COIL R20 1 1 672 0hm ±1%; 0,33W B5	45035-D641-T2
R19,20 2 1,5k0hm ±1%; 0,1W B51263-A9152-F WIRING-LINK B R24 1 330 0hm ±5%; 0,33W B54413-A2331-J Sohichtwiderstand LAYER-TYPE RESISTOR R25 1 900 chm ±5%; 0,25W B51263-A2272-J R15,25 2 2 220 0hm ±5%; 0,33W B5 R29 1 39 0hm ±5%; 0,33W B54413-A2390-J R16 1 1 11k0hm ±5%; 0,25W B5 R16 1 Schichtarehwiderstand LAYER-TYPE VAR RESISTOR R16 1 2k0hm ±5%; 0,25W B5 R16 1 470 0hm ±5%; 0,25W B5 Ubertrager TRANSFORMER R19 1 1 10 0hm ±5%; 0,33W B5 Ut 1 1 kel sp 75n Rel Ev 622 T 3075 R24 1 1 9,1k0hm ±5%; 0,25W B5 Spule COLL R20 R20 1 1 672 0hm ±1%; 0,25W B5	
R25 1 900 Chm +5%; 0,33w B54413-A2901-J LATER-TTPE RSSISTOR R28 1 2,7k0hm +5%; 0,25w B51263-A2272-J R15,25 2 2 220 Ohm +5%; 0,33w B5 R29 1 39 Ohm +5%; 0,33w B54413-A2390-J R16 1 1 1 1 1 1 1 1 R16 1 Schichtdrehwiderstand LATER-TTPE VAR RESISTOR W40955-D8201-M001 R17 1 1 2 k0hm +5%; 0,25w B5 R16 1 Schichtdrehwiderstand W40955-D8201-M001 R17 1 1 2 k0hm +5%; 0,25w B5 R18 1 1 470 Ohm +5%; 0,33w B5 Ubertrager R19 1 1 10 Ohm +5%; 0,33w B5 Ubertrager R23 1 1 10 Ohm +5%; 0,25w B5 U1 1 Rel sp 75n Rel Ew 622 T 3075 R24 1 1 9,1k0hm +5%; 0,25w B5 U2 1 9 Rel sp 6h Rel Ew 622 P 3420 R26 1 1 1,2k0hm +5%; 0,25w B5 Spule COIL R28 1 1 672 Ohm +1%; 0,33w B5 COIL R38	45035-D641-T1
R25 1 900 chm ±5%; 0,33W B54413-A2901-J R28 1 2,7kohm ±5%; 0,25W B51263-A2272-J R15,25 2 2 220 ohm ±5%; 0,33W B5 R29 1 39 ohm ±5%; 0,33W B54413-A2390-J R16 1 1 11kohm ±5%; 0,25W B5 R16 1 Schichtarehwiderstand LAYRR-TYPE VAR RESISTOR 200 ohm ±20%; 1W; 1in Ubertragor TRANSPORMER R25 1 1 10 ohm ±5%; 0,33W B5 U1 1 kel sp 75n Rel By 622 T 3075 R24 1 1 9,1kohm ±5%; 0,25W B5 U2 1 9 Rel sp 6h Rel By 622 P 3420 R26 1 1 1,2kohm ±5%; 0,25W B5 Spule COIL	
R29 1 39 Ohm ±5%; 0,25W B51265-A2272-3 R16 1 1 11kOhm ±5%; 0,25W B5 R16 1 3 10kOhm ±5%; 0,25W B5 R17 1 1 2kOhm ±5%; 0,25W B5 R18 1 1 470 Ohm ±5%; 0,33W B5 Ubertrager TRANSFORMER U1 1 kel sp 75n Rel Ev 622 T 3075 R24 1 1 9,1kOhm ±5%; 0,25W B5 Spule COLL R18 1 1 1 1kOhm ±5%; 0,25W B5 R19 1 1 10 Ohm ±5%; 0,33W B5 R23 1 1 1 0kOhm ±5%; 0,25W B5 R24 1 1 9,1kOhm ±5%; 0,25W B5 R25 1 1 1 1,2kOhm ±5%; 0,25W B5	
R29 1 39 Ohm ±5%; 0,33W B54413-A2390-J R16 1 Schichtdrehviderstand LAYER-TYPE VAR RESISTOR 200 Ohm ±20%; 1W; lin Ubertrager TRANSFORMER U1 1 Rel sp 75n Rel Ev 622 T 3075 R24 1 1 9,1k0hm ±5%; 0,25W B5 U2 1 9 Rel sp 6h Rel Ev 622 P 3420 R26 1 1 1,2k0hm ±5%; 0,25W B5 Spule COLL	54413-A2221-J
#16 1 Schichtdrehviderstand LAYBR-TYPE VAR RRSISTOR R18 1 1 470 Ohm ±5%; 0,33W B5 Ubertrager TRANSFORMER R23 1 1 1 10 kohm ±5%; 0,25W B5 U1	51263-A2113-J
200 0 hm +20%; 1W; lin R19 1 1 10 0 hm ±5%; 0,33W B5	51263-A2202-J
Ubertrager TRANSFORMER R23 1 1 10k0hm ±5%; 0,25W B5	54413-A2471-J
### ### ##############################	54413-A2100-J
ti2 1 9 Rel sp 6h Rel Bv 622 F 3420 R26 1 1 1,2k0hm ±5%; 0,25W B5 Spule COIL R28 1 1 672 Ohm ±1%; 0,33W B5	51263-A2103-J 51263-A2912-J
Spule R28 1 1 672 Ohm ±1%; 0,33W B5	51263-A2122-J
COIL	54413-A9671-F200
11.5 2 Pol en 75m Pol Pol Co W 7002 R29 1 1 2,1kUhm +1%; 0,1W B5	51263-A9212-F
Rel By 622 T 3062 R31 1 1 20 0hm +1%; 0,15W B5	51264-A9200-F
HeI By 622 T 3065 R32 1 1 43.25 0hm +0.2%; 0.15W R5	51264-A9430-C250
1 Rel sp (2p Hel Bw 622 T 3064 - 835 1 1 167.2 Ohm +0.5%; 0.15W B5	51264-A9161-U720
R54 1 1 20 Ohm +0.2%; 0.15W R5	51264-A9200-C
AI-Annaensator STYROFLEX CAPACITOR R20 1 1 Schichtdrehwiderstand W4: LAYER-TYPE VAR RESISTOR	10955-A8202-M001
C2 1 B1mB 1.1mb 500U B24144 15040 B	
C3 1 59pF +1pF; 500V B31141-A5590-F 1 1 Staubschutzkappe C4-PROTECTION CAP	14408-Z3-03
CA 1 1100P 150 FOOT PYSIA 1514 P U1 1 Ubertrager Re	ol Bv 622 T 3133
C.S.	0440 B0774 W
C6 1 Keramik-Kondensator B38222-J5150-H600 C7 1 1 MKL-Kondensator B39 CERAMIC CAPACITOR CERAMIC CAPACITOR	32110-E9334-M
15,6pF ±2,5%; 500V; N150	1141-A1252-F
STYROFLEX CAPACITOR 106pF +1%; 500V MKL-Kondensator MKL-CAPACITOR C9,11 3 MKL-Kondensator B32110_C3475_W	
D)2110=0)4()=m	2110-E9154-M
C12 1 1 0,68 µF ±20%; 63V B3:	2110-E9684-M
TANTALUM ELECTROLYTIC CAPACITOR C13 1 1 Kermaik-Kondensator B3(10 uF +20%; 20V CERAMIC CAPACITOR 22pF +5%; 500V	8222 -J 52 2 0 - J
	60203-¥58-Н
C14 1 Kf-Kondensator B31141-A5101-F TRANSISTOR STYROFLEX CAPACITOR BCY 58 / VIII 100PF +1%; 500V Wert wie eingebaut 2 2 Halterung C4:	2121-&11-010
VALUE AS MOUNTED MOUNTING	
MKL-Kondensator 4 4 Isolierperle C4: MKL-CAPACITOR BEAD	2187-27-02
C16,18 2 0,15/uF +20%; 63V B32110-E9154-M Diode	
C17 1 0,33 /uF ±20%; 63V B32110-B9334-M	2004 1744
019,21 4 0,1/uF ±20%; 100V B32110-D0104-W	201-Y41
C2O 1 Tantal-Elko B45170-A4685-M	2702-Z339-F4 2121-A11-C7
C15 1 Lufttrimmer Rel ko 131f Pl.3 Umsetzer 2,4 MHz/100 kHz S45035-D643-A10 AIR-DIELECTRIC TRIMMER 2,511pF CONVERTER 2,4 MHz/100 kHz	1, A401
Transistor für Ausfg. TRANSISTOR FOR MODEL	
Te1,2,4 3 BCY 58 / VII Q60203-Y58-G -A101-A401	
Ta3 1 BCY 58 / VIII 060203 VER H Schichtwiderstand	
4 Halterung C42121-A11-C10 P1 4 775 P1	417-40774 7500
#OUNTING P2 1 1 5 1000m 1/0, 0,17 200	413-A9371-F500 263-A9512-F
Diodenquartett V42292-E4-A3 DIODE QUARTET R3 1 1 4 ADDR-146.0 19	263-A9432-F
4xOA90 rauscharm 4xOA90 LOW NOTSE	413-A2221-J
Gri, 2 Diode Pel TV. 672 P too R54	413-A2221-J 263-A2182-J
DIODE 2/4 4 4 2 2 2 4 2 2 2 4 2 2 2 4 2 2 2 4 2 2 2 4 2 2 4 2 2 2 4 2 2 2 4 2	413-A2331-J

					26.2			
R7 .	1	1	270 Ohm +5%; 0,33W	B54413-A2271-J	R6,7	2	390 Ohm ±5%; 0,33W	B54413-A2391-J
R8 11	4	4	1kOhm +1%; 0,33W	B54413-A9102-F	R8	1	1,8kChm +5%; 0,25W	B51263-A2182-J
R14	1	1	18kOhm ±5%; 0,25W	B51263-A2183-J	R3	1	Schichtdrehwiderstand LAYER-TYPE VAR RESISTOR	W40955-A8202-M001
R15	1	1,	5,6k0hm +5%; 0,25W	B51263-A2562-J			2k0hm +20%; 1W; lin	
R16	1	1	180 Ohm +5%; 0,33W	B54413-A2181-J		1	Staubschutzkappe PROTECTION CAP	U44408-Z3-C3
R17	1	1	3,3k0hm +5%; 0,25W	B51263-A2332-J			Übertrager	
R18,26	2	2	1k0hm ±5%; 0,33W	B54413-A2102-J			TRANSFORMER	
R19	1	1	330 Ohm +1%; 0,33W	B54413-A9331-F	tt 1	1	Rel sp 75n	Rel Bv 622 T 3070
R22	1	1	27kOhm +5%; 0,25W	B51263-A2273-J	₩2	1	Rel sp 75n	Rel Bv 622
R23	1	1	6,8k0hm +5%; 0,25W	B51263-A2682-J			Kf-Kondensator	
R24	1	1	2,2kChm +5%; 0,25W	B51263-A2222-J			PLASTIC-FOIL CAPACITOR	
R25	1	1	100 Ohm +5%; 0,33W	B54413-A2101-J	C1,8	2	2400pF ±1%; 125V	B31141- :242-F
R27	1		1,8kChm +1%; 0,25W	B51263-A2182-F	03,6	2	147pF ±1%; 500V	B31141-A5141-F700
R27		1	2kChm +1%; 0,25W	B51263-A2202-F	C4	1	218pF ±1%; 500V	B31141-A5211- 8CO
R31	. 1	1	10k0hm +5%; 0,25W	B51263-A2103-J	C7	1	205pr +1%; 500V	B31141-A5201-F500
R32	1	1	2,7kChm +5%; 0,25W	B51263-A2272-J	09,12	2	MKL-Kondensator MKL-CAPACITOR	В32110-Е91,4-М
R33	1	1	47 Ohm +5%; 0,33W				0,15/ur +20%; 63V	
R35	1	1		B54413-A2470-J	C1 0	1	Keramik-Kondensator	B38222-A5200-J
1())		'	75 (hm ±5%; 0,33W	B54413-A2750-J			CERAMIC CAPACITOR 20pF +5%; 500V	
			Ubertrager TRANSFORMER		C11	1	Tantal-Elko TANTALUM ELECTROLYTIC CAPACITOR	B45170-A4685-M
tt1	1	1	9 Rel sp 5n	Rel Bv 622 N 3564			6,8 ur ±20%; 35V	
tt2	1	1	9 Rel sp 5n	Rel Bv 622 N 3565	02,5	2	Lufttrimmer	Rel ko 130cb
# 3	1	1	9 Rel sp 75n	Rel Bv 622 T 3077			AIR-DIELECTRIC TRIMMER 231pF	
			Spule		Kr1,2	2	Filter-Quarz	Q83402-A9998-F500
			COIL				FILTER-CRYSTAL Q34; f = 99,985 kHz	
L1,2	2	2	9 Rel sp 5n	Rel Bv 622 N 3562		2	Quarzhalterung	C42121-A25-A2
L3	1	1	9 Rel sp 5n	Rel Bv 622 N 3563		_	CRYSTAL-MOUNTING	V4L /L V-RE J-RE
01	1	1	Kf-Kondensator STYROFLEX CAPACITOR 884pF ±1%; 500V	B31141-A5881-F400	Te1	1	Transistor TRANSISTOR BCY 58 / VIII	Q60203-Y58-J
02,5	2	2	Keramik-Kondensator CERAMIC CAPACITOR 180pF +1%; 500V; N033	B38240-J5181-F		1	Halterung MOUNTING	C42121-A11-C
С3	1	1	Kf-Kondensator STYROFLEX CAPACITOR	B31141-A5111-F600		2 .	Isolierperle BEAD	C42187-Z7-C2
C4	1	1	116pF ±1%; 500V Kf-Kondensator PLASTIC-FOIL CAPACITOR	B31141-A5841-F600	P1.5		lter II S45035-D645-A701 FILTER II Schichtwiderstand	
			846pF ±1%; 500V				LAYER-TYPE RESISTOR	
C6	1	1	Keramik-Kondensator CERAMIC CAPACITOR 16,9pF +2,5%; 500V; N150	В38222-J5160-H900	R1	1	590 Ohm +1%; 0,33W	B54413-A959'-F
C7	1	1	132pF ±1%; 500V; NO47	B38248-J5131-F200	R2,6 R7	3	390 Ohm ±5%; 0,33W Wert wie eingebaut VALUE AS MOUNTED	B54413-A2391-J
08,10,15	9	9	MKL-Kondensator	B32110-E9154-M	D.4	1		DE4067 40407 P
017,18,21 023,25,27			MKL-CAPACITOR 0,15,uF +20%; 63V	3	R4		10k0hm +1%; 0,1W	B51263-A9103-F
09,14	2	2	Tantal-Elko	B45170-A3106-M	R5	1	9,1k0hm ±1%; 0,1W	B51263-A9912-F
			TANTALUM ELECTROLYTIC CAR 10/uF +20%; 20V	ACITOR	R8 R3	1	1,8k0hm ±5%; 0,25W Schichtdrehwiderstand LAYER-TYPE VAR RESISTOR	B51263-A2182-J W40955-A8202-M001
013	1	1	Kf-Kondensator PLASTIC-FOIL CAPACITOR 4900pF ±1%; 125V	B31141-A1492-F		1	2kOhm +20%; 1W; lin Staubschutzkappe	C44408-Z3-C3
			Keramik-Kondensator CERAMIC CAPACITOR				PROTECTION CAP	
016	1	1	330pF +30-20% 500V	B37635-B5331-R000			TRANSFORMER	
C22	1	1	15pF +5%; 500V	B38222-A5150-J	Ü 1	1	Rel sp 75n	Rel Bv 622 T 3071
C26	1	1	Tantal-Elko	B45170-A4685-M	Ü2	1	Rel sp 75n	Rel Bv 622 T 3072
			TANTALUM ELECTROLYTIC CAP 6,8,uF ±20%; 35V	ACITOR	Ü3	1	Rel sp 75n	Rel Bv 622 T 3073
Ma2	1	1	Diodenquartett	V42292-E4-A3			Kf-Kondensator PLASTIC-FOIL CAPACITOR	
			DIODE QUARTET 4 x OA 90		01,9	2	567pF +1%; 500V	B31141-A5561-F700
			rauscharm/LOW NOISE		03,5,8	3	58pF +1pF; 500V	B31141-A5580-F
Ts1	5	5	Transistor TRANSISTOR	Q60203-Y58-H	C6	1	130pF +1%; 500V	
,	5	5	BCY 58 / VIII Halterung	C42121-A11-C10	010,13	2	MKL-Kondensatór MKL-CAPACITOR	B32110-E9154-**
	4-	1.	MOUNTING				0,15/uF +20%; 63V	
	10	10	Isolierperle BEAD .	C42187-27-C2	C11	1	Keramik-Kondensator CERAMIC CAPACITOR 20pF +5%; 500V	B38222-A5200-J
P1.4			ter I <u>S45035-D644-A701</u> PLITER I	**	C12	1	Tantal-Elko TANTALUM ELECTROLYTIC CAPACITOR 6,8/uF ±20%; 35V	B45170-A4685-M
·			Schichtwiderstand LAYER-TYPE RESISTOR		02,4,7	3	Lufttrimmer AIR-DIELECTRIC TRIMMER	Rel ko 130cb
R1	1		590 Ohm +1%; 0,33W	B54413-A9591-F			231pF	
R4	1		10k0hm +1%; 0,1W	B51263-A9103-F	Kr1,2	3	Filter-Quarz	Q83402-A9994-F
R5	1		15k0hm +1%; 0,1W	B51263-A9153-F	Kr3		FILTER-CRYSTAL Q34; f _o = 99,940 kHz	

	3	Qu	arzhal terung	C42121-A25-A2	R19	1 1	1	560 Ohm +5%; 0,33W	B54413-A2561-J
			YSTAL-MOUNTING		R20	1	1	180 Ohm ±1%; 0,33W	B54413-A9181-F
Ts1	1	TR	ansistor ANSISTOR 7 58 / IX	Q60203-Y58-J	R21 R26	1	1	22k0hm <u>+</u> 5%; 0,25\ 2,5k0hm +1%; 0,1\	B51263-A2223-J
	1		l terung	C42121-A11-C10	R26	•	1	2,2kOhm +1%; 0,1W	B51263-A9252-F
		MOT	INTING		R27	1		923 Ohm +0,2%; 0,15W	B51263-A9222-F B51264-A9921-0300
	2	Isc	olierperle	C42187-Z7-C2	R27		1	1614 Ohm +0,2%; 0,15W	
P1.6	100-1	Hz-Fi	lter S45035-D646-B701		R28	1	1	30 Ohm +0,2%; 0,15W	B51264-A9162-C140
	100-1		nichtwiders tand		R29	1	1	· .	B51264-A9300-C
			CER-TYPE RESISTOR		R30	1	1	27 Ohm +5%; 0,33W 570 Ohm +1%; 0,33W	B54413-A2270-J
R1	1	590	Ohm +1%; 0,33W	B54413-A9591-F	R31	1	'	100 Ohm +0,2%; 0,15W	B54413-A9571-F
R4	1	101	:Ohm +1%; O,1W	B51263-A9103-H	R31		1	60 Ohm +0,2%; 0,15W	B51264-A9101-C
R5	1	7,5	6kOhm +1%; 0,1W	B51263-A9752-F	R32	1	1	Thernewid	B51264-A9600-C
R6,7	2	390	Ohm +5%; 0,33W	B54413-A2391-J	1		,	THERM. RESISTOR 20 Ohm +10%; 2580°K	Q63011-K200-K
R8	1	1,8	kOhm ±5%; 0,25W	B51263-A2182-J				Spule	
R3	1	LAY	ichtdrehwiderstand ER-TYPE VAR RESISTOR hm +20%; 1W; lin	w40955-⊅8202 -M001	L1	1	1	COIL Rel sp 75n	V45231 03016
		Spu	_		L2 .	1.	1		V45231-C3016
		COI			F2 .	1	1	Rel sp 75n	V45231-03017
L1	1	Rel	sp 75n	V45231-03016	т)	'	,	Rel sp 75n	V45231-03018
L2	1	Rel	s p 75n	V45231-03017				MKL-Kondensator MKL-CAPACITOR	
L3	1	Rel	sp 75n	V45231-C3018	01,4,5	8	8	0,1/uF +20%; 100V	В32110-D0104-М
			Kondensator STIC-FOIL CAPACITOR		06,8,10 011,12			,	
C1	1	4920	OpF +1%; 125V	B31141-A1492-F200	C2,7,13	4	4	1/uF +20%; 63V	В32110-Е9105-М
C2	1		oF +1%; 500V	B31141-A5141-F600	03,9	2	2	Keramik-Kondensator CERAMIC CAPACITOR	B37635-B5271-R000
03	1		3pF +1%; 125V	B31141-A1472-F980				270pF +30-20%; 500V	
34	1		oF +1pF; 500V	B31141-A5121-F200	C15	1 .	1	Kf-Kondensator PLASTIC-FOIL CAPACITOR	B31141-A1492-F200
C 5	1	4944	1pF +1%; 125V	B31141-A1492-F440	~			4920pF ±1%; 125V	
06,9	2		-Kondensator	B32110-E9154-M	C16	1	1	146pF ±1%; 500V	B31141-A5141-F600
			CAPACITOR 5/uF ±20%; 63V		C17	1	1	4798pF ±1%; 125V	B31141-A1472-F980
C 7	1		mik-Kondensator	B38222-A5200-J	C18	1	1	122pF .+1pF; 500V	B31141-A5121-F200
			MIC CAPACITOR 3 +5%; 500V		019	1	, 1	4944pF +1%; 125V	B31141-A1492-F440
C8	1	Tant	al-Elko	B45170-A4685-M	Н,Ј,	3	3	S-G-Relais	Rel Bv 662 E 56
		6,8/	CALUM ELECTROLYTIC CAPACITOR LE +20%; 35V	,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,	K Gr1,2	7	,	DRY-REED RELAY Rel rls 24a	<i>(</i>
Ts1	1	TRAN	sistor SISTOR 58 / IX	Q60203-Y58-J	Gr3	3	3	Diode DIODE AA 118	ų60101 - X118
	1		erung TING	C42121-A11-C10	Ta1.	6	6	Transistor TRANSISTOR BCY 58 / VIII	Q60203-Y58-H
	2	Isol BEAD	ierperle	042187-27-02		6	6	Hal terung MOUN TING	C42121-A11-C10
P1.7	10	0-kHz-	Verstärker S45035-D647-B101 PREAMPLIFIER	, B401		4	4	Isolierperle BEAD	C42187-Z7-C2
	für A		REAMFLIFIER		P1.8		Breith	andverstärker S45035-D648	-R701
	FOR M	ODEL			- 240		WIDEBA	ND AMPLIFIER	-B[0]
	-B101	-B401						Schichtwiderstand LAYER-TYPE RESISTOR	
			Schichtwiderstand		R1		1		DE40(2 10052 D
R1	1	1	LAYER-TYPE RESISTOR 18k0hm +5%; 0,25W	BE4067 10407	R2		1	25k0hm ±1%; 0,1W 6,2k0hm ±1%; 0,1W	B51263-A9253-F B51263-A9622-F
R2,3	2	2	3,9k0hm +1%; 0,1W	B51263-A2183-J	R3		1	2,2kChm +5%; 0,25W	B51263-A9022-F B51263-A2222-J
R4,10,25	3	3	680 Ohm +5%; 0,33W	B51263-A9392-F	R4,12		2	1k(hm +5%; 0,33W	B54413-A2102-J
R5	1		280 Ohm +1%; 0,33W	B54413-A2681-J	R5,20		2	200 Ohm +1%; 0,33W	B54413-A9201-F
R5		1	230 Ohm +1%; 0,33W	B54413-A9281-F	R6,22		2	270 Ohm +5%; 0,33W	
R6	1	1	27kChm +5%; 0,25w	B54413-A9231-F	R7,8		2	_	B54413-A2271-J
R7,22	2	2	6,8k0hm +5%; 0,25W	B51263-A2273-J	R9,18		2	220 Ohm +5%; 0,33W	B54413-A2221-J
R8,23	2	2	_	B51263-A2682-J	R10			3,3k0hm ±5%; 0,25W	B51263-A2332-J
R9,24	2	2	2,2k0hm ±5%; 0,25W 82 Ohm ±5%; 0,33W	B51263-A2222-J	R11,23		1	15kChm +5%; 0,25W	B51263-A2153-J
R11	1	1		B54413-A2820-J			2	2,7k0hm +5%; 0,25W	B51263-A2272-J
R12,15	2	2	1,8k0hm +1%; 0,1W	B51263-A9182-F	R13		1	56 Chm +5%; 0,33W	B54413-A2560-J
R13	1		270 Ohm +5%; 0,33W	B54413-A2271-J	R14		1	200 Ohm +5%; 0,33W	B54413-A2201-J
R13		1	658,7 Ohm +0,2%; 0,15W	B51264-A9651-C870	R15,27		2	4kOhm +1%; 0,1W	B51263-A9402-F
R14	1		274,2 Ohm ±0,2%; 0,15W	B51264-A9271-C420	R16		1	120 Ohm +5%; 0,33W	B54413-A2121-J
R14		1	224 Ohm +0,2%; 0,15\\	B51264-A9221-C400	R17,24		2	18k0hm +5%; 0,25W	B51263-A2183-J
R16	1	1	104,7 Ohm +0,2%; 0,15W	B51264-A9101-C470	R19		1	1,2k0hm +5%; 0,25W	B51263-A2122-J
R17	1	1	27k0hm ±1%; 0,1₩	B51263-A9273-F	R21		1	100 Ohm +5%; 0,33W	B54413-A2101-J
R18	1	1	6,8k0hm +1%; 0,1W	B51263-A9682-F	R25		1	1,6k0hm +5%; 0,25W	B51263-A2162-J
			3,3k0hm ±5%; 0,25₩	B51263-A2332-J	R26		1	43 Ohm ±5%; 0,33W '	B54413-A2430-J

			1	D17	4	701-01- 14d o 48	DC4067 AD707 T
R28,29	2.	2,5k0hm +1%; 0,1W	* B51263-A9252-F	R17 R13,15	1 2	38k0hm +1%; 0,1% Schichtdrehwiderstand	B51263-A9383-F W40955-A8103-M001
R34	1 .	3,3k0hm +1%; 0,1W	B51263-A9332-F B51263-A9822-F	x,,,,,	-	LAYER-TYPE VAR RESISTOR 10k0hm +20%; 1W; lin	##U///-AU/U/-AU/U
R36	1	8,2k(hm +1%; 0,1W	B51263-A9122-F		2	Staubschutzkappe	C44408-Z3-C3
R37 R35	1	1,2k0hm ±1%; 0,1W Schichtdrehwiderstand	W40955-A8202-M001		-	PROTECTION CAP	044400 27 07
K))	'	LAYER-TYPE VAR RESISTOR 2kOhm +20%; 1W; lin	HACTYT-ROLLE MOO.	C1	1	Tantal-Elko TANTALUM ELECTROLYTIC CAPACIT 47/uF +20%; 20V	B45170-J3476-M COR
	1	Staubschutzkappe PRCTECTION CAP	C44408+Z3-C3	02,4	2	68 uF +20%; 20V	B45170-J3686-M
L1	1	Spule COIL Rel sp 74i	Rel Bv 622 S 3388	С3	1	Keramik-Kondensator CERAMIC CAPACITOR 10pF +1pF; 500V	B38222-A5100-F
01,9	2	MKL-Kondensator MKL-CAPACITOR 6,8/uF +20%; 63V	ъ32110- E 9685-М	C5	1	Tantal-Elko TANTALUM ELECTROLYTIC CAPACITO 150/uF +20%; 15V	B45170-J2157-M
C2	1	Tantal-Elko TANTALUM ELECTROLYTIC CAPAC	B45170-A3476-M ITCR	c 6	1	MKH-Kondensator MKH-CAPACITOR 0,047,uF +20%; 250V	B32220-K3473-M
С3	1	47/uF ±20%; 20V Keramik-Kondensator JERAMIC CAPACITOR	В38222-А5270-Н	Ts1,2	2	Transistor TRANSISTOR 2 N 2218	ų62702-S0002
		27pF ±2,5%; 500V Tantal-Elko Tantalum ELECTROLYTIC CAPA	CITCR		2	Halterung MOUNTING	C42121-A11-C6
C4	1	47 /uF +20&; 10V	B45170-A1476-M		2	Kühlschelle	C42121-Z21-C2
C5	1	10/uF ±20%; 20V	B45170-A3106-M			COOLER-SLEEVE	
06,11	2	68 uf +20%; 20V	B45170-A3686-M	Gr1,2	2	Diode DIODE	Q60101-X118
C7	1	100/uF +20%; 10V	B45170-A1107-M			AA 118	
C10	1	Keramik-Kondensator CERAMIC CAPACITOR	B38222-A5080-D		2	Isolierperle BEAD	C42187-Z7-C2
012	1	8pF ±0,5pF; 500V Tantal-Elko	B45170-A3156-M		Netz1	ceil I S45035-D650-A701	
		TANTALUM ELECTROLYTIC CAPA 15/uF +20%; 20V			1	Netzeingang MAINS INPUT	S45035-D652-A701
014,15	2	MKL-Kondensator MKL-CAPACITOR 4,7/uF +20%; 63V	В32110-Е9475-М			Schichtwiderstand LAYER-TYPE RESISTOR	
		Keramik-Kondensator CERAMIC CAPACITOR		R2	1	400 Ohm +5%; 0,33W	B54413-A2401-J
046	1		B38222-A5300-J	R3	1	2,5kOhm +1%; 0,1W	B51263-A9252-F
C16	r	30pF +5%; 500V Wert wie eingebaut VALUE AS MOUNTED	B)0222-R))00-0	R4	1	27,5kOhm +1%; 0,1W	B51263-A9273-F500
C18	1		B38222-A5060-D	C1.	4	Llko	B41611-B8257-S
019	1	6pF +0,5pF; 500V Tantal-Elko	B4517U-A2476-M	••4		ELECTROLYTIC CAPACITOR 250 pur +50-20%; 70V	
019	٠	TANTALUM ELECTROLYTIC CAPA 47/uF ±20%; 15V		Т1	1	Drucktastenschalter PUSHBUTTON SWITCH	C44315-Z2-01
		Lufttrimmer AIR-DIELECTRIC TRIMMER		Gr1	1	Silizium-Kleingleichrichter-	- V23212-01406
08,13	2	2,35pF	Rel ko 131e			satz SILICON RECTIFIER SETUP	•
C17	1	2,511pF	Rel ko s31f			B40 C2C00	&62702-U7
r .	1	S-G-Relais DRY-REED RELAY Rel rls 24a	Rel Bv 662 E 56	Ts1	1	Transistor TRANSISTOR 2 N 3054	₩ 02 02-0
Gr1,2	2	Diode DIODE	Rel TL 672 R 108	в5,6	2	Buchseneinheit JACK ASSEMBLY C42334-A175-A2O	V42255-B7-B15
Ts1.	7	OA 90 Transistor TRANSISTOR	Q60203-Y58-H	Bu7	1	Gerätebuchse COAX JACK 1,6/5,6	C42334-A76-A14
	7	BCY 58 / VIII Halterung	C42121-A11-C10	Bu8	1	Gerätebuchse JACK	C42334-Z3-C79
	6	MOUNTING Isolierperle	C42187-Z7-C2		1	Behälter für Ersatzteile CONTAINER FOR SPARES	C44165-A11-C2
P1.9		BEAD ungsverstärker und Demodulator			1	Lampenfassung LAMP-HOLDER	C42230-A3-A1
***7	POWER	AMPLIFIER AND DEMODULATOR Schichtwiderstand	0-1/0/) 00-4/-A-[0]	SL1	1	Signallampe SIGNAL LAMP 247/0,6W	Fg lp 62be
		LAYER-TYPE RESISTOR					
R1,4	2	6,2k0hm +5%; 0,25W	B51263-A2622-J			ingang S45035-D652-A701	
R2	1	9,1k0hm +5%; 0,25W	B51263-A2912-J	Tr1	1	Netztransformator	Rel Bv 621 G 3125
R3	1	120 Ohm +5%; 0,33W	B54413-A2121-J			POWER TRANSFORMATOR Zub tr MD 65c	
R5	1	1kOhm ±5%; 0,33W	B54413-A2102-J			Wicklg.I (AI, EI)	
R6	1	82 Ohm +5%; 0,33W	B54413-A2820-J			824 Windg. 0,24 CuL; 38 Ohm Wicklg.II (AII, EII)	
R7	1	15 Ohm +5%; 0,33W	B54413-A2150-J			824 Windg. 0,24 CuL; 42 Ohm	
R8	1	51 Ohm +5%; 0,33W	B54413-A2510-J			Wicklg. III (AIII, EIII/2c, 260 Windg. 0,50 CuL; 3,6 Oh	im
R9	1	390 Ohm +5%; 0,33W	B54413-A2391-J	\$8	1	Netzeinbaustecker mit	Rel Bv 654 A 3002
R10	1	73 Ohm +1%; 0,33W	B54413-A9730-F			Spannungswähler POWER SOCKET WITH VOLTAGE	ADJUSTER
R11	1	3,9k0hm +5%; 0,25W	B51263-A2392-J			C44334-A11-A1	
R12	1	43k0hm +1%; 0,1W	B51263-A9433-F		1	G-Sicherungshalter FUSE HOLDER	C42327-Z13-C1
R14	1	10k0hm +1%; 0,1W	B51263-A9103-F		1	G-Schraubkappe	U42327-Z12-C2
R16	1-1	91k0hm +1%; 0,1W	B51263-A9913-F			FUSE CAP	

P1.10	Netzte POWER	eil II S45035-D651-A701 SUPPLY UNIT II	
		Schichtwiderstand LAYER-TYPE RESISTOR	
R1,2,8	3	1,8k0hm +5%; 0,25W	B51263-A2182-J
R3	1	100k0hm +5%; 0,25W	B51263-A2104-J
R4,10,16	3	2,7k0hm +5%; 0,25W	B51263-A2272-J
R6,13	2	1,2k0hm +5%; 0,25W	B51263-A2122-J
R7	1	820 Ohm +5%; 0,33\	B54413-A2821-J
R9	1 1	3,3kOhm ±5%; 0,25\	B51263-A2332-J
R12	1	1,6kOhm +5%; 0,25W	B51263-A2162-J
R14	1	430 Ohm ±5%; 0,33\	B54413-A2431-J
R5,11 R15	3	Schichtdrehwiderstand LAYER-TYPE VAR RESISTOR 1kChm +20%; 1W; lin	W50955-A8102-M001
	3	Staubschutzkappe PROTECTION CAP	C44408-Z3-C3
01,3 06	3	Keramik-Kondensator CERAMIC CAPACITOR 1000pF +50-20%; 500V	B37623-B5102-S
	6	Isolierperle BEAD	042187-27-02
		Tantal-Elko TANTALUM ELECTROLYTIC CAN	PACITOR
C2,4	2	47/uF ±20%; 20V	B45170-A3476-M
C5,7	2	68/uF ±20%; 20V	B45170-A3686-M
Gr2,3 Gr4	3	Zenerdiode ZENER DIODE Z7	Q62702-Z339-F4
	3	Falterung MOUNTING	C42121-A9-A1
02,3 05,6 08	5	Transistor TRANSISTOR 2 N 3053	Q62702-L15
	5	Halterung MOUNTING	C42121-A11-C6
	2	Kühlschelle für Ts2,3 COOLER-SLEEVE FOR Ts2,3	C42121-Z21-C2
Ts4,7	2	Transistor TRANSISTOR 2 N 3054	¥62702-U7

Oszillat OSCILLAT		01600 kHz S45034-D36	9- <u>4702</u>		R21	1	1k0hm ±5%; 0,33	B54413-A2102-J
)1600 kHz	7(00		R23	1	22kOhm +5%; 0,25W	B51263-A2223-J
		elmesser S45034-D354-B302 METER S45034-D354-B302, B			R25	1	2,2k0hm +5%; 0,25W	B51263-A2222-J
					R26,34	2	15k0hm +5%; 0,25W	B51263-A2153-J
Symbol SYMBOL	Stck QTY	Gegens tand DESCRIPTION	Bestellangabe ORDERING DATA	Seite PAGE	R27,35	2	3kOhm +5%; 0,25W	B51263-A2302-J
					R30,38	2	180 Ohm ±1%; 0,33W	B54413-A9181-F
Pl.1	1	Rasteroszillator-	\$45035-W667-A701		R31	1	68 Ohm +5%; 0,33W	B54413-A2680-J
		Platte 1 SPECTRUM OSCILLATOR			R32,39	2	300 Ohm +1%; 0,33\	B54413-A9301-F
		BOARD 1			R33,40	2	1,2k0hm +5%; 0,25W	B51263-A2122-J
P1.2	1	Rasteroszillator- Platte 2	\$45035-W668-A701		R41,43	2	200 Ohm +5%; 0,33W	B54413-A2201-J
		SPECTRUM OSCILLATOR BOARD 2			R42	1	910 Ohm ±5%; 0,33W	B54413-A2911-J
P1.3	1	Rasteroszillator- Platte 3 SPECTRUM OSCILLATOR	S45035-D623-A701		Ü1, 2	2	Übertrager TRANSFORMER Rel sp 82i	Rel Bv 622 W 3040
	-1	BOARD 3 Verdrahtungsleiter- platte	S45035-#670-A701		L1	1	Spulentopf COIL-CAN C44330-A3-A1	Rel Bv 623 G 3062
R1,2	2	PRINTED CIRCUIT BOARD Schichtwiderstand	DEAA12 NO7EO P		C14 C11,13, C1417	12	MKH-Kondensator MKH-CAPACITOR 0,01/uF +20%; 250V	В32220-К3103-М
	2	LAYER-TYPE RESISTOR 75 Ohm +1%; 0,33W	B54413-A9750-F		C2O,22		Keramik-Kondensator CERAMIC CAPACITOR	
C1	1	Lufttrimmer AIR-DIELECTRIC TRIMMER 1,35pF	Rel ko 131ac		¢5	1	7pF +0,5pF; 500V Wert wie eingebaut VALUE AS MOUNTED	в38226-J5070-D
C3	1	Keramik-Kondensator CERAMIC CAPACITOR 2pr +0,25pF; 500V	B38212-A5020-C		C7	1	15pF <u>+</u> 5%; 500V Kf-Kondensator	B38226-J5150-J
K 1	1	Drehko	Hel TL 632 B 3002a2				PLASTIC-FOIL CAPACITOR	
		VAR. CAPACITOR 17U/10 pF			C8	1	150pF ±2,5%; 500♥	В31141-А5151-Н
		COO1 ZZ195 (Fa.Valvo)			C 9	1	1000pF ±2,5%; 500V	B31141-A5102-H
Sz1	1	Allsichtschauzeichen INDICATOR h'grün/orange br'green/orange	v45282-23009-A1		C12	1	MKL-Kondensator MKL-CAPACITOR 0,15/uF +20%; 63V	В32110-E9154-M
s 6	. 1	Kleindrehschalter MIDGET ROTARY SWITCH	C40315-M303-N1		C18	1	MKH-Kondensator MKH-CAPACITOR 0,022/uF +20%; 250V	В32220-К3223-М
	1	Kurbel-Drehknopf ROTARY KNOB FOR CRANK 37 p	C44106-A20-A2		019,21	2	Kf-Kondensator PLASTIC-FOIL CAPACITOR 100pF +5%; 500V	B31141-A5101-J
	1	Drehknopf ROTARY KNOB Knebelgriff	C44106-A20-A3 Rel antr 93c		¢6	1	Lufttrimmer AIR-DIELECTRIC TRIMMER 1,719pF	Rel ko 130ca
	•	KNOB	ner and yye		Gr1,2	2	Germaniumdiode	Rel TL 672 R 108
Bu9	1	Gerätebuchse gerade COAX JACK 1,6/5,6	C42334-A76-A14				GERMANIUM-DIODE OA 90	
		Schaltbuchse SWITCHING JACK			Gr3	1	Varaktordiode VARACTOR-DIODE HC 7004B 70pF +5%; bei/AT -4V/2500	Rel TL 672 R129 a1
BuA	1	1,6/5,6 (2u)	C42334-A76-A36		Gr4	1	Zenerdiode	Q62702-Z339-F4
BuB	1	1,6/5,6 (1a,1r)	C42334-A76-A34		G14	· ·	ZENER DIODE	4 02/02-2)))-14
	1	Filmskalenantrieb FILM-SCALE DRIVE 1m grob/fein	C44106-A7-A4			1	Z7 Halterung MOUNTING	C42121-A9-A1
	1	1m COARSE/FINE Membrankupplung MEMBRANE DRIVE COUPLIN	C44106-A5-A61		Ts1	9	Transistor TRANSISTOR BCY 58 / VIII	Q60203-Y58-H
P1.1	Raste	Proszillator-Platte 1 S4	5035- \ 667 -\ 701			9	Halterung MOUNTING	C42121-A11-C10
		Schichtwiderstand LAYER-TYPE RESISTOR			Pl.2		eroszillator-Flatte 2 S4503	5- W 668- <u>A701</u>
R1	1	56kOhm +5%; 0,25W	B51263-A2563-J				Schichtwiderstand	
R2	1	18k0hm +1%; 0,1W	B51263-A9183-F				LAYER-TYPE RESISTOR	
R3	1	6,8k0hm ±1%; 0,1W	B51263-A9682-F		R1,2	2	2,2k0hm +5%; 0,25W	B51263-A2222-J
R4,29 R37	3	47 Ohm +5%; 0,33W	B54413-A2470-J		R3	1	300 Ohm +1%; 0,33W	B54413-A9301-F
R5,19 R28,36	4	1k0hm +1%; 0,33W	B54413-A9102-F		R4	1	600 Ohm +1%; 0,33W	B54413-A9601-F
R6	1	150 Ohm ±5%; 0,33W	B54413-A2151-J		R5,6,33	3	220 Ohm +5%; 0,35W	B54413-A2221-J
R7	1	2,5kOhm +1%; 0,1W	B51263-A9252-F		R7	1	12kOhm <u>+</u> 5%; 0,25\	B51263-A2123-J
R8,9 R13	3	30k0hm +1%; 0,1W	B51263-A9303-F		R8	1	16k0hm <u>+</u> 5%; 0,25W	B51263-A2163-J
R10	1	47kOhm +1%; 0,1W	B51263-A9473-F		R9	1	2,4kOhm +5%; 0,25W	B51263-A2242-J
R11	1	22kOhm +1%; 0,1W	B51263-A9223-F		R10	1	1,8k0hm +5%; 0,25\	B51263-A2182-J
R12	1	47kOhm +5%; 0,25W	B51263-A2473-J		R11	1	200 Ohm +1%; 0,33W	B54413-A9201-F
R14	1	18k0hm +5%; 0,25W	B51263-A2183-J		R12	1	30k0hm +5%; 0,25\	B51263-A2303-J
R15,22	2	15k0hm +5%; 0,25W	B51263-A2153-J		R14	1	3,9k0hm <u>+</u> 1%; 0,1W	B51263-A9392-F
R16,18	3	100 Ohm ±5%; 0,33W	B54413-A2101-J		R15,38	2	8,2kOhm <u>+</u> 5%; 0,25W	B51263-A2822-J
R24 R17	1	285 Ohm +1%; 0,33W	B54413-A9281-F	500	R16,34	2	1,2kOhm ±5%; 0,25W	B51263-A2122-J
R20	1	200 Ohm ±5%; 0,33W	B54413-A2201-J		R17	1	270 Ohm +5%; 0,33W	B54413-≜2271-J

R 18	1	150 Ohm ±5%; 0,33W	B54413-A2151-J	R10	1	5,6k0hm +1%; 0,25W	B51263-A2562-F
R19	1	47kOhm ±5%; 0,25W	B51263-A2473-J	R11	1	820 Ohm ±5%; 0,33W	B54413-A2821-J
R20,21	2	3,9k0hm +1%; 0,1W	B51263-A9392-F	R13	1	50kOhm +1%; 0,1W	B51263-A9503-F
R22,26	2	2k0hm +1%; 0,1W	B51263-A9202-F	R14	1	3,9kOhm +5%; 0,25W	B51263-A2392-J
R23	1	22k0hm +1%; 0,1W	B51263-A9223-F	R15	1	1,5k0hm +5%; 0,25W	B51263-A2152-J
R25,32	2	5,6k0hm +1%; 0,1W	B51263-A9562-F	R16	1	6,2kOhm +5%; 0,2W	B51362-A2622-J
R27	1	360 Ohm +1%; 0,33W	B54413-A9361-F	R17	1	75kOhm ±5%; 0,33W	B51263-A2753-J
R28	1	3k0hm +1%; 0,1W	B51263-A9302-F	R18	1	56 Ohm ±5%; 0,33W	B54413-A2560 - J
2 29	1	1k0hm +1%; 0,33W	B54413-A9102-F	R19	1	200 Ohm ±1%; 0,33W	B54413-A9201-F
R30	1	30k0hm +1%; 0,1W	B51263-A9303-F	R20	1	120 Ohm +1%; 0,33W Wert wie eingebaut	B54413-A9121-F
R35	1	4,7kOhm +5%; 0,25W	B51263-A2472-J			VALUE AS MOUNTED	
R36	1	470 Ohm +5%; 0,33W	B54413-A2471-J	R21	1	30kOhm +5%; 0,25W	B51263-A2303-J
R37	1	56kOhm +5%; 0,25W	B51263-A2563-J	R22	1	6,8k0hm +5%; 0,25W	B51263-A2682-J
R39	1	330 Ohm ±5%; 0,33₩	B54413-A2331-J	R23	1	56kOhm +1%; 0,1W	B51263-A9563-F
R13	1	Schichtdrehwiderstand LAYER-TYPE VAR RESISTOR 5kOhm +20%; 1W; lin	W40955-A8502-M001	R24 R25	1	560 Ohm ±1%; 0,33W 18kOhm ±5%; 0,25W	B54413-A9561-F B51263-A2183-J
	1	Staubschutzkappe	U44408-23-03	R26,34	2	1,2kOhm +1%; 0,1W	B51263-A9122-F
704 74		PROTECTION CAP	0(7044 VED4 V	R27	1	2,7kOhm +1%; 0,1W	B51263-A9272-F
R24,31	2	Thernewid THERM. RESISTOR	Q63011-K501-K	R28	1	1,8kOhm <u>+</u> 5%; 0,25W	B51263-A2182-J
		K11c / 3000°K		R29	1	390 Ohm +1%; 0,33W	B54413-A9391-F
		Ubertrager TRANSFORMER		R31	1	150 Ohm +5%; 0,33W	B54413-A2151-J
Ü1	1	C42035-A10-A3	V45231-03137	R33	1	12kChm +5%; 0,25W	B51263-A2123-J
tt2	1	C42035-A10-A3	V45231-03138	R35,36	2	12kChm +1%; 0,1W	B51263-A9123-F
		Spule COIL		R37	1	100 Ohm +5%; 0,33W	B54413-A2101-J
L1	1		D-1 D- 600 W 3041	R38	1	1,8kOhm +1%; 0,1W	B51263-A9182-F
L2	1	Rel sp 82i	Rel Bv 622 W 3041 Rel Bv 622 W 3042	R39	1	220 Ohm +5%; 0,33W	B54413-A2221-J
01,2,7	3	Rel sp 82i MKH-Kondensator MKH-CAPACITOR	B32220-E9154-M	R40	1	Thernewid THERM.RESISTOR 20k0hm ±5%; 3250°K	Q63011-K203-J
C3,5,6 C10,20	5	0,022/uF +20%; 250V MKL-Kondensator MKL-CAPACITOR	B32110-E9154-M			Ubertrager TRANSFORMER	
010,20		0,15/uF +20%; 63V		Ü1	1	C42035-A10-A3	V45231-03139
C4	1	Kf-Kondensator PLASTIC-FOIL CAPACITOR	B31141-A5601-J	₩2	1	Rel sp 82i	Rel Bv 622 W 3035
		600pF ±5%; 500V MKL-Kondensator				Spule COIL	
		MKL-CAPACITOR		L1	1	Rel sp 82i	Rel Bv 622 W 3043
C8, C1619	5	1,5 _/ uF ±20%; 63V	B32110-E9155-M	L2	1	Rel sp 82i	Rel Bv 622 W 3044
09	1	0,68 uF +20%; 63V	B32110-E9684-M			Kf-Kondensator	
		Kf-Kondensator				PLASTIC-FOIL CAPACITOR	
211	4	PLASTIC-FOIL CAPACITOR	774444 44000 T	C2	1	80pF ±5%; 500V	B31141-A5800-J
C11	1	2000pF ±5%; 125V	B31141-A1202-J	03	1	500pF ±1%; 500V	B31141-A5501-F
012	1	4240pF +1%; 125V	B31142-A1422-F400	C46, C8,11,23	8	MKL-Kondensator MKL-CAPACITOR	В32110-Е9154-М
013	1	1190pF +1%; 125V	B31141-A1112-F900	025		0,15/UF +20%; 63V	
C14 C15	1	9540pF ±1%; 125V 5300pF ±1%; 125V	B31142-A1952-F400 B31142-A1532-F	c7	1	Kf-Kondensator PLASTIC-FOIL CAPACITOR 60pF +5%; 500V	B31141-A5600-J
C21	1	MKL-Kondensator MKL-CAPACITOR O,47/uF +20%; 63V	В32110-Е9474-М	С9	1	Keramik-Kondensator CERAMIC CAPACITOR 22pF +5%; 500V	B38222-J5220-J
		Germaniumdiode GERMANIUM DIODE		C10	1	Kf-Kondensator PLASTIC-FOIL CAPACITOR	B31141-A1252-F
Gr1,2	2	OA 159	Q62701-A49-F2	74.0		2500pF ±1%; 125V	
Gr3,4 Ta1	2	OA 90 Transistor	Rel TL 672 R 108 Q60203-Y58-H	C12	1	Tantal-Elko TANTALUM ELECTOLYTIC CAPA 22/uF +20%; 15V	B45170-A2226-M ACITOR
••9	9	TRANSISTOR BCY 58 / VIII	042121 411 010	C13,18 C19,20	4	MKH-Kondensator MKH-CAPACITOR 0,01/uF +20%; 250V	B32220-K3103-M
	7	Hal terung MOUNTING	C42121-A11-C10			Keramik-Kondensator	
P1.3	Rast	eroszillator-Platte 3 S45035	-D623-A701	C14	1	CERAMIC CAPACITOR 66pF +2%; 500V	B38221-J5660-G
	SFEC	TRUM OSCILLATOR BOARD 3		C16	1	20pF +2,5%; 500V	В38221-Ј5200-Н
		Schichtwiderstand LAYER-TYPE RESISTOR		C17	1	32pF +2%; 500V	B38221-J5320-G
R1	1	300 Ohm ±5%; 0,33W	B54413-A2301-J	C22	1	Kf-Kondensator	B31141-A1132-F200
R2,12	2	15kOhm +5%; 0,25W	B51263-A2153-J			PLASTIC-FOIL CAPACITOR 1320pF +1%; 125V	
R3,6	2	4,7kOhm +5%; 0,25W	B51263-A2472-J	024	1	MKL-Kondensator	B32110-E9224-M
R4	1	10 Ohm ±5%; 0,33W	B54413-A2100-J			MKL-CAPACITOR 0,22/uF +20%; 63V	
R5,32	2	22kOhm +5%; 0,25W	B51263-A2223-J			Lufttrimmer	
R7,30	2	2,2k0hm +5%; 0,25W	B51263-A2222-J			AIR-DIELECTRIC TRIMMER	
THE	1	2,2k0hm +1%; 0,1W	B51263-A9222-F	C1	1	231 pF	Rel ko 130cb
R9	1	220 Ohma +1%; 0,33W	B54413-A9221-F	015	1	2,511 pF	Rel ko 131f

Kr1	1	Steuer-Quarz CONTROL-CRYSTAL Q34; f=100kHz	: -Q83404-A1000-G
	1	Hal terung MOUNTING	C42121-A25-A2
Kr2	1	Filter-Quarz FILTER-CRYSTAL Q31; f=2,23975MHz	Q83124-02239-H75
	1	Hal terung . MOUNTING	C42121-A25-A1
Gr1,2	2	Germanium-Diode GERMANIUM DIODE OA 90	Rel TL 672 R 108
Gr3	1	Zener-Diode ZENER DIODE SZ 7 KB	Q62604-K7-B
	1	Hal terung MOUNTING	C42121-A9-A1
Gr4	1	Germanium-Diode GERMANIUM DIODE AAY 26	Q60101-Y26
Gr5	1	Silizium-Diode SILICON DIODE BAY 30	Q60201 - Y30
	1	Halterung MOUNTING Transistor	∪42121 - A9-A1
		TRANSISTOR	
Ts1,2 Ts610	7	BCY / VIII	Q60203+Y58-H
Ts3,4	2	2 N 2218	Q62702-S0002
Ts5	1	MM 1614	Q62702-S55-F6
		Hal terung MOUNTING	
	7	für Ts1,2,610 FOR Ts1,2,610	C42121-A11-C10
	3	für Ts35 FOR Ts35	C42121-A11-C6
	8	Isolierperle BEAD	C42187-Z7-C2
	Verdr PRINT	ahtungsleiterplatte S45035-W6	70-A701
C1	1	Tantal-Elko TANTALUM ELECTROLYTIC CAPACITOR 4,7,uF ±20%; 20V	B45170-A3475-M
L1	1	Drossel REACTOR 70/uH/0,2A	B82501-A-C18
	8	Lötstift SOLDERING PIN	022195-Z11-01

Verwendung: Pegelmesser S45034-D354-B302, B602 R20	%; 0,33W B54413-A9101-F %; 0,33W B54413-A2661-J %; 0,33W B54413-A2471-J %; 0,33W B54413-A2821-J
USED IN: LEVEL METER \$45034-D354-D302, B602 R22 1 100 Ohm ±190	%; 0,33W B54413-A2561-J %; 0,33W B54413-A2471-J %; 0,33W B54413-A2821-J
Symbol Stok Gegenstand Bestellangabe CRDERING DATA DESCRIPTION DESCRIPTION R24 1 470 Ohm ±5%	%; 0,33W B54413-A2471-J %; 0,33W B54413-A2821-J
SYMBOL QTY DESCRIPTION ORDERING DATA PAGE R24 1	%; 0,33W B54413-A2821-J
P1.1 1 Interpolator- Platte 1 INTERPOLATOR BOARD 1	
F1.1 TRANSFORMER Platte 1	
### BOARD 1	<u> </u>
F1.2 Interpolator	Rel Bv 622 W 3032
INTERPOLATOR BOARD 2 MKL-Kondens MKL-CAPACIT F1.3 1 Interpolator- \$45035-D627-A701 C1 1 C,68 \(\text{uF} \\ \pm \) 2 Flatte 3	Rel Bv 622 P 3417
Platte 3	
	0%; 63V B32110-E9684-M
BOARD 3	0%; 63V B32110-E9154-M
1 · Verdrahtungs- S45035-W674-A701 C6,8,14 3 0,33/UF +20	0%; 63V B3211C-E9334-M
leiterplatte Keramik-Kon PRINTED CIRCUIT BOARD	
R1 1 Schichtwiderstand B54413-A9601-F C11 1 90pF +1%; 5	B38241-J5900-F003
LAYER-TYPE RESISTOR C12 1 15pF ±5%; 5	B38246-J5150-J003 ingebaut/VALUE AS MOUNTED
C2 1 Lufttrimmer Rel ko 131ac C13,16 2 MKL-Kondensa MKL-CAPACITC AIR-DIELECTRIC TRIMMER C15.5 P + 20%.	B32110-E9155-M
CZ 1 Variable Variance Process FOCO TOOK C10 1 Lufttrimmer	Rel ko 130cb
GERAMIC CAPACITOR 6pF +0,5pF; 500V 4IR-DIELECTR 231pF	RIC TRIMMER
K2 1 Drehko Rel TL 632 B 3002a1 Gr1 1 Diode VAR. CAPACITOR 0A 159	Q627U1 -A49-F2
C001 ZZ168 (Fa.Valvo) Gr2 1 Zenerdiode Sz2 1 Allsichtschauzeichen V45282-Z3009-A1	Q62702-2339-F4
INCIGATE INCIGATE h'grun/orange br'green/orange 1 Halterung MOUNTING	U42121-A9-A1
S7 1 Kleindrehschalter C40315-M303-N1 Ts1 7 Transistor7 Transistor	4 60203- Y 58- H
1 Kurbel-Drehknopf C44106-A20-A2 BCY 58 / VII ROTARY KNOB FOR CRANK 37 6 7 Halterung	C42121-A11-C10
1 Drehknopf C44106-A20-A3 Place T-to-place Place	0.45075 W/30 >304
ROTARY KNOB P1.2 Interpolator-Platte 2 INTERPOLATOR BOARD 2	545055-W0[2-A[0]
1 Knebelgriff Rel antr 93c Schichtwider ROTARY KNOB Schichtwider LAIER-TYPE R	
U1 1 Ubertrager V45231-F3082 R1,7 2 33kOhm +5%;	0,25W B51263-A2333-J
BuD 2 Gerätebuchse gerade C42334-A76-A14 R2 1 5,1kOhm +5%;	
Bu10 COAX JACK 1,6/5,6 R3 1 2,7kOhm +5%;	; 0,25W B51263-A2272-J
EuC 1 Schaltbuchse C42334-A76-A34 R4 1 330 Ohm +1%;	; 0,33W B54413~A9331-F
SWITCHING JACK 1,6/5,6; (1a, 1r) R5,13 2 8,2k0hm ±1%;	B51263-A9822-F
1 Filmskalenantrieb C44106-A7-A4 R6 1 270 Ohm ±5%;	; 0,33W B54413-A2271-J
FILM-SCALE DRIVE 1m grob/fein R8 1 5,6k0hm ±5%;	; 0,25W B51263-A2562-J
1m COARSE/FINE R10,11,14 3 5,6k0hm +1%;	B51263-A9562-F
1 Membrankupplung C44106-A5-A61 R12 1 2,5k0hm ±1%;	B51263-A9252-F
Pl.1 Interpolator-Platte 1 S45035-W671-A701 R15 1 3,9k0hm +5%;	B51263-A2392-J
INTERPOLATOR BOARD 1 R16,18 2 8,2k0hm +5%;	B51263-A2822-J
Schichtwiderstand R17 1 1k0hm ±5%; LAYER-TYPE RESISTOR	0,33W B54413-A2102-J
R1,12,21 3 150 Ohm +5%; 0,33W B54413-A2151-J	%; 0,25W B51263-A2152-J
R20,27 2 820 Ohm +5%; 0,25W B51263-A2272-J	%; 0,33W B54413-A2821-J
R3 1 2,7kOhm +1%; 0,1W B51263-A9272-F	0,1W B51263-A9302-F
R4 1 1k0hm ±1%; 0,33W B54413-A9102-F	0,33W B54413-A9102-F
R5 1 27kOhm +5%; 0,25W B51263-A2273-J	%; 0,33W B54413-A9621-F
R6 1 8,2k0hm +1%; 0,1W B51263-A9822-F	; 0,1W B51263-A9273-F
R7 1 5,6k0hm ±1%; 0,1W B51263-A9562-F	%; 0,25W B51263-A2912-J
R8,25 3 6,8kOhm +5%; 0,25W B51263-A2682-J R28 1 680 Ohm +1%	%; 0,33W B54413-A9681-F
R28 Thernewid R9,13,29 3 18kOhm +5%; 0,25W B51263-A2183-J THERM. RESI	ISTOR
R10,30 2 330 Ohm ±5%; 0,33W B54413-A2331-J R30 1 200 Ohm ±5%	
R11,31 2 1,8k0hm +5%; 0,25W B51263-A2182-J R31 1 1k0hm +5%;	
R14 1 4,3k0hm +5%; 0,25W B51263-A2432-J U1 1 Ubertrager	
R15 1 4,7k0hm +1%; 0,1W B51263-A9472-F	!
R16 1 200 Ohm ±1%; 0,33W B54413-A9201-F COIL	Rel Bv 622 W 3034
R17 1 1kOhm +5%; 0,33W B54413-A2102-J C1 1 Kf-Kondensa	ator B31141-A1202-J
	IL CAPACITOR ; 125V

		MKL-Kondensator MKL-CAPACITOR		Ü4	1	Rel sp 82i	Rel Bv 622 W 3038
C2	1		D20110 D0474 M	Ü5	1	9 Rel sp 6h	Rel Bv 622 P 3418
03,6	2	0,47 _/ uF ±20%; 63V 0,1 _/ uF ±20%; 100V	B32110-E9474-M B32110-D0104-M	C1	1	Keramik-Kondensator CERAMIC CAPACITOR	B38221-J5660-J
C4	1	Keramik-Kondensator CERAMIC CAPACITOR	B38211-J5080-D	02,6,8,9	12	66pF ±5%; 500V MKH-Kondensator MKH-CAPACITOR	B32220-K3103-M
C5	1	8pF ±0,5pF; 500V MKH-Kondensator MKH-CAPACITOR	В32220-К3473-М	01113, 01517, 019,23		0,01/uF +20%; 250V	
07		0,047/uF ±20%; 250V				Keramik-Kondensator CERAMIC CAPACITOR	
C7 , ·	1	MKL-Kondensator MKL-CAPACITOR	В32110-Е9225-М	C3	1	25pF +2%; 500V	B38221-J5250-G
		2,2/uF +20%; 63V Kf-Kondensator		C 5	1 .	32pF <u>+</u> 2%; 500V	B38221-J5320-G
08,10	2	PLASTIC-FOIL CAPACITOR 5000pF +5%; 125V	DZ1140 41500 T			Kf-Kondensator PLASTIC-FOIL CAPACITOR	
	1		B31142-A1502-J	C7	1	113pF +1%; 500V	B31141-A5111-F300
09	1	10000pF +5%; 125V	B31142-A1103-J	C10	1	1000pF +5%; 500V	B31141-A5102-J
		MKL-Kondensator MKL-CAPACITOR		C14	1	444pF ±1%; 500V	B31141-A5441-F400
C11,12 C15,16	4	4,7 _/ uF <u>+</u> 20%; 63V	В32110-Е9475- Ж	C18	1	MKL-Kondensator MKL-CAPACITOR	B32110-D0104-M
013 .	1	0,68/uF +20%; 63V	В32110-Е9475-М			0,1/uF ±20%; 100V	
C14 .	1	0,22/uF +20%; 63V	В32110-Е9224-М			Keramik-Kondensator CERAMIC CAPACITOR	
C17 _.	1	Kf-Kondensator PLASTIC-FOIL CAPACITOR	B31141-A5101-J	°20	1	90pF +2%; 500V	B38221-J5900-G
		100pF ±5%; 500V		C22	1	36pF <u>+</u> 2%; 500♥	B38222-J5360-G
Gr1 ••4	4	Diode DIODE	Rel TL 672 R 108			Lufttrimmer AIR-DIELECTRIC TRIMMER	
		0▲ 90		C4	1	2,511pF	Rel ko 131f
		Transistor TRANSISTOR		021	1	1,719pF	Rel ko 130ca
Ts13	5	BCY 58 / VIII	Q60203-Y58-H	Kr1	1		Q83124-C2239-H750
Ts5,6	.1	2 N 3250	Q62702 - F76	KT.		Filter-Quarz FILTER'CRYSTAL Q31; F=2,23975 MHz	407124-02275-1170
	6	Hal terung	C42121-A11-C10		1	Halterung	C42121-A25-A1
	0	MOUNTING	042121-R11-010		·	MOUNTING	042121-A27-A1
	2	Isolierperle BEAD	C42187-Z2-C2	Gr1,2	2	Diode DIODE	Rel TL 672 R 108
P1.3	Interpola INTERPOLA	tor-Platte 3 S45035-D627-A701 TUR BOARD 3	1	Gr3	1	Zener-Diode ZENER DIODE Z7	Q62702-Z339-F4
		Schichtwiderstand LAYER-TYPE RESISTOR			1	Hal terung	C42121-A9-A1
R1,5	2	33kOhm +5%; 0,25W	B51263-A2333-J	0-5 6	2	MOUNTING	Dol MT 672 P 120c10
R1,5	2		B51263-A2333-J B51263-A2822-J	Gr5,6	2	MOUNTING Varaktordiode VARACTOR DIODE	Rel TL 672 R 129a10
R2		33kOhm <u>+</u> 5%; 0,25W		Gr5,6	2	MOUNTING Varaktordiode	
R2 R3	1	33kOhm ±5%; 0,25W 8,2kOhm ±5%; 0,25W	B51263-A2822-J	Gr5,6 Md1	2	MOUNTING Varaktordiode VARACTOR DIODE 70pF +5%; bet/AT -4V/25°C HC 7004B (Fa.Hughes) Richtleiterquartett	
R2 R3 R4,25	1	33kOhm ±5%; 0,25W 8,2kOhm ±5%; 0,25W 56kOhm ±1%; 0,1W	B51263-A2822-J B51263-A9563-F			MOUNTING Varaktordiode VARACTOR DIODE 70pF +5%; bei/AT -4V/25°C HC 7004B (Fa.Hughes)	
R2 R3 R4,25 R6	1 1 2	33kOhm ±5%; 0,25W 8,2kOhm ±5%; 0,25W 56kOhm ±1%; 0,1W 560 Ohm ±1%; 0,33W	B51263-A2822-J B51263-A9563-F B54413-A9561-F	Md1		MOUNTING Varaktordiode VARACTER DIODE 70pF +5%; bei/AT -4V/25°C HC 7004B (Fa.Hughes) Richtleiterquartett DIODE QURTET 4XOA 90 Transistor	
R2 R3 R4,25 R6 R7 R8,18,20	1 1 2 1	33kOhm ±5%; 0,25W 8,2kOhm ±5%; 0,25W 56kOhm ±1%; 0,1W 560 Ohm ±1%; 0,33W 1,2kOhm ±1%; 0,1W	B51263-A2822-J B51263-A9563-F B54413-A9561-F B51263-A9122-F	Md1	. 1	MOUNTING Varaktordiode VARACTOR DIODE TOPF +5%; bet/AT -4V/25°C HC 7004B (Fa.Hughes) Richtleiterquartett DIODE QURTET 4x0A 90	V42292-E4-A1
R2 R3 R4,25 R6 R7 R8,18,20 R37	1 1 2 1 1	33kOhm ±5%; 0,25W 8,2kOhm ±5%; 0,25W 56kOhm ±1%; 0,1W 560 Ohm ±1%; 0,33W 1,2kOhm ±1%; 0,1W 10kOhm ±5%; 0,25W 470 Ohm ±5%; 0,33W	B51263-A2822-J B51263-A9563-F B54413-A9561-F B51263-A9122-F B51263-A2103-J	Md1	. 1	MOUNTING Varaktordiode VARACTOR DIODE TOPF +5%; bet/AT -4V/25°C HC 7004B (Fa.Hughes) Richtleiterquartett DIODE QURTET 4x0A 90 Transistor TRANSISTOR BCY 58 / VIII Halterung	V42292-E4-A1
R2 R3 R4,25 R6 R7 R8,18,20 R37	1 1 2 1 1 4	33k0hm ±5%; 0,25W 8,2k0hm ±5%; 0,25W 56k0hm ±1%; 0,1W 560 0hm ±1%; 0,33W 1,2k0hm ±1%; 0,1W 10k0hm ±5%; 0,25W 470 0hm ±5%; 0,35W 680 0hm ±5%; 0,33W	B51263-A2822-J B51263-A9563-F B54413-A9561-F B51263-A9122-F B51263-A2103-J B54413-A2471-J	Md1	1 8	MOUNTING Varaktordiode VARACTOR DIODE TOPF +5%; bei/AT -4V/25°C HC 7004B (Fa.Hughes) Richtleiterquartett DIODE QURTET 4x0A 90 Transistor TRANSISTOR BCY 58 / VIII Halterung MOUNTING	V42292-E4-A1 Q60203-Y58-H 042121-A11-010
R2 R3 R4,25 R6 R7 R8,18,20 R37 R9 R10,23,34	1 1 2 1 1 4	33kOhm ±5%; 0,25W 8,2kOhm ±5%; 0,25W 56kOhm ±1%; 0,1W 560 Ohm ±1%; 0,33W 1,2kOhm ±1%; 0,1W 10kOhm ±5%; 0,25W 470 Ohm ±5%; 0,33W 680 Ohm ±5%; 0,33W	B51263-A2822-J B51263-A9563-F B54413-A9561-F B51263-A9122-F B51263-A2103-J B54413-A2471-J	Md1	1 8 8 Verdral	MOUNTING Varaktordiode VARACTOR DIODE TOPF +5%; bet/AT -4V/25°C HC 7004B (Fa.Hughes) Richtleiterquartett DIODE QURTET 4x0A 90 Transistor TRANSISTOR BCY 58 / VIII Halterung	V42292-E4-A1 Q60203-Y58-H 042121-A11-010
R2 R3 R4,25 R6 R7 R8,18,20 R37 R9 R10,23,34 R11	1 1 2 1 1 4 1 3	33kOhm ±5%; 0,25W 8,2kOhm ±1%; 0,25W 56kOhm ±1%; 0,33W 1,2kOhm ±1%; 0,1W 10kOhm ±5%; 0,25W 470 Ohm ±5%; 0,33W 680 Ohm ±5%; 0,33W 150 Ohm ±5%; 0,33W 300 Ohm ±1%; 0,33W	B51263-A2822-J B51263-A9563-F B54413-A9561-F B51263-A9122-F B51263-A2103-J B54413-A2471-J B54413-A2681-J B54413-A2151-J	Md1	1 8 8 Verdral	MOUNTING Varaktordiode VARACTOR DIODE 70pF +5%; bei/AT -4V/25°C HC 7004B (Fa.Hughes) Richtleiterquartett DIODE QURTET 4XOA 90 Transistor TRANSISTOR BCY 58 / VIII Halterung MOUNTING	V42292-E4-A1 Q60203-Y58-H C42121-A11-C10 74-A701 B45170-A3475-M
R2 R3 R4,25 R6 R7 R8,18,20 R37 R9 R10,23,34 R11 R12	1 1 2 1 1 4 4 1 3 1 1 1	33kOhm ±5%; 0,25W 8,2kOhm ±1%; 0,25W 56kOhm ±1%; 0,33W 1,2kOhm ±1%; 0,1W 10kOhm ±5%; 0,25W 470 Ohm ±5%; 0,35W 680 Ohm ±5%; 0,33W 150 Ohm ±5%; 0,33W 300 Ohm ±1%; 0,33W 390 Ohm ±5%; 0,33W	B51263-A2822-J B51263-A9563-F B54413-A9561-F B51263-A9122-F B51263-A2103-J B54413-A2471-J B54413-A2681-J B54413-A2151-J B54413-A9301-F	Md1	1 8 8 Verdral PRINT	MOUNTING Varaktordiode VARACTOR DIODE 70pF +5%; bei/AT -4V/25°C HC 7004B (Fa.Hughes) Richtleiterquartett DIODE QURTET 4X0A 90 Transistor TRANSISTOR BCY 58 / VIII Halterung MOUNTING intungsleiterplatte \$45035-W6 DO TROUTT BOARD Tantal-Elko	V42292-E4-A1 Q60203-Y58-H C42121-A11-C10 74-A701 B45170-A3475-M
R2 R3 R4,25 R6 R7 R8,18,20 R37 R9 R10,23,34 R11 R12 R1316,28	1 1 2 1 1 4 4 1 3 1	33k0hm ±5%; 0,25W 8,2k0hm ±5%; 0,25W 56k0hm ±1%; 0,1W 560 %hm ±1%; 0,33W 1,2k0hm ±1%; 0,1W 10k0hm ±5%; 0,25W 470 0hm ±5%; 0,33W 150 0hm ±5%; 0,33W 300 0hm ±1%; 0,33W 300 0hm ±5%; 0,33W 300 0hm ±5%; 0,33W	B51263-A2822-J B51263-A9563-F B54413-A9561-F B51263-A9122-F B51263-A2103-J B54413-A2471-J B54413-A2681-J B54413-A2151-J B54413-A9301-F B54413-A2391-J	Md1	1 8 8 Verdral PRINT	MOUNTING Varaktordiode VARACTOR DIODE TOPF +5%; be1/AT -4V/25°C HC 7004B (Fa.Hughes) Richtleiterquartett DIODE QURTET 4XOA 90 Transistor TRANSISTOR BCY 58 / VIII Halterung MOUNTING AUMINISTIC S45035-W6 DO CHROUTT BOARD Tantal-Elko TANTALUM ELECTROLYTIC BOA 4,7/uf ±20%; 20V Drossel REACTOR	V42292-E4-A1 Q60203-Y58-H C42121-A11-C10 74-A701 B45170-A3475-M
R2 R3 R4,25 R6 R7 R8,18,20 R37 R9 R10,23,34 R11 R12	1 1 2 1 1 1 4 4 1 3 1 1 1 5	33kOhm ±5%; 0,25W 8,2kOhm ±1%; 0,25W 56kOhm ±1%; 0,33W 1,2kOhm ±1%; 0,1W 10kOhm ±5%; 0,25W 470 Ohm ±5%; 0,35W 680 Ohm ±5%; 0,33W 150 Ohm ±5%; 0,33W 300 Ohm ±1%; 0,33W 390 Ohm ±5%; 0,33W	B51263-A2822-J B51263-A9563-F B54413-A9561-F B51263-A9122-F B51263-A2103-J B54413-A2471-J B54413-A2681-J B54413-A2591-J B54413-A2391-J B54413-A9301-F	Md18 Ts18	1 8 8 Verdral PRINT!	MOUNTING Varaktordiode VARACTOR DIODE 70pF +5%; bei/AT -4V/25°C HC 7004B (Fa.Hughes) Richtleiterquartett DIODE QURTET 4×0A 90 Transistor TRANSISTOR BCY 58 / VIII Halterung MOUNTING Itungsleiterplatte \$45035-W6 ED CIRCUIT BOARD Tantal-Elko TANTALUM ELECTROLYTIC BOA 4,7/UF +20%; 20V Drossel REACTOR 70/uH/0,2A	V42292-E4-A1 Q60203-Y58-H C42121-A11-C10 74-A701 B45170-A3475-M RD B82501-A-C18
R2 R3 R4,25 R6 R7 R8,18,20 R37 R9 R10,23,34 R11 R12 R1316,28 R17	1 1 2 1 1 1 4 4 1 1 3 1 1 1 5 1 1	33kOhm ±5%; 0,25W 8,2kOhm ±5%; 0,25W 56kOhm ±1%; 0,1W 560 Ohm ±1%; 0,33W 1,2kOhm ±1%; 0,1W 10kOhm ±5%; 0,25W 470 Ohm ±5%; 0,33W 150 Ohm ±5%; 0,33W 300 Ohm ±5%; 0,33W 390 Ohm ±5%; 0,33W 1,2kOhm ±5%; 0,33W 1,2kOhm ±5%; 0,25W 3,9kOhm ±5%; 0,25W	B51263-A2822-J B51263-A29563-F B54413-A9561-F B51263-A2103-J B54413-A2471-J B54413-A2681-J B54413-A2151-J B54413-A2391-J B54413-A2391-J B54413-A9151-F B51263-A2122-J	Md18 Ts18	1 8 8 Verdral PRINT	MOUNTING Varaktordiode VARACTOR DIODE TOPF +5%; be1/AT -4V/25°C HC 7004B (Fa.Hughes) Richtleiterquartett DIODE QURTET 4XOA 90 Transistor TRANSISTOR BCY 58 / VIII Halterung MOUNTING AUMINISTIC S45035-W6 DO CHROUTT BOARD Tantal-Elko TANTALUM ELECTROLYTIC BOA 4,7/uf ±20%; 20V Drossel REACTOR	V42292-E4-A1 Q60203-Y58-H C42121-A11-C10 74-A701 B45170-A3475-M RD
R2 R3 R4,25 R6 R7 R8,18,20 R37 R9 R10,23,34 R11 R12 R1316,28 R17	1 1 2 1 1 1 4 4 1 3 1 1 5 1 1 1 1	33kOhm ±5%; 0,25W 8,2kOhm ±5%; 0,25W 56kOhm ±1%; 0,1W 560 Ohm ±1%; 0,33W 1,2kOhm ±5%; 0,25W 470 Ohm ±5%; 0,33W 480 Ohm ±5%; 0,33W 490 Ohm ±5%; 0,33W 390 Ohm ±5%; 0,33W 150 Ohm ±1%; 0,33W 150 Ohm ±5%; 0,25W 20kOhm ±5%; 0,25W	B51263-A2822-J B51263-A9563-F B54413-A9561-F B51263-A9122-F B51263-A2103-J B54413-A2471-J B54413-A2681-J B54413-A2151-J B54413-A2301-F B54413-A2391-J B54413-A2151-F B51263-A2122-J B51263-A2392-J	Md18 Ts18	1 8 8 Verdral PRINT!	MOUNTING Varaktordiode VARACTUR DIODE TOPF +5%; bei/AT -4V/25°C HC 7004B (Fa.Hughes) Richtleiterquartett DIODE QURTET 4X0A 90 Transistor TRANSISTOR BCY 58 / VIII Halterung MOUNTING DIRGUIT BOARD Tantal-Elko TANTALUM ELECTROLYTIC BOA 4,7/AF ±20%; 20V Drossel REACTOR 70/uH/0,2A Lötstift	V42292-E4-A1 Q60203-Y58-H C42121-A11-C10 74-A701 B45170-A3475-M RD B82501-A-C18
R2 R3 R4,25 R6 R7 R8,18,20 R37 R9 R10,23,34 R11 R12 R1316,28 R17 R19 R21	1 1 2 1 1 4 4 1 3 1 1 1 5 1 1 1 1 1	33kOhm ±5%; 0,25W 8,2kOhm ±5%; 0,25W 56kOhm ±1%; 0,1W 560 Ohm ±1%; 0,33W 1,2kOhm ±1%; 0,1W 10kOhm ±5%; 0,25W 470 Ohm ±5%; 0,33W 150 Ohm ±5%; 0,33W 300 Ohm ±5%; 0,33W 390 Ohm ±5%; 0,33W 1,2kOhm ±5%; 0,33W 1,2kOhm ±5%; 0,25W 3,9kOhm ±5%; 0,25W	B51263-A2822-J B51263-A9563-F B54413-A9561-F B51263-A9122-F B51263-A2103-J B54413-A2471-J B54413-A2681-J B54413-A2511-J B54413-A2391-J B54413-A2511-F B51263-A2122-J B51263-A2392-J B51263-A2203-J	Md18 Ts18	1 8 8 Verdral PRINT!	MOUNTING Varaktordiode VARACTUR DIODE TOPF +5%; bei/AT -4V/25°C HC 7004B (Fa.Hughes) Richtleiterquartett DIODE QURTET 4X0A 90 Transistor TRANSISTOR BCY 58 / VIII Halterung MOUNTING DIRGUIT BOARD Tantal-Elko TANTALUM ELECTROLYTIC BOA 4,7/AF ±20%; 20V Drossel REACTOR 70/uH/0,2A Lötstift	V42292-E4-A1 Q60203-Y58-H C42121-A11-C10 74-A701 B45170-A3475-M RD B82501-A-C18
R2 R3 R4,25 R6 R7 R8,18,20 R37 R9 R10,23,34 R11 R12 R1316,28 R17 R19 R21 R22	1 1 2 1 1 4 4 1 3 1 1 1 5 1 1 1 1 1 1	33kOhm ±5%; 0,25W 8,2kOhm ±1%; 0,1W 560 Ohm ±1%; 0,33W 1,2kOhm ±5%; 0,25W 470 Ohm ±5%; 0,33W 150 Ohm ±5%; 0,33W 300 Ohm ±5%; 0,33W 390 Ohm ±5%; 0,33W 150 Ohm ±5%; 0,33W 170 Ohm ±5%; 0,33W 170 Ohm ±5%; 0,25W 20kOhm ±5%; 0,25W 20kOhm ±5%; 0,25W	B51263-A2822-J B51263-A9563-F B54413-A9561-F B51263-A9122-F B51263-A2103-J B54413-A2471-J B54413-A2681-J B54413-A2151-J B54413-A2391-J B54413-A2391-J B51263-A2203-J B51263-A2203-J B51263-A2203-J B51263-A2273-J	Md18 Ts18	1 8 8 Verdral PRINT!	MOUNTING Varaktordiode VARACTUR DIODE TOPF +5%; bei/AT -4V/25°C HC 7004B (Fa.Hughes) Richtleiterquartett DIODE QURTET 4X0A 90 Transistor TRANSISTOR BCY 58 / VIII Halterung MOUNTING DIRGUIT BOARD Tantal-Elko TANTALUM ELECTROLYTIC BOA 4,7/AF ±20%; 20V Drossel REACTOR 70/uH/0,2A Lötstift	V42292-E4-A1 Q60203-Y58-H C42121-A11-C10 74-A701 B45170-A3475-M RD B82501-A-C18
R2 R3 R4,25 R6 R7 R8,18,20 R37 R9 R10,23,34 R11 R12 R1316,28 R17 R19 R21 R22 R24 R26	1 1 2 1 1 4 4 1 3 1 1 1 5 1 1 1 1 1 1 1 1	33k0hm ±5%; 0,25W 8,2k0hm ±1%; 0,1W 560 0hm ±1%; 0,1W 560 0hm ±1%; 0,1W 10k0hm ±5%; 0,25W 470 0hm ±5%; 0,33W 150 0hm ±5%; 0,33W 300 0hm ±1%; 0,33W 300 0hm ±1%; 0,33W 150 0hm ±5%; 0,33W 150 0hm ±5%; 0,33W 20k0hm ±5%; 0,25W 27k0hm ±5%; 0,25W 27k0hm ±5%; 0,25W 27k0hm ±1%; 0,1W 30k0hm ±5%; 0,25W	B51263-A2822-J B51263-A9563-F B54413-A9561-F B51263-A9122-F B51263-A2103-J B54413-A2471-J B54413-A2681-J B54413-A2151-J B54413-A2391-J B54413-A9151-F B51263-A2122-J B51263-A2203-J B51263-A2273-J B51263-A9272-F	Md18 Ts18	1 8 8 Verdral PRINT!	MOUNTING Varaktordiode VARACTUR DIODE TOPF +5%; bei/AT -4V/25°C HC 7004B (Fa.Hughes) Richtleiterquartett DIODE QURTET 4X0A 90 Transistor TRANSISTOR BCY 58 / VIII Halterung MOUNTING DIRGUIT BOARD Tantal-Elko TANTALUM ELECTROLYTIC BOA 4,7/AF ±20%; 20V Drossel REACTOR 70/uH/0,2A Lötstift	V42292-E4-A1 Q60203-Y58-H C42121-A11-C10 74-A701 B45170-A3475-M RD B82501-A-C18
R2 R3 R4,25 R6 R7 R8,18,20 R37 R9 R10,23,34 R11 R12 R1316,28 R17 R19 R21 R22 R24	1 1 2 1 1 4 4 1 3 1 1 1 5 1 1 1 1 1 1 1 1 1	33kOhm ±5%; 0,25W 8,2kOhm ±1%; 0,1W 560 Ohm ±1%; 0,1W 560 Ohm ±1%; 0,1W 10kOhm ±5%; 0,25W 470 Ohm ±5%; 0,33W 150 Ohm ±5%; 0,33W 300 Ohm ±5%; 0,33W 300 Ohm ±5%; 0,33W 150 Ohm ±5%; 0,33W 150 Ohm ±5%; 0,33W 150 Ohm ±5%; 0,25W 20kOhm ±5%; 0,25W 27kOhm ±5%; 0,25W 27kOhm ±5%; 0,25W	B51263-A2822-J B51263-A9563-F B54413-A9561-F B51263-A9122-F B51263-A2103-J B54413-A2471-J B54413-A2681-J B54413-A251-J B54413-A9301-F B54413-A9301-F B54413-A9301-F B51263-A2122-J B51263-A2203-J B51263-A2273-J B51263-A2273-J B51263-A2273-J B51263-A2303-J	Md18 Ts18	1 8 8 Verdral PRINT!	MOUNTING Varaktordiode VARACTUR DIODE TOPF +5%; bei/AT -4V/25°C HC 7004B (Fa.Hughes) Richtleiterquartett DIODE QURTET 4X0A 90 Transistor TRANSISTOR BCY 58 / VIII Halterung MOUNTING DIRGUIT BOARD Tantal-Elko TANTALUM ELECTROLYTIC BOA 4,7/AF ±20%; 20V Drossel REACTOR 70/uH/0,2A Lötstift	V42292-E4-A1 Q60203-Y58-H C42121-A11-C10 74-A701 B45170-A3475-M RD B82501-A-C18
R2 R3 R4,25 R6 R7 R8,18,20 R37 R9 R10,23,34 R11 R12 R1316,28 R17 R19 R21 R22 R24 R26 R27	1	33kOhm ±5%; 0,25W 8,2kOhm ±1%; 0,1W 560 Ohm ±1%; 0,1W 10kOhm ±1%; 0,1W 10kOhm ±5%; 0,25W 470 Ohm ±5%; 0,33W 150 Ohm ±5%; 0,33W 390 Ohm ±5%; 0,33W 150 Ohm ±1%; 0,33W 150 Ohm ±1%; 0,33W 150 Ohm ±5%; 0,25W 20kOhm ±5%; 0,25W 27kOhm ±5%; 0,25W 2,7kOhm ±1%; 0,1W 30kOhm ±5%; 0,25W	B51263-A2822-J B51263-A9563-F B54413-A9561-F B51263-A2103-J B54413-A2471-J B54413-A2681-J B54413-A2151-J B54413-A2391-J B54413-A29151-F B51263-A2122-J B51263-A2203-J B51263-A2273-J B51263-A2273-J B51263-A2303-J B51263-A2153-J	Md18 Ts18	1 8 8 Verdral PRINT!	MOUNTING Varaktordiode VARACTUR DIODE TOPF +5%; bei/AT -4V/25°C HC 7004B (Fa.Hughes) Richtleiterquartett DIODE QURTET 4X0A 90 Transistor TRANSISTOR BCY 58 / VIII Halterung MOUNTING DIRGUIT BOARD Tantal-Elko TANTALUM ELECTROLYTIC BOA 4,7/AF ±20%; 20V Drossel REACTOR 70/uH/0,2A Lötstift	V42292-E4-A1 Q60203-Y58-H C42121-A11-C10 74-A701 B45170-A3475-M RD B82501-A-C18
R2 R3 R4,25 R6 R7 R8,18,20 R37 R9 R10,23,34 R11 R12 R1316,28 R17 R19 R21 R22 R24 R26 R27 R29	1	33kOhm ±5%; 0,25W 8,2kOhm ±1%; 0,1W 560 Ohm ±1%; 0,33W 1,2kOhm ±5%; 0,25W 470 Ohm ±5%; 0,33W 150 Ohm ±5%; 0,33W 300 Ohm ±5%; 0,33W 390 Ohm ±5%; 0,33W 150 Ohm ±5%; 0,33W 150 Ohm ±5%; 0,25W 20kOhm ±5%; 0,25W 27kOhm ±5%; 0,25W	B51263-A2822-J B51263-A9563-F B54413-A9561-F B51263-A2103-J B54413-A2471-J B54413-A2681-J B54413-A2151-J B54413-A2391-J B54413-A2391-J B51263-A2392-J B51263-A2392-J B51263-A2392-J B51263-A2392-J B51263-A2393-J B51263-A2393-J B51263-A2303-J B51263-A2153-J B51263-A2153-J B54413-A2221-J	Md18 Ts18	1 8 8 Verdral PRINT!	MOUNTING Varaktordiode VARACTUR DIODE TOPF +5%; bei/AT -4V/25°C HC 7004B (Fa.Hughes) Richtleiterquartett DIODE QURTET 4X0A 90 Transistor TRANSISTOR BCY 58 / VIII Halterung MOUNTING DIRGUIT BOARD Tantal-Elko TANTALUM ELECTROLYTIC BOA 4,7/AF ±20%; 20V Drossel REACTOR 70/uH/0,2A Lötstift	V42292-E4-A1 Q60203-Y58-H C42121-A11-C10 74-A701 B45170-A3475-M RD B82501-A-C18
R2 R3 R4,25 R6 R7 R8,18,20 R37 R9 R10,23,34 R11 R12 R1316,28 R17 R19 R21 R22 R24 R26 R27 R29 R30	1 1 2 1 1 4 4 1 3 5 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1	33kOhm ±5%; 0,25W 8,2kOhm ±1%; 0,1W 560 Ohm ±1%; 0,33W 1,2kOhm ±5%; 0,25W 470 Ohm ±5%; 0,33W 450 Ohm ±5%; 0,33W 300 Ohm ±5%; 0,33W 390 Ohm ±5%; 0,33W 150 Ohm ±5%; 0,33W 390 Ohm ±5%; 0,33W 1,2kOhm ±5%; 0,25W 20kOhm ±5%; 0,25W 27kOhm ±5%; 0,25W 20kOhm ±5%; 0,25W 20kOhm ±5%; 0,25W	B51263-A2822-J B51263-A9563-F B54413-A9561-F B51263-A9122-F B51263-A2103-J B54413-A2681-J B54413-A2681-J B54413-A251-J B54413-A2951-F B51263-A2122-J B51263-A2122-J B51263-A2203-J B51263-A2273-J B51263-A253-J B51263-A253-J B51263-A2221-J B51263-A2221-J B51263-A2221-J B51263-A2683-J	Md18 Ts18	1 8 8 Verdral PRINT!	MOUNTING Varaktordiode VARACTUR DIODE TOPF +5%; bei/AT -4V/25°C HC 7004B (Fa.Hughes) Richtleiterquartett DIODE QURTET 4X0A 90 Transistor TRANSISTOR BCY 58 / VIII Halterung MOUNTING DIRGUIT BOARD Tantal-Elko TANTALUM ELECTROLYTIC BOA 4,7/4F ±20%; 20V Drossel REACTOR 70/uH/0,2A Lötstift	V42292-E4-A1 Q60203-Y58-H C42121-A11-C10 74-A701 B45170-A3475-M RD B82501-A-C18
R2 R3 R4,25 R6 R7 R8,18,20 R37 R9 R10,23,34 R11 R12 R1316,28 R17 R19 R21 R22 R24 R26 R27 R29 R30 R31	1 1 2 1 1 4 4 1 3 1 1 1 1 1 1 1 1 1 1 1 1 1 1	33kOhm ±5%; 0,25W 8,2kOhm ±1%; 0,1W 560 Ohm ±1%; 0,1W 560 Ohm ±1%; 0,33W 1,2kOhm ±5%; 0,25W 470 Ohm ±5%; 0,33W 680 Ohm ±5%; 0,33W 150 Ohm ±5%; 0,33W 300 Ohm ±5%; 0,33W 300 Ohm ±5%; 0,33W 150 Ohm ±5%; 0,33W 150 Ohm ±5%; 0,25W 20kOhm ±5%; 0,25W 27kOhm ±5%; 0,25W 20kOhm ±5%; 0,25W 27kOhm ±5%; 0,25W	B51263-A2822-J B51263-A9563-F B54413-A9561-F B51263-A9122-F B51263-A2103-J B54413-A2471-J B54413-A2681-J B54413-A2151-J B54413-A2391-J B54413-A9301-F B54413-A9301-F B51263-A2122-J B51263-A2203-J B51263-A2203-J B51263-A2203-J B51263-A2203-J B51263-A2212-J B51263-A2212-J B51263-A2123-J B51263-A2123-J B51263-A2153-J B54413-A2221-J B51263-A2683-J B51263-A2683-J B51263-A9153-F	Md18 Ts18	1 8 8 Verdral PRINT!	MOUNTING Varaktordiode VARACTUR DIODE TOPF +5%; bei/AT -4V/25°C HC 7004B (Fa.Hughes) Richtleiterquartett DIODE QURTET 4X0A 90 Transistor TRANSISTOR BCY 58 / VIII Halterung MOUNTING DIRGUIT BOARD Tantal-Elko TANTALUM ELECTROLYTIC BOA 4,7/4F ±20%; 20V Drossel REACTOR 70/uH/0,2A Lötstift	V42292-E4-A1 Q60203-Y58-H C42121-A11-C10 74-A701 B45170-A3475-M RD B82501-A-C18
R2 R3 R4,25 R6 R7 R8,18,20 R37 R9 R10,23,34 R11 R12 R1316,28 R17 R19 R21 R22 R24 R26 R27 R29 R30 R31 R32	1 1 2 1 1 4 4 1 3 1 1 1 1 1 1 1 1 1 1 1 1 1 1	33kOhm ±5%; 0,25W 8,2kOhm ±1%; 0,1W 560 Ohm ±1%; 0,1W 560 Ohm ±1%; 0,1W 10kOhm ±5%; 0,25W 470 Ohm ±5%; 0,33W 150 Ohm ±5%; 0,33W 300 Ohm ±5%; 0,33W 300 Ohm ±5%; 0,33W 150 Ohm ±5%; 0,33W 150 Ohm ±5%; 0,33W 200 Ohm ±5%; 0,25W 27kOhm ±5%; 0,25W 27kOhm ±5%; 0,25W 27kOhm ±5%; 0,25W 15kOhm ±5%; 0,25W 20 Ohm ±5%; 0,25W 20 Ohm ±5%; 0,25W 21kOhm ±5%; 0,25W 220 Ohm ±5%; 0,25W 220 Ohm ±5%; 0,25W 25kOhm ±5%; 0,25W	B51263-A2822-J B51263-A9563-F B54413-A9561-F B51263-A9122-F B51263-A2103-J B54413-A2471-J B54413-A2681-J B54413-A2591-J B54413-A9301-F B54413-A9301-F B51263-A2122-J B51263-A2292-J B51263-A2292-J B51263-A29272-F B51263-A29272-F B51263-A29272-F B51263-A29273-F B51263-A2683-J B51263-A9683-J B51263-A9973-F	Md18 Ts18	1 8 8 Verdral PRINT!	MOUNTING Varaktordiode VARACTUR DIODE TOPF +5%; bei/AT -4V/25°C HC 7004B (Fa.Hughes) Richtleiterquartett DIODE QURTET 4X0A 90 Transistor TRANSISTOR BCY 58 / VIII Halterung MOUNTING DIRGUIT BOARD Tantal-Elko TANTALUM ELECTROLYTIC BOA 4,7/4F ±20%; 20V Drossel REACTOR 70/uH/0,2A Lötstift	V42292-E4-A1 Q60203-Y58-H C42121-A11-C10 74-A701 B45170-A3475-M RD B82501-A-C18
R2 R3 R4,25 R6 R7 R8,18,20 R37 R9 R10,23,34 R11 R12 R1316,28 R17 R19 R21 R22 R24 R26 R27 R29 R30 R31 R32 R33	1	33kOhm ±5%; 0,25W 8,2kOhm ±1%; 0,1W 560 Ohm ±1%; 0,1W 560 Ohm ±1%; 0,1W 10kOhm ±5%; 0,25W 470 Ohm ±5%; 0,33W 150 Ohm ±5%; 0,33W 390 Ohm ±5%; 0,33W 390 Ohm ±5%; 0,33W 150 Ohm ±1%; 0,33W 390 Ohm ±5%; 0,33W 20kOhm ±5%; 0,25W 27kOhm ±5%; 0,25W 27kOhm ±5%; 0,25W 27kOhm ±5%; 0,25W 20kOhm ±5%; 0,25W 27kOhm ±5%; 0,25W	B51263-A2822-J B51263-A9563-F B54413-A9561-F B51263-A9122-F B51263-A2103-J B54413-A2471-J B54413-A2681-J B54413-A251-J B54413-A9301-F B54413-A9301-F B54413-A9301-F B51263-A2122-J B51263-A2203-J B51263-A2203-J B51263-A2203-J B51263-A2203-J B51263-A2203-J B51263-A2303-J B51263-A2303-J B51263-A2503-J	Md18 Ts18	1 8 8 Verdral PRINT!	MOUNTING Varaktordiode VARACTUR DIODE TOPF +5%; bei/AT -4V/25°C HC 7004B (Fa.Hughes) Richtleiterquartett DIODE QURTET 4X0A 90 Transistor TRANSISTOR BCY 58 / VIII Halterung MOUNTING DIRGUIT BOARD Tantal-Elko TANTALUM ELECTROLYTIC BOA 4,7/4F ±20%; 20V Drossel REACTOR 70/uH/0,2A Lötstift	V42292-E4-A1 Q60203-Y58-H C42121-A11-C10 74-A701 B45170-A3475-M RD B82501-A-C18
R2 R3 R4,25 R6 R7 R8,18,20 R37 R9 R10,23,34 R11 R12 R1316,28 R17 R19 R21 R22 R24 R26 R27 R29 R30 R31 R32 R33	1	33kOhm ±5%; 0,25W 8,2kOhm ±1%; 0,1W 560 Ohm ±1%; 0,1W 560 Ohm ±1%; 0,1W 10kOhm ±5%; 0,25W 470 Ohm ±5%; 0,33W 150 Ohm ±5%; 0,33W 390 Ohm ±5%; 0,33W 390 Ohm ±5%; 0,33W 150 Ohm ±5%; 0,33W 390 Ohm ±5%; 0,25W 20kOhm ±5%; 0,25W 27kOhm ±5%; 0,25W 20 Ohm ±5%; 0,25W	B51263-A2822-J B51263-A9563-F B54413-A9561-F B51263-A2103-J B54413-A2471-J B54413-A2681-J B54413-A2511-J B54413-A2391-J B54413-A2391-J B51263-A2122-J B51263-A2203-J B51263-A2273-J B51263-A2273-J B51263-A2563-J B51263-A2683-J B51263-A2683-J B51263-A9273-F	Md18 Ts18	1 8 8 Verdral PRINT!	MOUNTING Varaktordiode VARACTUR DIODE TOPF +5%; bei/AT -4V/25°C HC 7004B (Fa.Hughes) Richtleiterquartett DIODE QURTET 4X0A 90 Transistor TRANSISTOR BCY 58 / VIII Halterung MOUNTING DIRGUIT BOARD Tantal-Elko TANTALUM ELECTROLYTIC BOA 4,7/4F ±20%; 20V Drossel REACTOR 70/uH/0,2A Lötstift	V42292-E4-A1 Q60203-Y58-H C42121-A11-C10 74-A701 B45170-A3475-M RD B82501-A-C18
R2 R3 R4,25 R6 R7 R8,18,20 R37 R9 R10,23,34 R11 R12 R1316,28 R17 R19 R21 R22 R24 R26 R27 R29 R30 R31 R32 R33 R35 R36	1	33kOhm ±5%; 0,25W 8,2kOhm ±1%; 0,1W 560 Ohm ±1%; 0,1W 560 Ohm ±1%; 0,33W 1,2kOhm ±5%; 0,25W 470 Ohm ±5%; 0,33W 150 Ohm ±5%; 0,33W 300 Ohm ±5%; 0,33W 300 Ohm ±5%; 0,33W 150 Ohm ±5%; 0,33W 300 Ohm ±5%; 0,25W 20kOhm ±5%; 0,25W 27kOhm ±5%; 0,25W 27kOhm ±5%; 0,25W 27kOhm ±5%; 0,25W 15kOhm ±5%; 0,25W 20 Ohm ±5%; 0,25W 20 Ohm ±5%; 0,25W 21kOhm ±5%; 0,25W 220 Ohm ±5%; 0,25W 25kOhm ±5%; 0,25W 26kOhm ±5%; 0,25W 27kOhm ±1%; 0,1W 36kOhm ±5%; 0,25W 20 Ohm ±5%; 0,25W	B51263-A2822-J B51263-A9563-F B54413-A9561-F B51263-A2103-J B54413-A2471-J B54413-A2681-J B54413-A2511-J B54413-A2391-J B54413-A2391-J B54413-A2392-J B51263-A2203-J B51263-A2203-J B51263-A2203-J B51263-A253-J B51263-A253-J B51263-A253-J B51263-A253-J B51263-A2563-J	Md18 Ts18	1 8 8 Verdral PRINT!	MOUNTING Varaktordiode VARACTUR DIODE TOPF +5%; bei/AT -4V/25°C HC 7004B (Fa.Hughes) Richtleiterquartett DIODE QURTET 4X0A 90 Transistor TRANSISTOR BCY 58 / VIII Halterung MOUNTING DIRGUIT BOARD Tantal-Elko TANTALUM ELECTROLYTIC BOA 4,7/4F ±20%; 20V Drossel REACTOR 70/uH/0,2A Lötstift	V42292-E4-A1 Q60203-Y58-H C42121-A11-C10 74-A701 B45170-A3475-M RD B82501-A-C18
R2 R3 R4,25 R6 R7 R8,18,20 R37 R9 R10,23,34 R11 R12 R1316,28 R17 R19 R21 R22 R24 R26 R27 R29 R30 R51 R32 R33 R35 R35	1	33kOhm ±5%; 0,25W 8,2kOhm ±1%; 0,1W 560 Ohm ±1%; 0,1W 560 Ohm ±1%; 0,1W 1,2kOhm ±1%; 0,1W 10kOhm ±5%; 0,25W 470 Ohm ±5%; 0,33W 150 Ohm ±5%; 0,33W 390 Ohm ±1%; 0,33W 390 Ohm ±1%; 0,33W 150 Ohm ±1%; 0,33W 150 Ohm ±1%; 0,33W 200 Ohm ±5%; 0,25W 20kOhm ±5%; 0,25W 27kOhm ±5%; 0,25W 27kOhm ±5%; 0,25W 27kOhm ±5%; 0,25W 20 Ohm ±5%; 0,25W 15kOhm ±5%; 0,25W 20 Ohm ±5%; 0,25W 27kOhm ±1%; 0,1W 30kOhm ±5%; 0,25W 15kOhm ±1%; 0,1W 27kOhm ±1%; 0,1W 27kOhm ±1%; 0,1W 27kOhm ±1%; 0,1W 27kOhm ±1%; 0,1W 560 Ohm ±5%; 0,25W 15kOhm ±5%; 0,25W 15kOhm ±1%; 0,1W 27kOhm ±5%; 0,25W 15kOhm ±5%; 0,25W 15kOhm ±5%; 0,25W 15kOhm ±5%; 0,25W 15kOhm ±5%; 0,25W	B51263-A2822-J B51263-A9563-F B54413-A9561-F B51263-A2103-J B54413-A2471-J B54413-A2681-J B54413-A2511-J B54413-A2511-J B54413-A2511-F B51263-A2122-J B51263-A2203-J B51263-A2203-J B51263-A2203-J B51263-A2593-J B51263-A2563-J B51263-A2563-J B51263-A2563-J B51263-A2563-J B51263-A2563-J B51263-A2222-J Re1 By 622 W 3035	Md18 Ts18	1 8 8 Verdral PRINT!	MOUNTING Varaktordiode VARACTUR DIODE TOPF +5%; bei/AT -4V/25°C HC 7004B (Fa.Hughes) Richtleiterquartett DIODE QURTET 4X0A 90 Transistor TRANSISTOR BCY 58 / VIII Halterung MOUNTING DIRGUIT BOARD Tantal-Elko TANTALUM ELECTROLYTIC BOA 4,7/4F ±20%; 20V Drossel REACTOR 70/uH/0,2A Lötstift	V42292-E4-A1 Q60203-Y58-H C42121-A11-C10 74-A701 B45170-A3475-M RD B82501-A-C18
R2 R3 R4,25 R6 R7 R8,18,20 R37 R9 R10,23,34 R11 R12 R1316,28 R17 R19 R21 R22 R24 R26 R27 R29 R30 R31 R32 R33 R35 R36	1	33kOhm ±5%; 0,25W 8,2kOhm ±1%; 0,1W 560 Ohm ±1%; 0,1W 560 Ohm ±1%; 0,33W 1,2kOhm ±5%; 0,25W 470 Ohm ±5%; 0,33W 150 Ohm ±5%; 0,33W 300 Ohm ±5%; 0,33W 300 Ohm ±5%; 0,33W 150 Ohm ±5%; 0,33W 300 Ohm ±5%; 0,25W 20kOhm ±5%; 0,25W 27kOhm ±5%; 0,25W 27kOhm ±5%; 0,25W 27kOhm ±5%; 0,25W 15kOhm ±5%; 0,25W 20 Ohm ±5%; 0,25W 20 Ohm ±5%; 0,25W 21kOhm ±5%; 0,25W 220 Ohm ±5%; 0,25W 25kOhm ±5%; 0,25W 26kOhm ±5%; 0,25W 27kOhm ±1%; 0,1W 36kOhm ±5%; 0,25W 20 Ohm ±5%; 0,25W	B51263-A2822-J B51263-A9563-F B54413-A9561-F B51263-A9122-F B51263-A2103-J B54413-A2471-J B54413-A2681-J B54413-A2591-J B54413-A9301-F B54413-A9301-F B51263-A2122-J B51263-A2203-J B51263-A2203-J B51263-A2203-J B51263-A2503-J B51263-A2503-J B51263-A2503-J B51263-A2683-J B51263-A9273-F B54413-A2561-J B51263-A2563-J B51263-A2563-J B51263-A2563-J B51263-A2563-J B51263-A2563-J B51263-A2563-J B51263-A2563-J B51263-A2563-J B51263-A2563-J B51263-A2222-J Rel By 622 W 3035	Md18 Ts18	1 8 8 Verdral PRINT!	MOUNTING Varaktordiode VARACTUR DIODE TOPF +5%; bei/AT -4V/25°C HC 7004B (Fa.Hughes) Richtleiterquartett DIODE QURTET 4X0A 90 Transistor TRANSISTOR BCY 58 / VIII Halterung MOUNTING DIRGUIT BOARD Tantal-Elko TANTALUM ELECTROLYTIC BOA 4,7/4F ±20%; 20V Drossel REACTOR 70/uH/0,2A Lötstift	V42292-E4-A1 Q60203-Y58-H C42121-A11-C10 74-A701 B45170-A3475-M RD B82501-A-C18



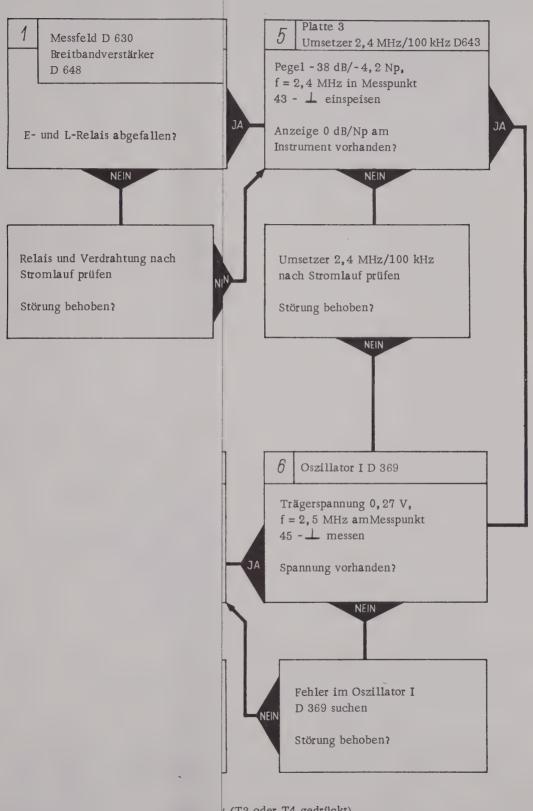


▼ II in Mittelstellung

 $f_2 = 0 \text{ kHz}, S7: 0 \text{ Hz}$

T4: gedrü

f₁ = 100 kHz, S6: gerastet S3: 0 dB/pss- und Anschlusspunkte siehe S4: dB/Np5034-D354-B302, B602-x-7411 S5: 1600 5034-D354-B602-x-7402



(T3 oder T4 gedrückt), z, 40 Hz, 1600 Hz)

Bildanlage 2



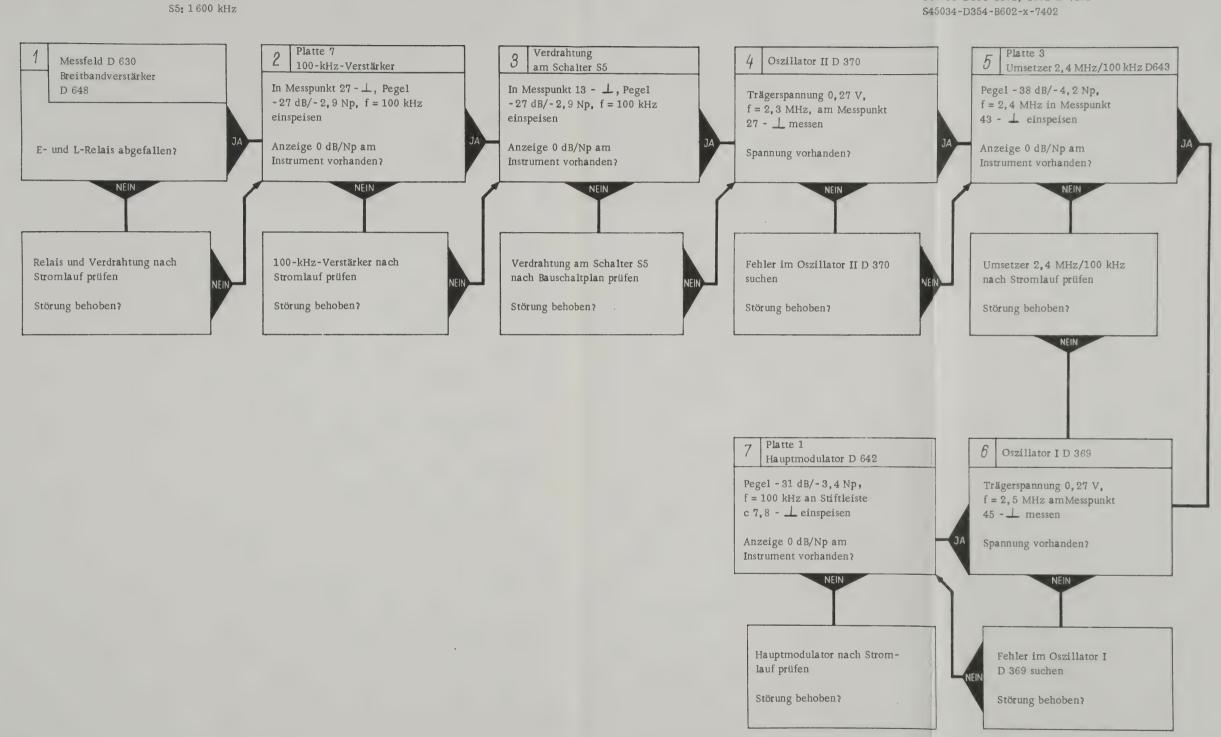
Einstellen:

▼ II in Mittelstellung $f_1 = 100 \text{ kHz}$, S6: gerastet S3: 0 dB/Np $f_2 = 0 \text{ kHz}, S7: 0 \text{ Hz}$

S4: dB/Np

T4: gedrückt

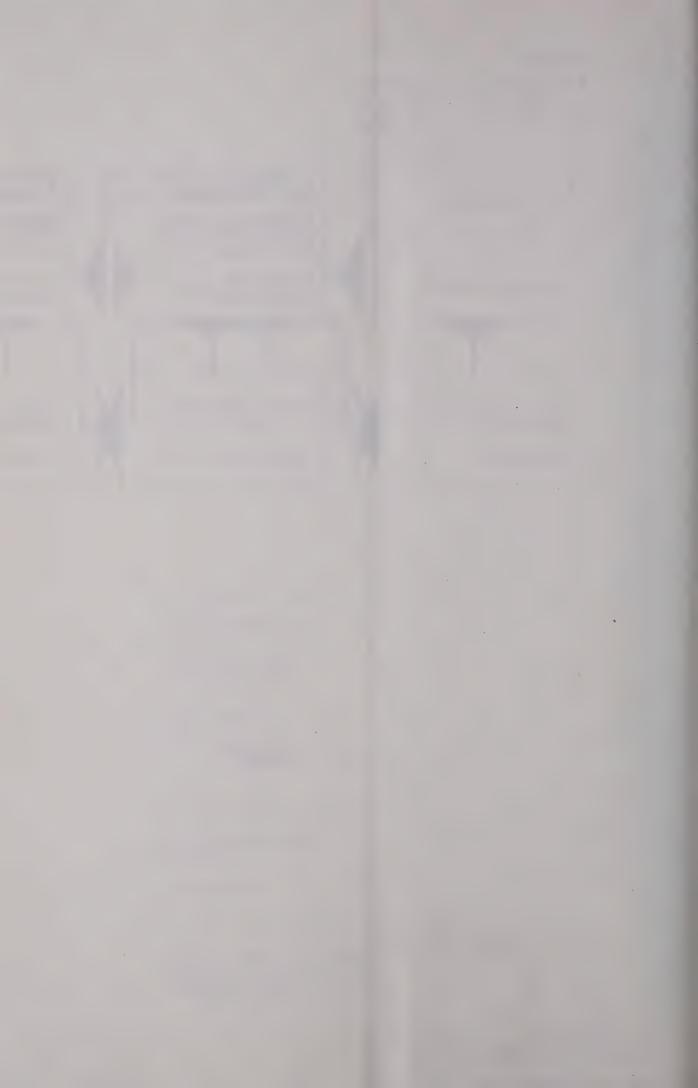
Mess- und Anschlusspunkte siehe \$45034-D354-B302, B602-x-7411

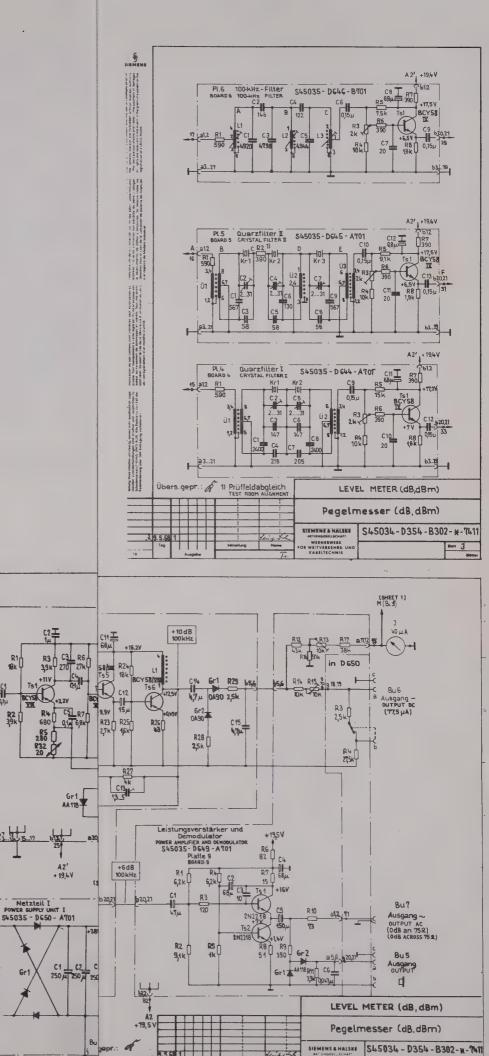


Fehlersuche, Befund: Messen selektiv (T3 oder T4 gedrückt), bei allen drei Durchlassbreiten (10 Hz, 40 Hz, 1600 Hz) und VII nicht möglich

Bildanlage 2

SIEMENS





- 27,5dB 100 kHz

82 d

\$3..13 15..17

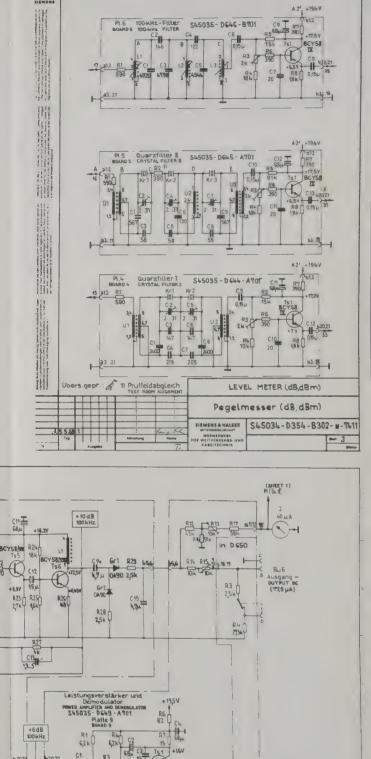
(BI.2) (SHEET 2)

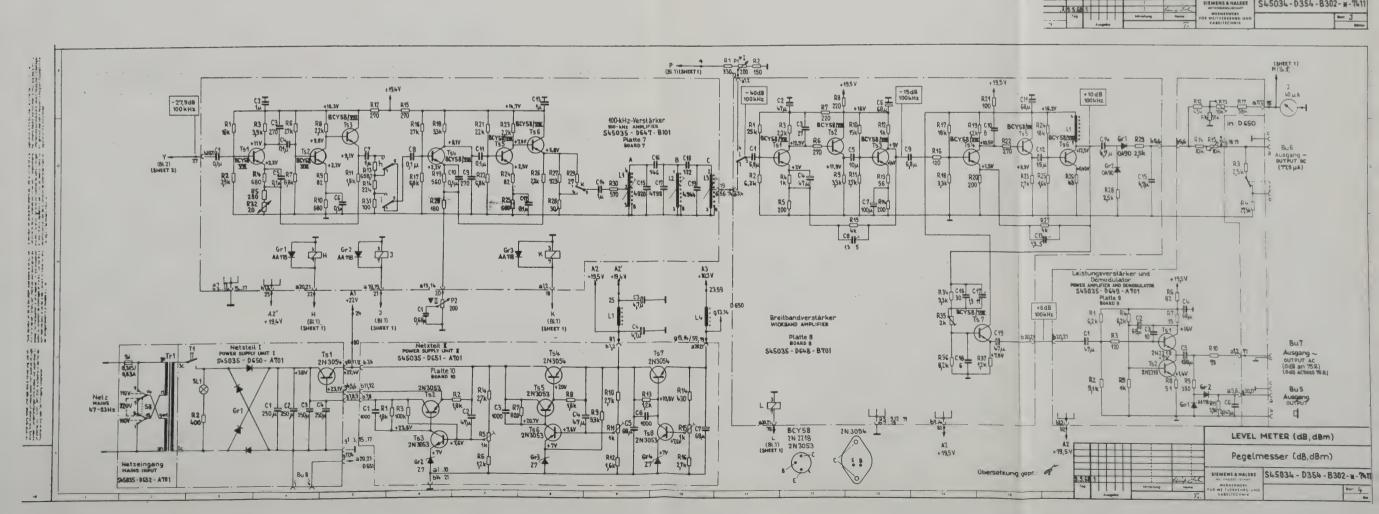
Netzeingang

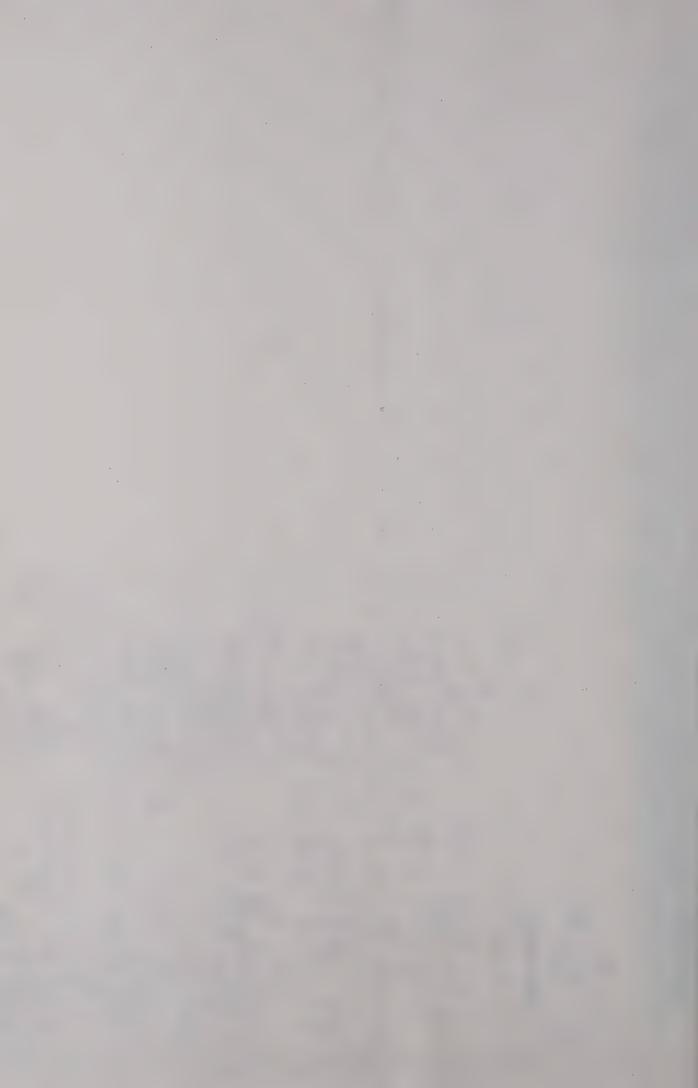
\$45035 - DES2 - A701

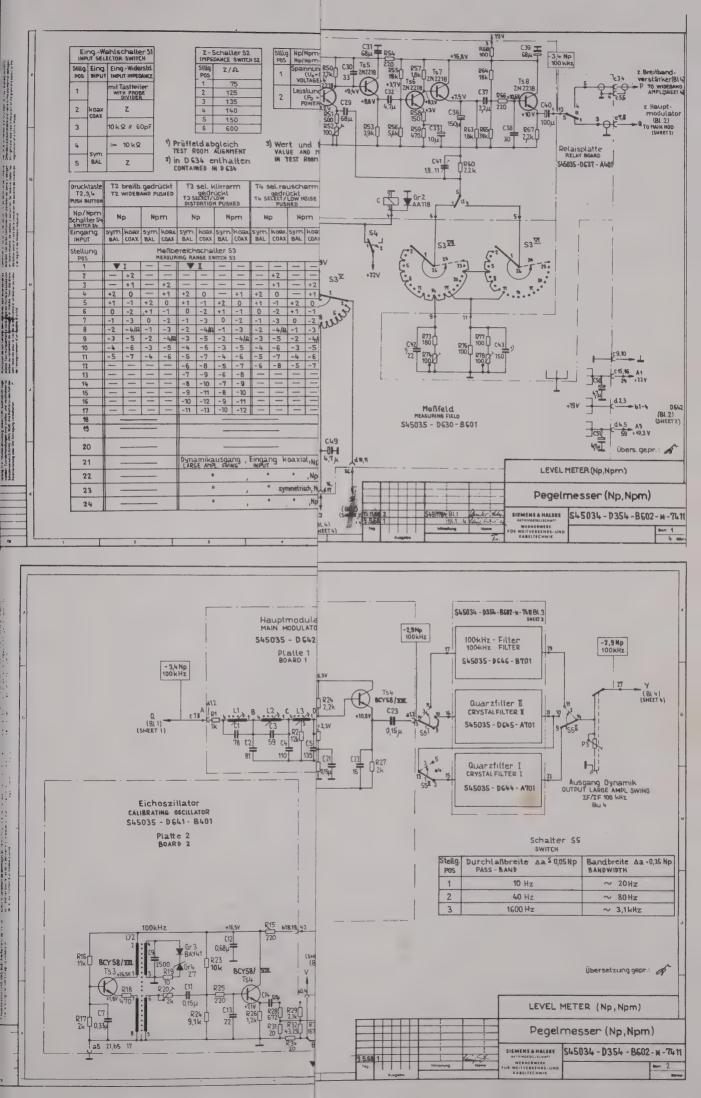
To colonial base of the coloni



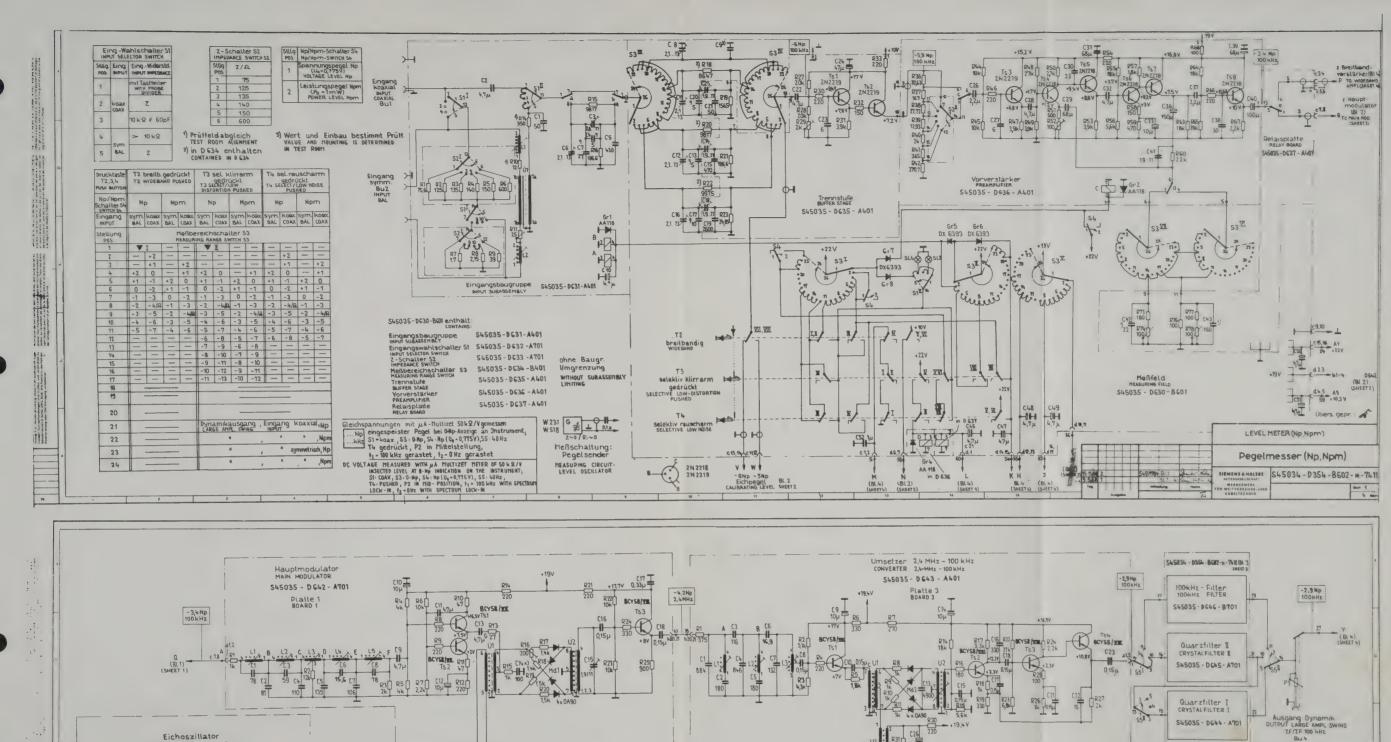


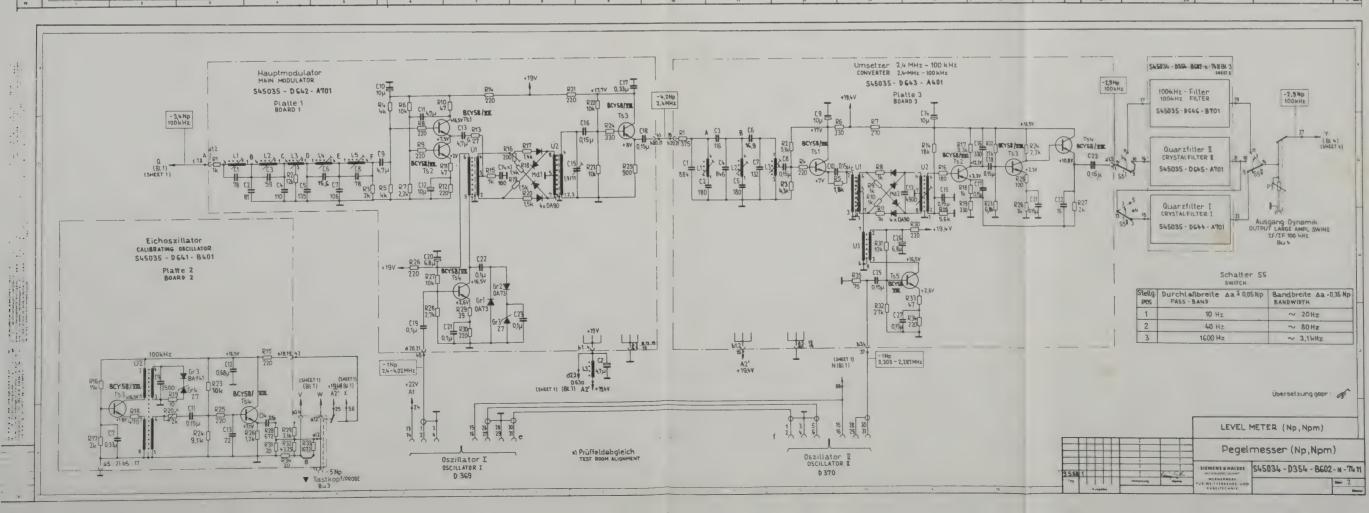


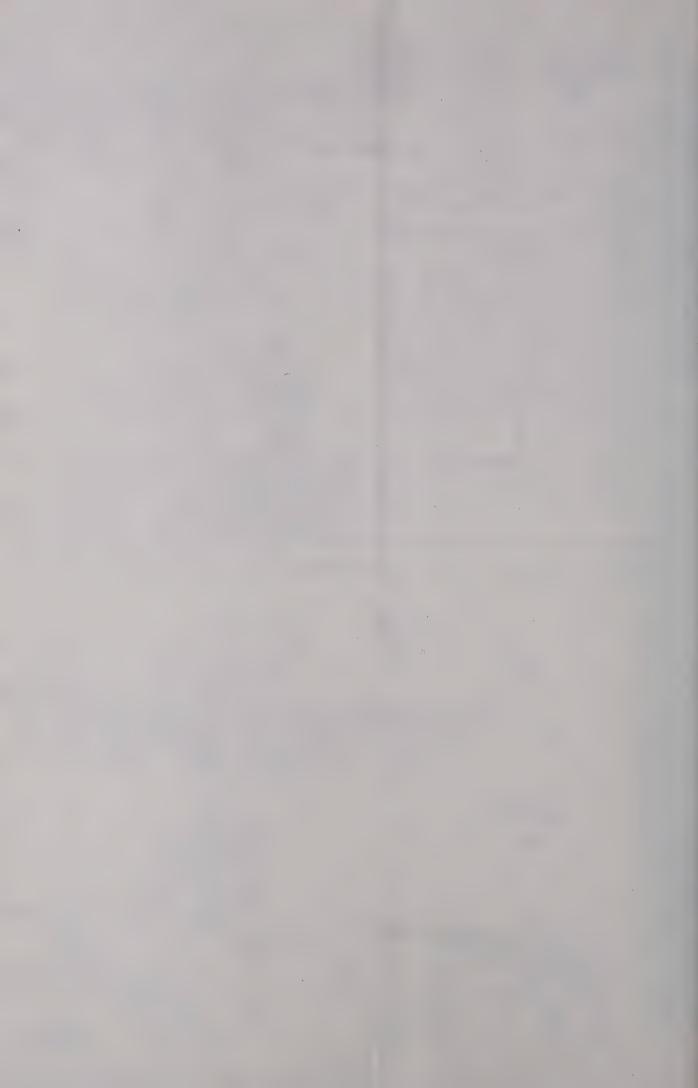


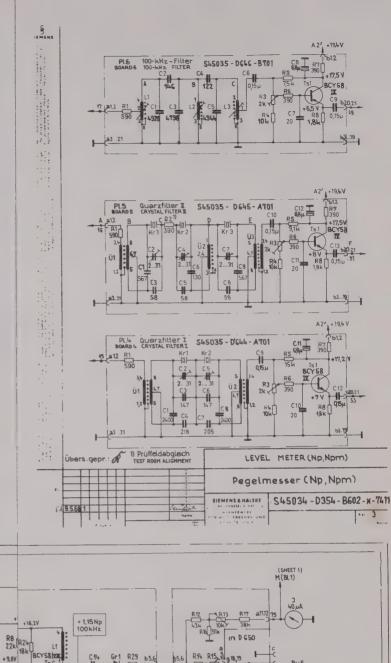


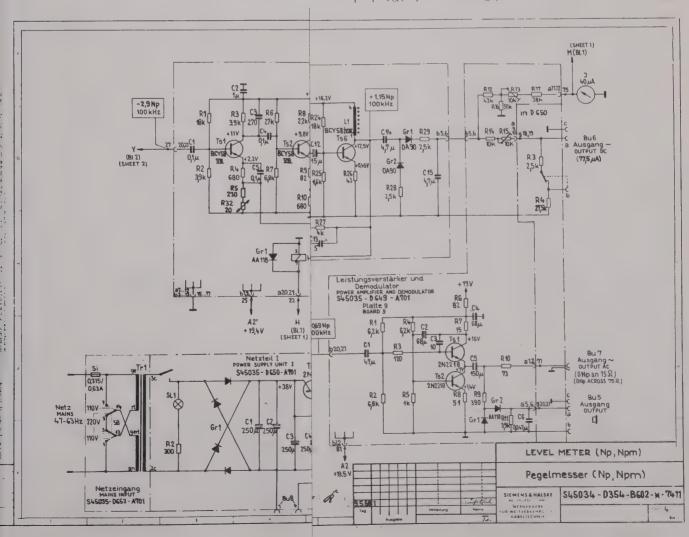




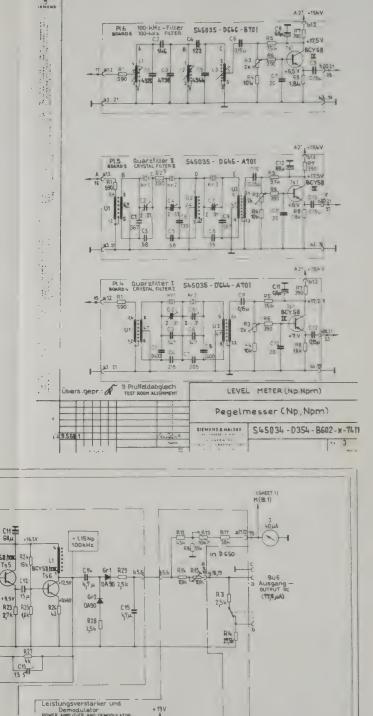


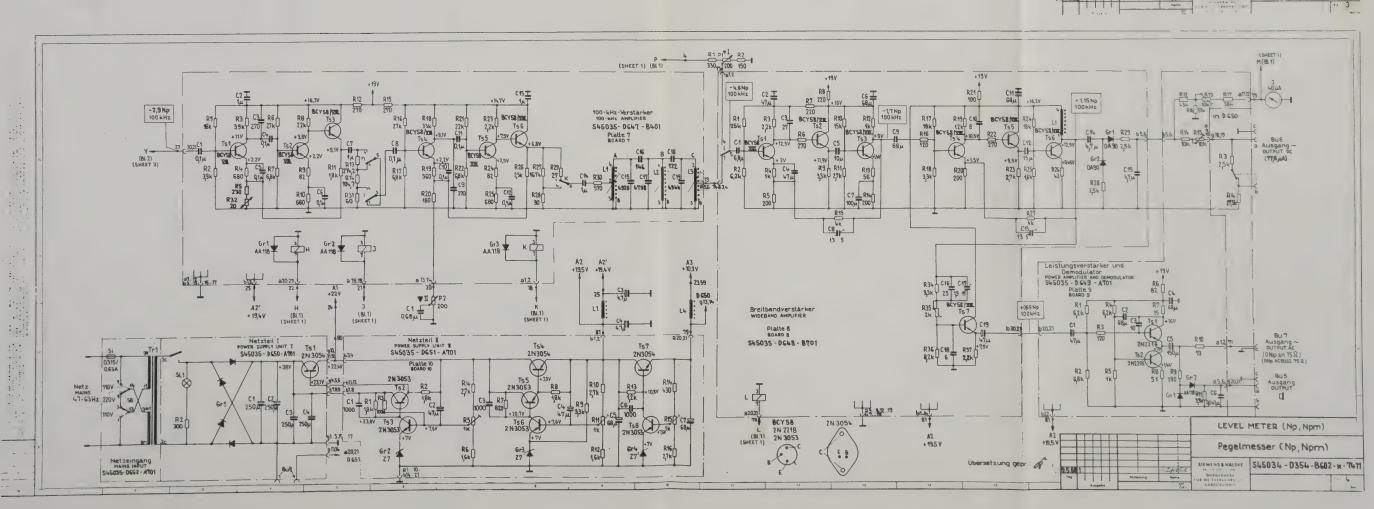


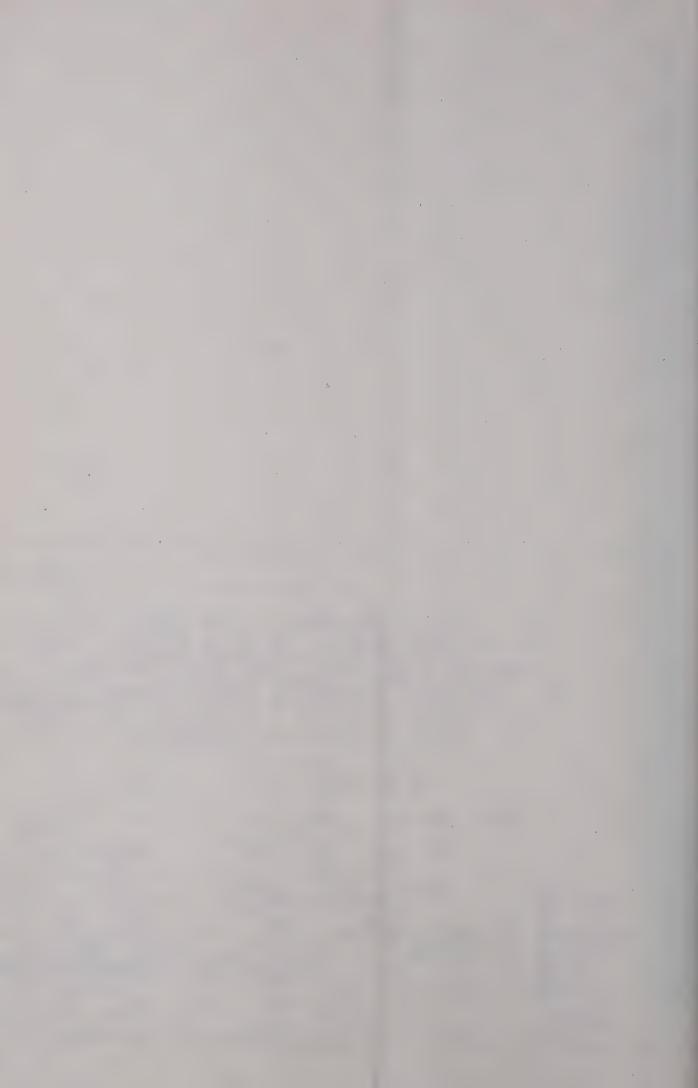


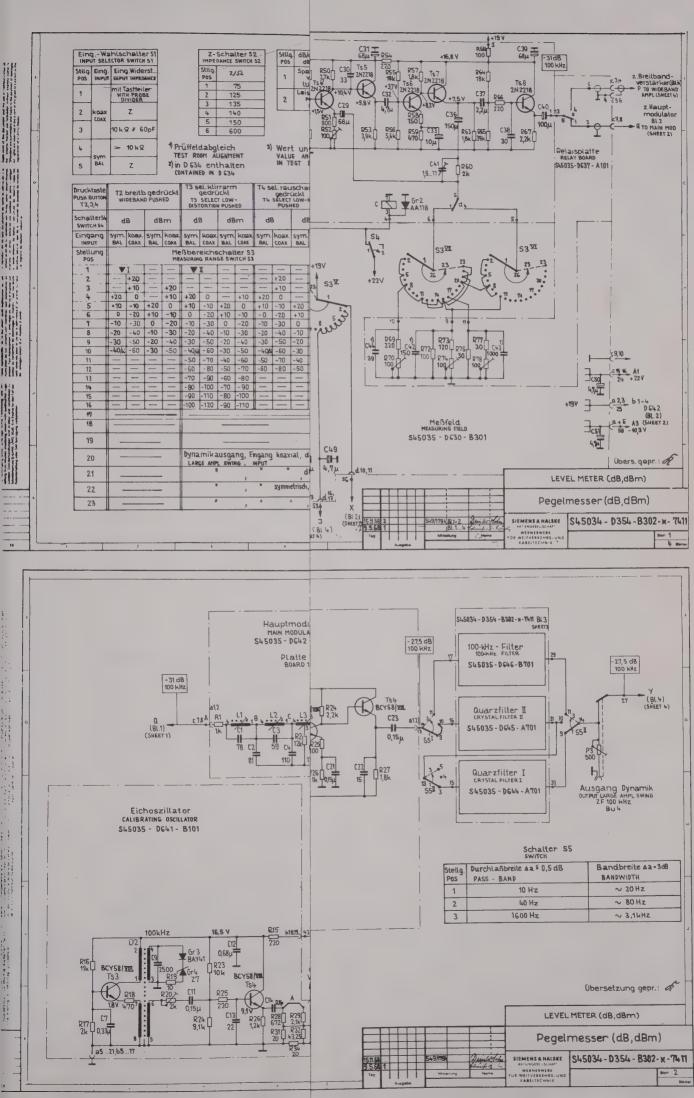




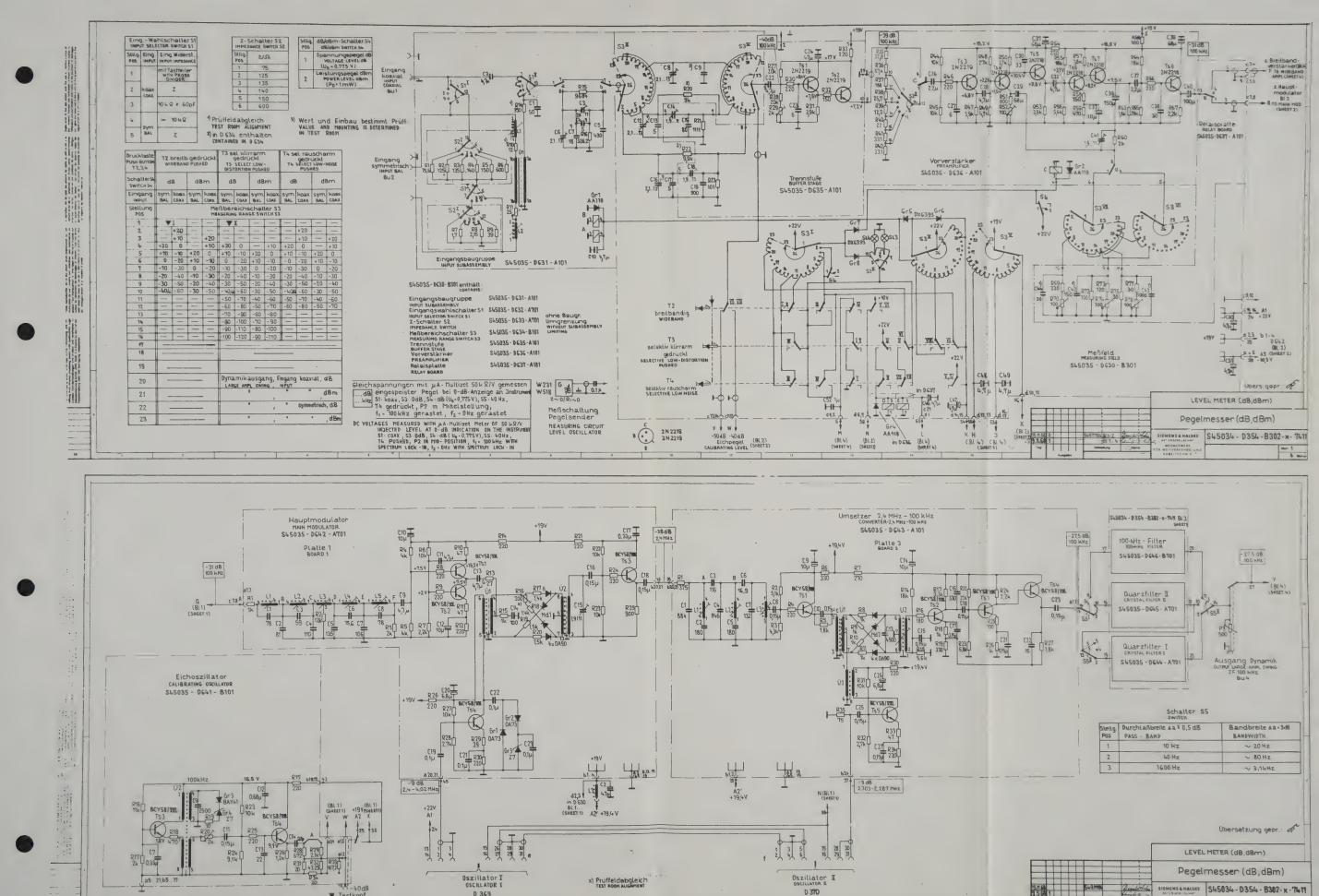




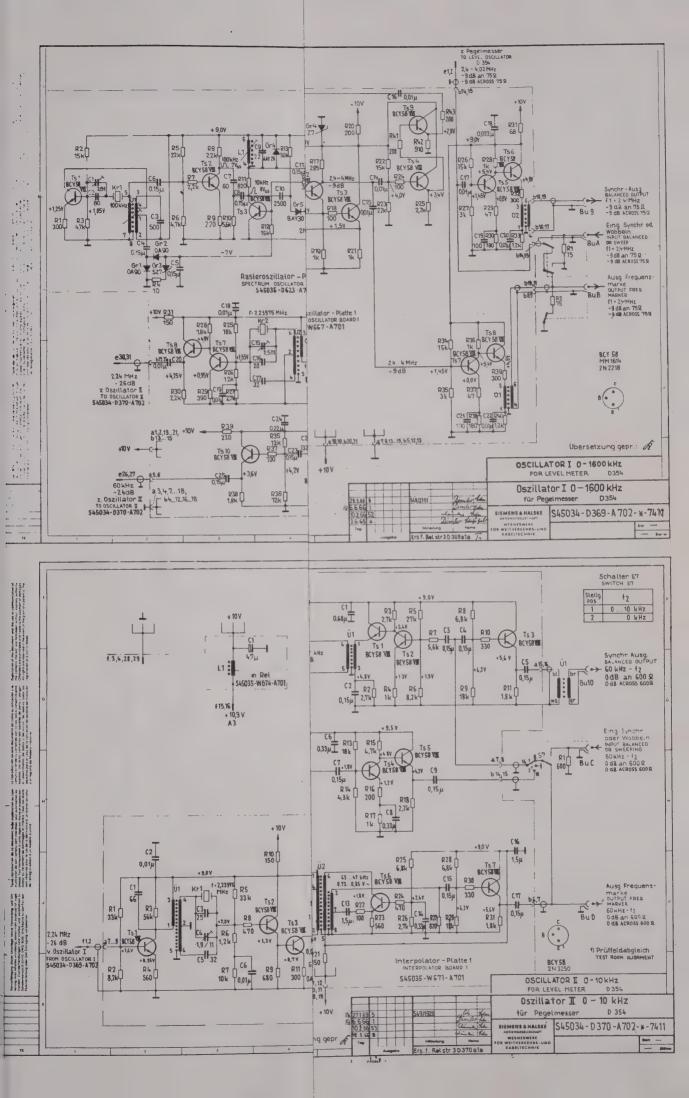


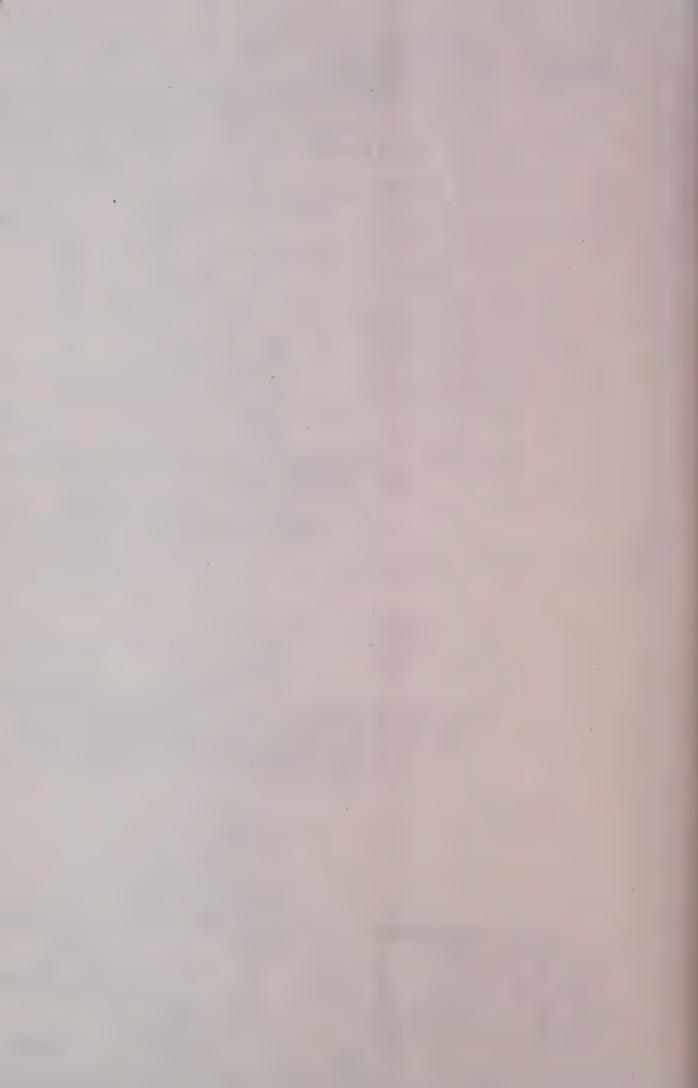


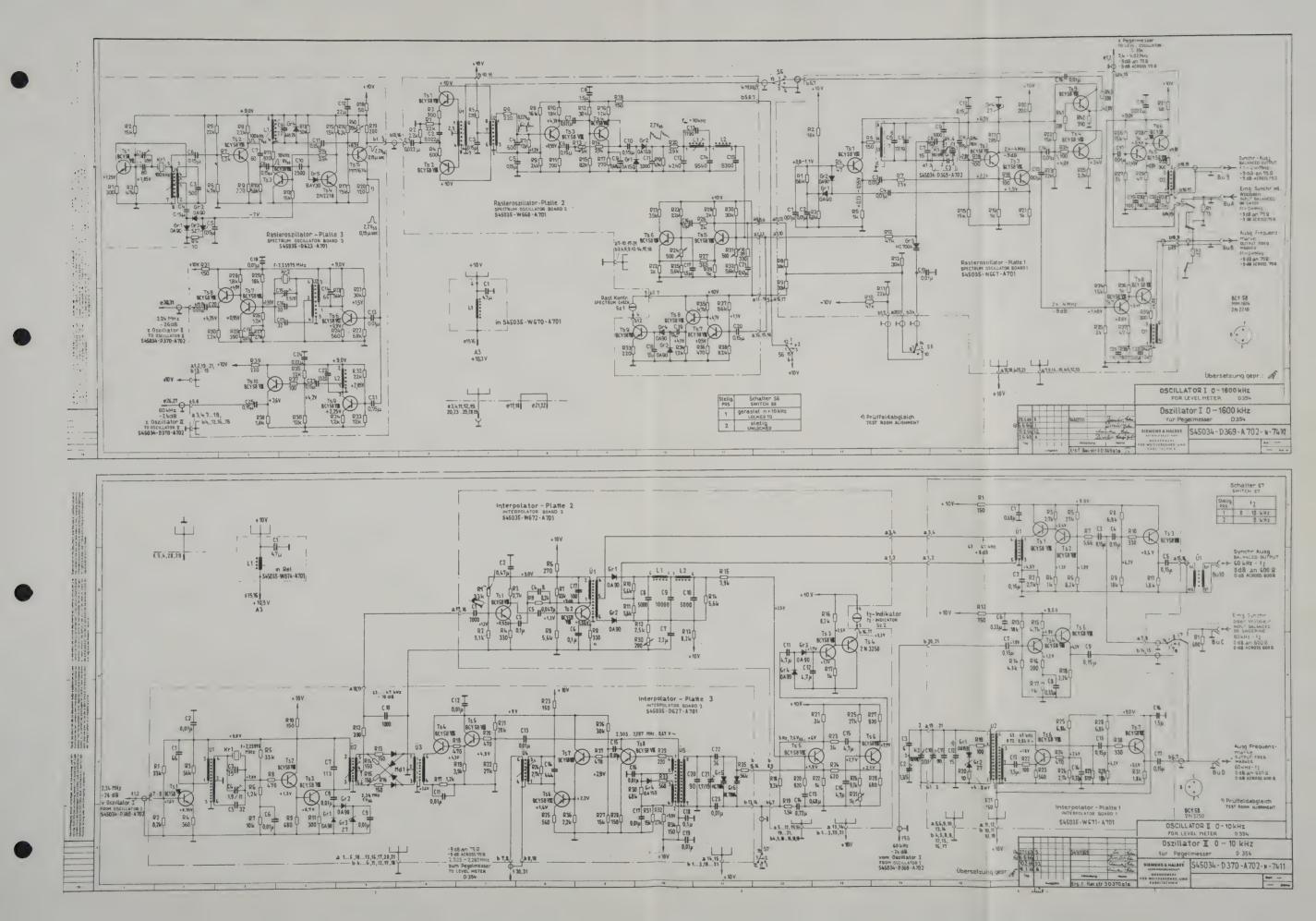




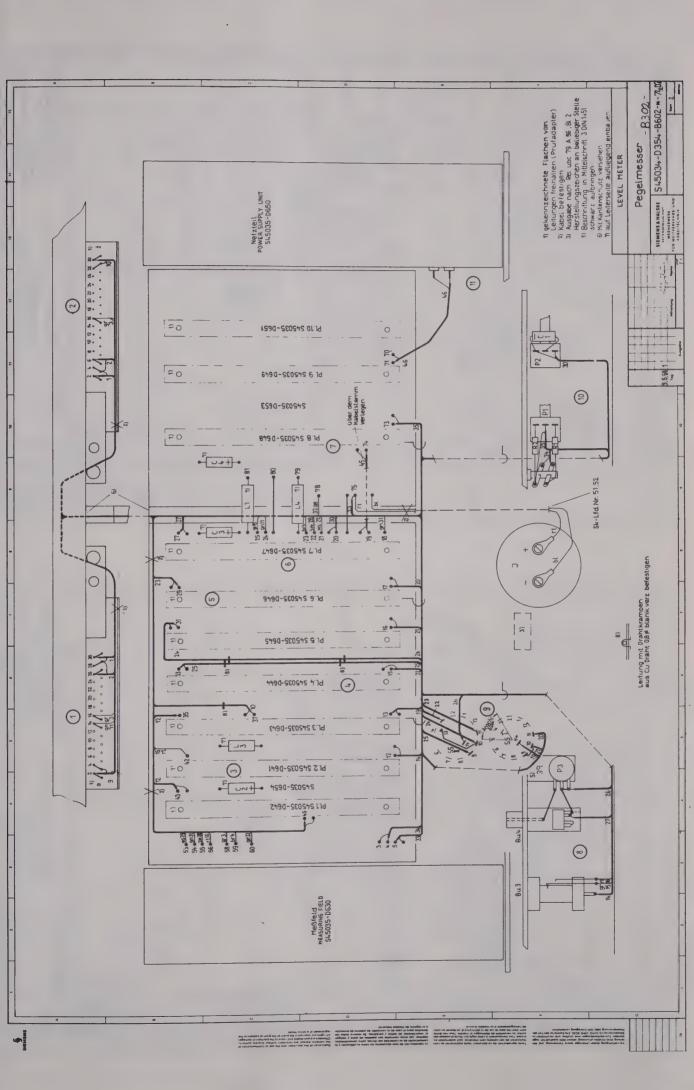


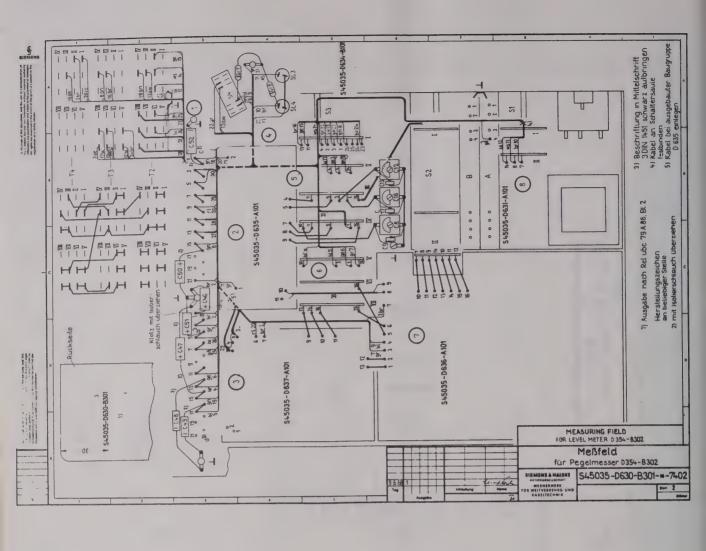


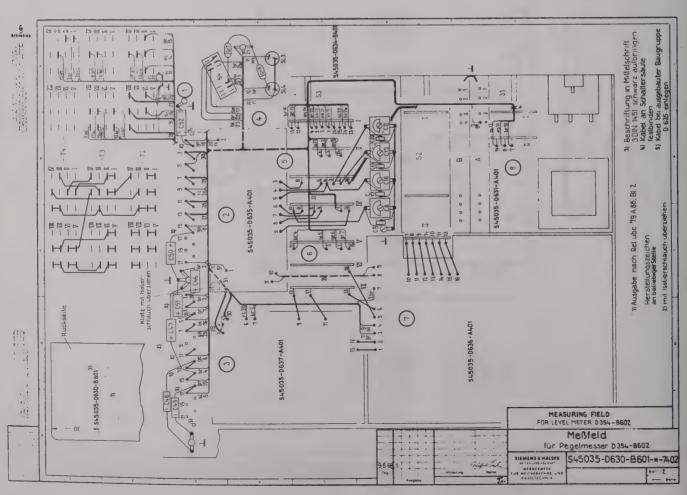


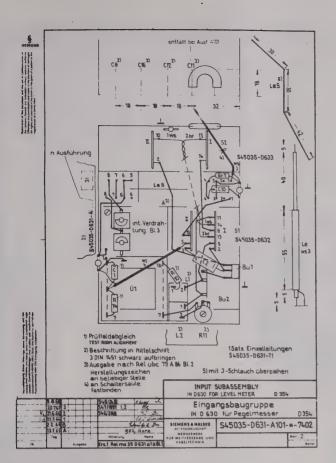


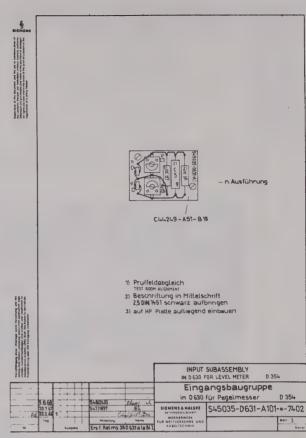


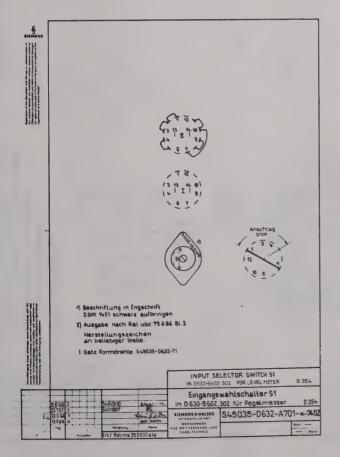


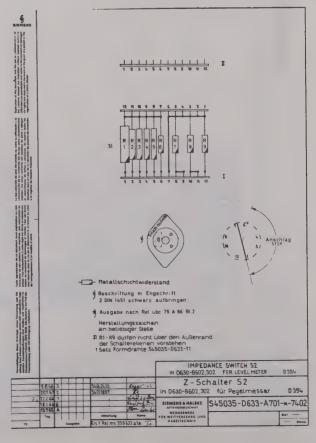


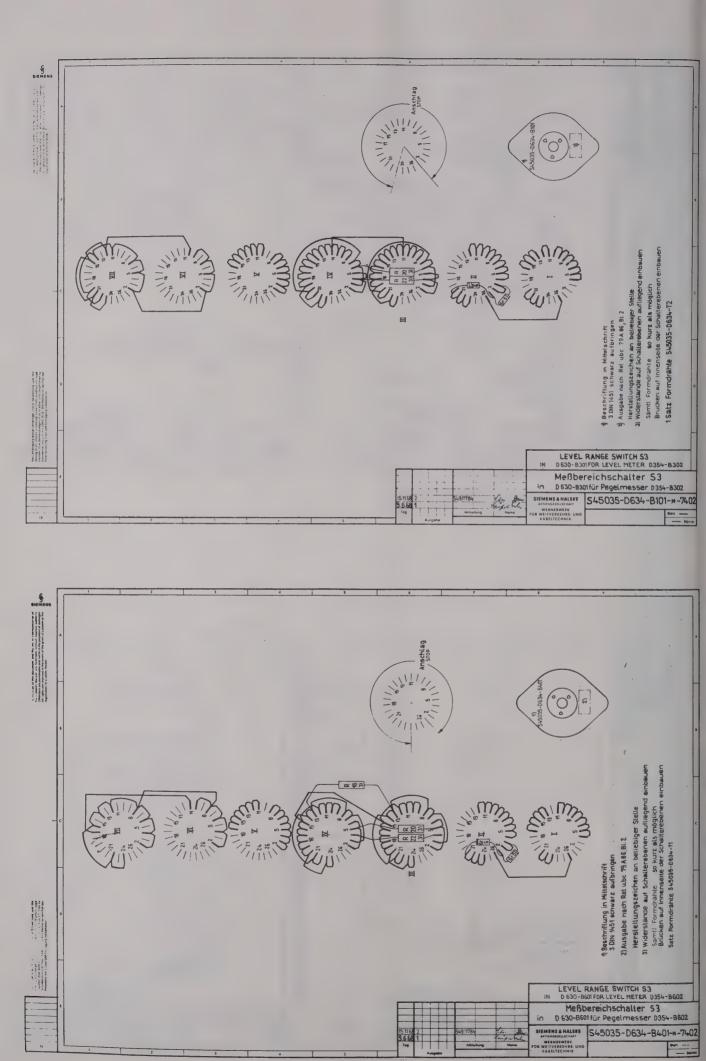


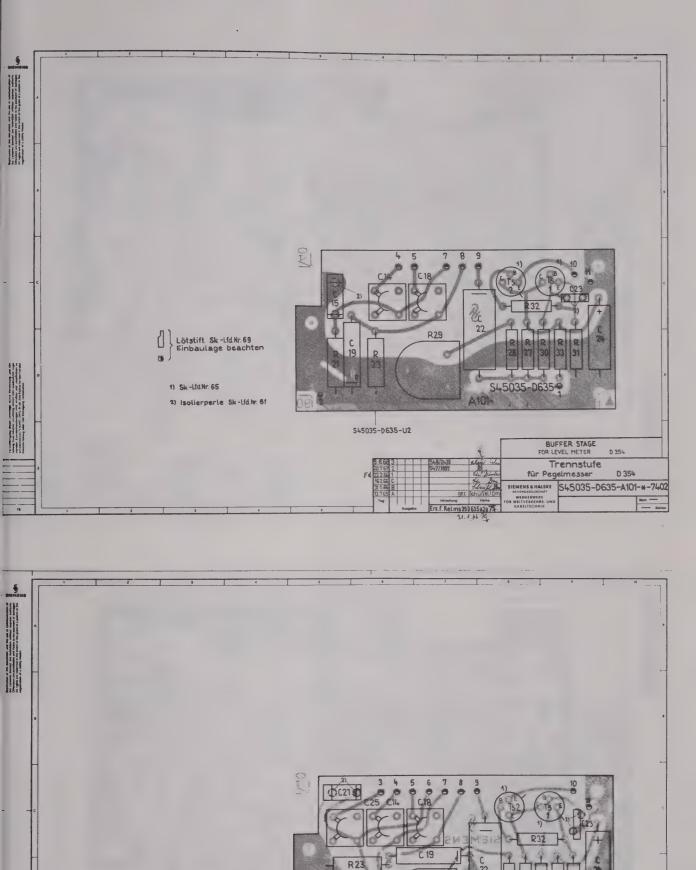












R21

\$45035-D635-U1

\$45035-D635-A401-

BUFFER STAGE FOR LEVEL METER

Trennstufe für Pegelmesser

SIEMENS & HALSKE

D 354

S45035-D635-A401-*-7402

Lötstift Sk-Lfd.W.69 Einbaulage beachten

2) Isolierperle Sk-Lfd.Nr. 61

1) Sk -Lfd.Nr. 65

